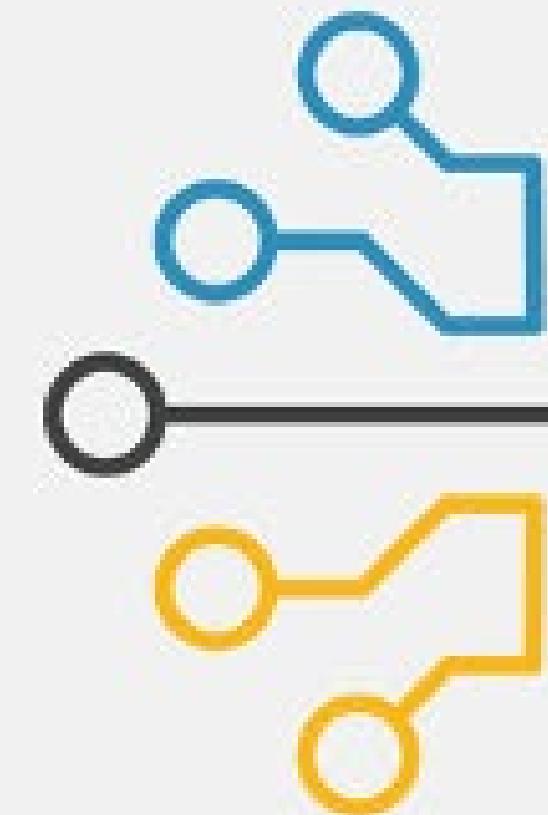




Welcome to



**E M E R G I N G
T E C H N O L O G I E S
C O N F E R E N C E** at Advanced Textiles **EXPO**



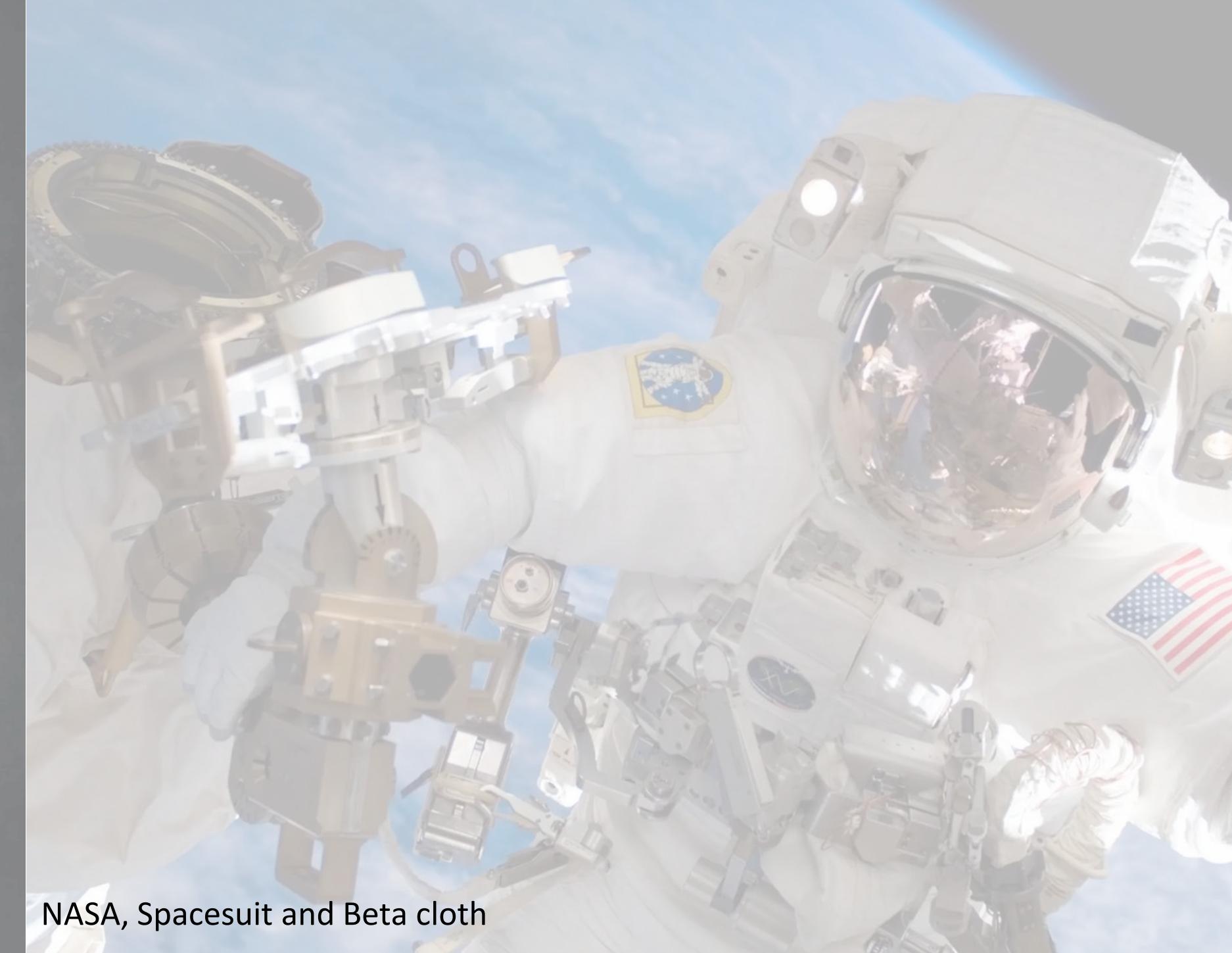
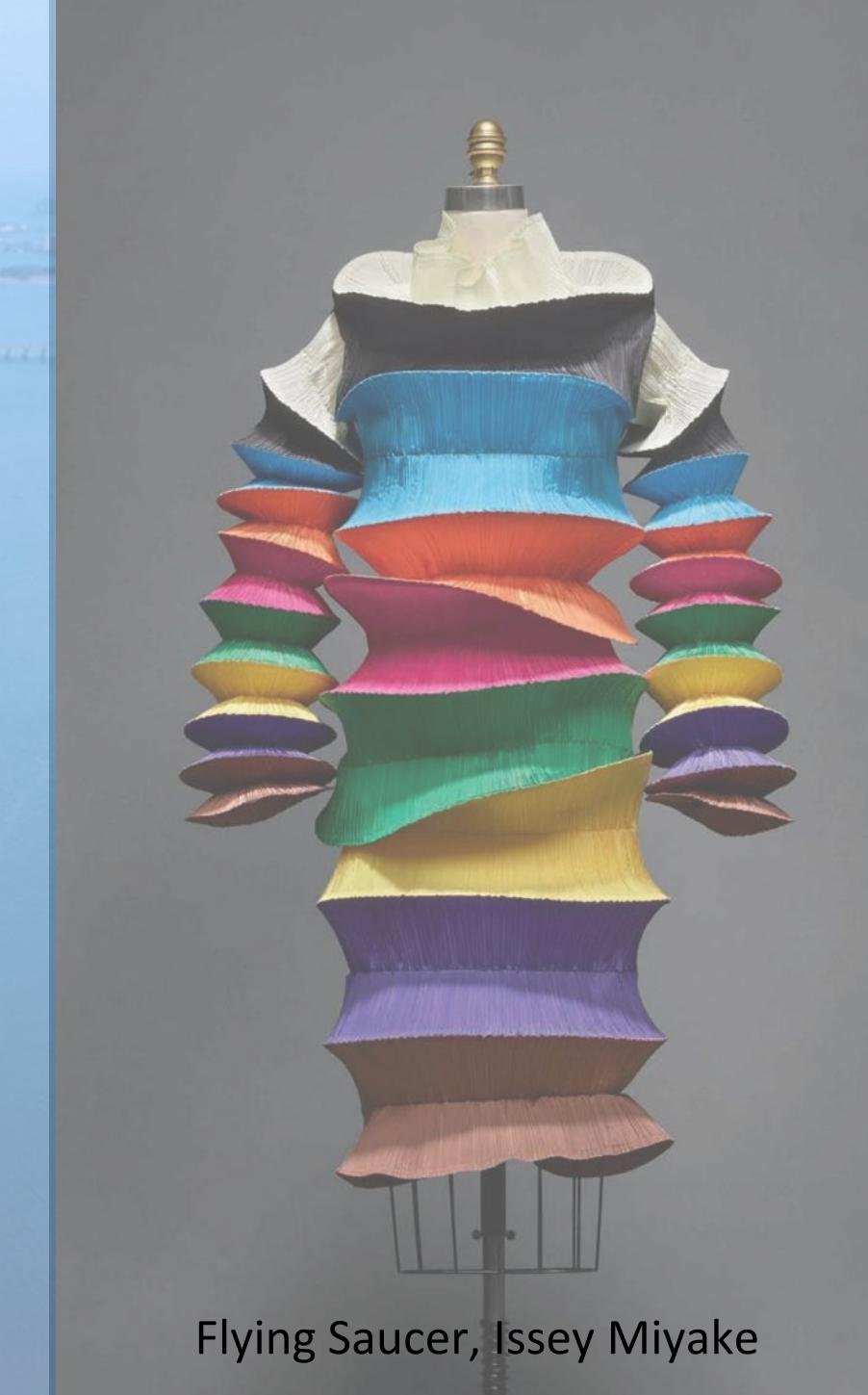
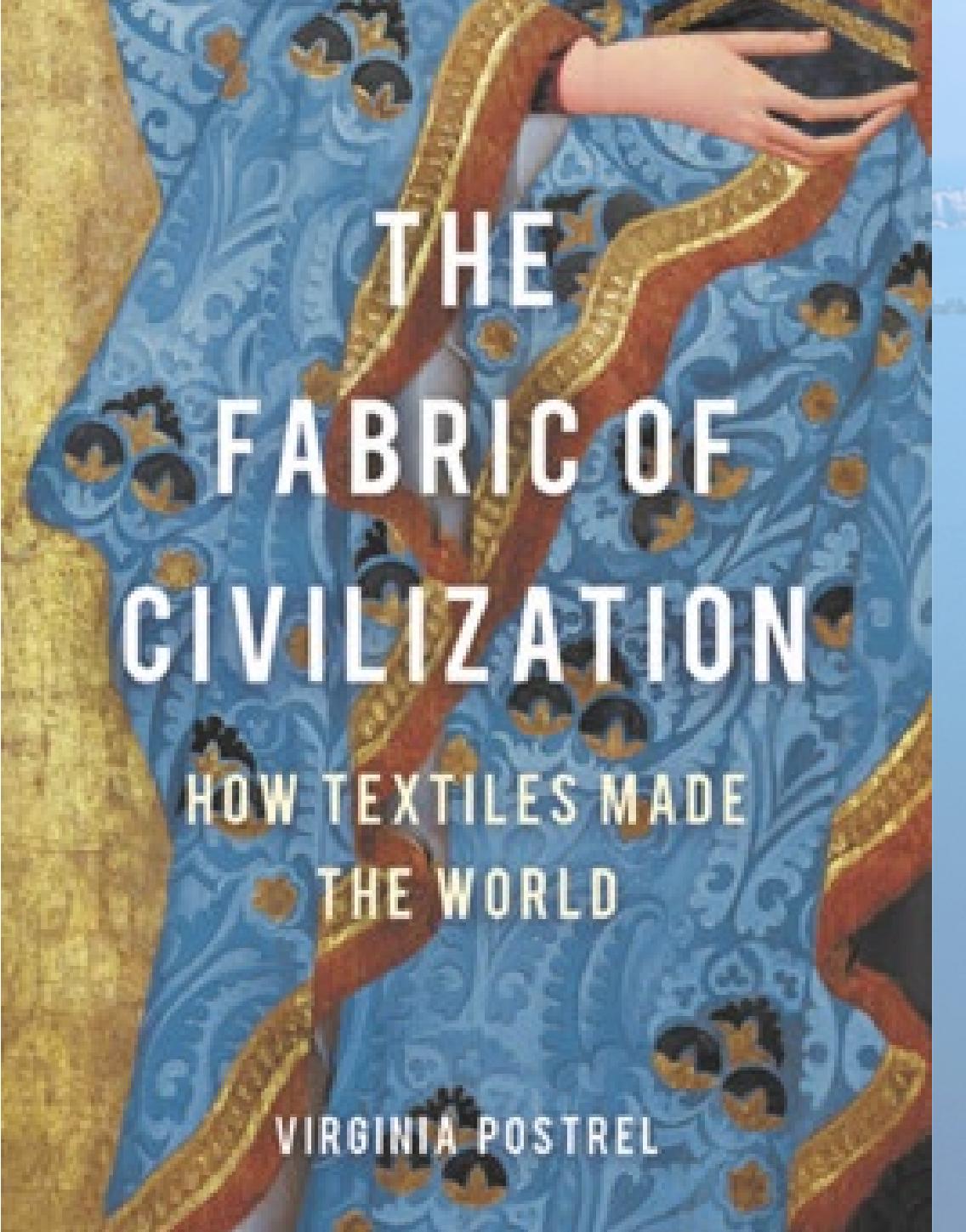
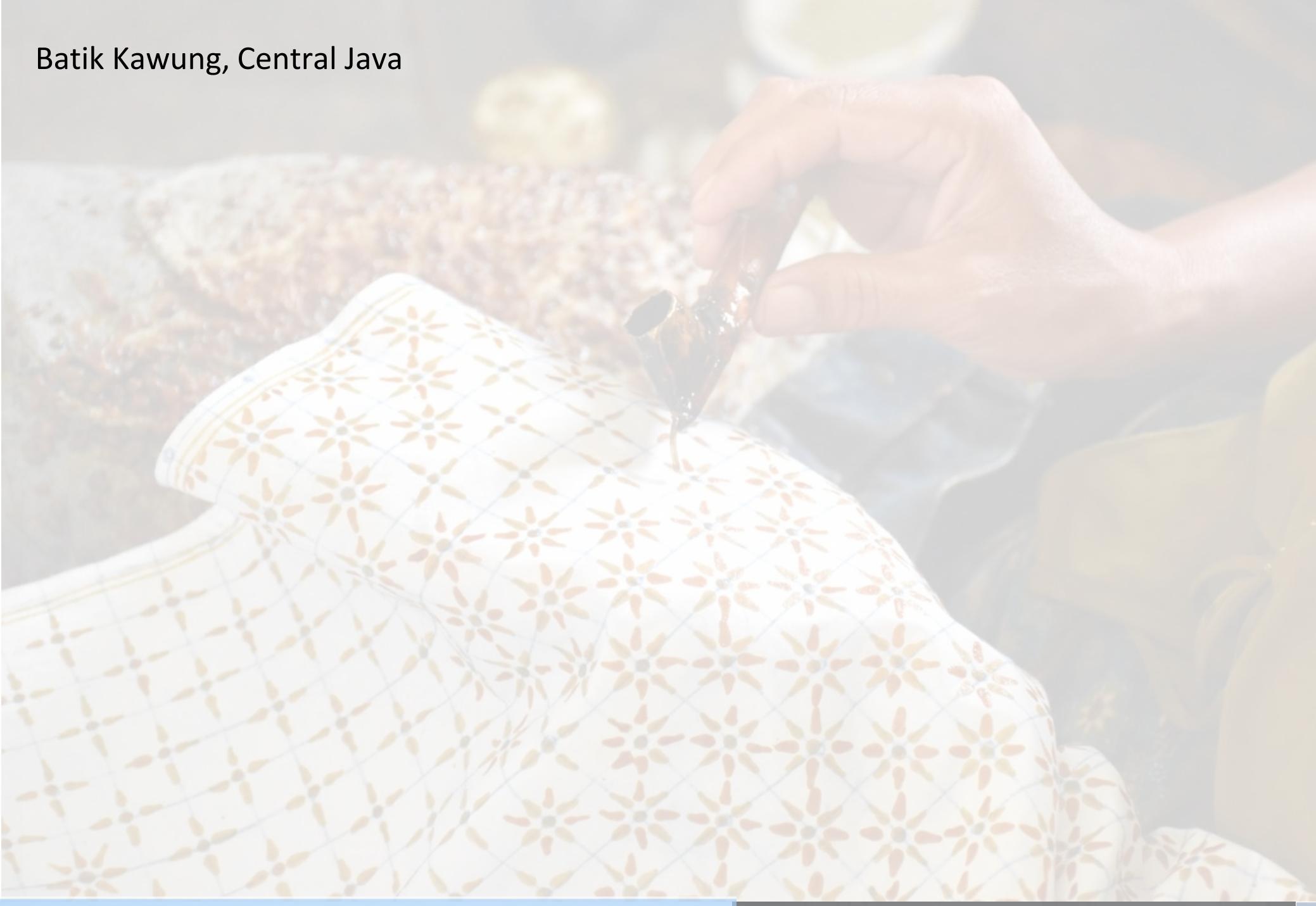
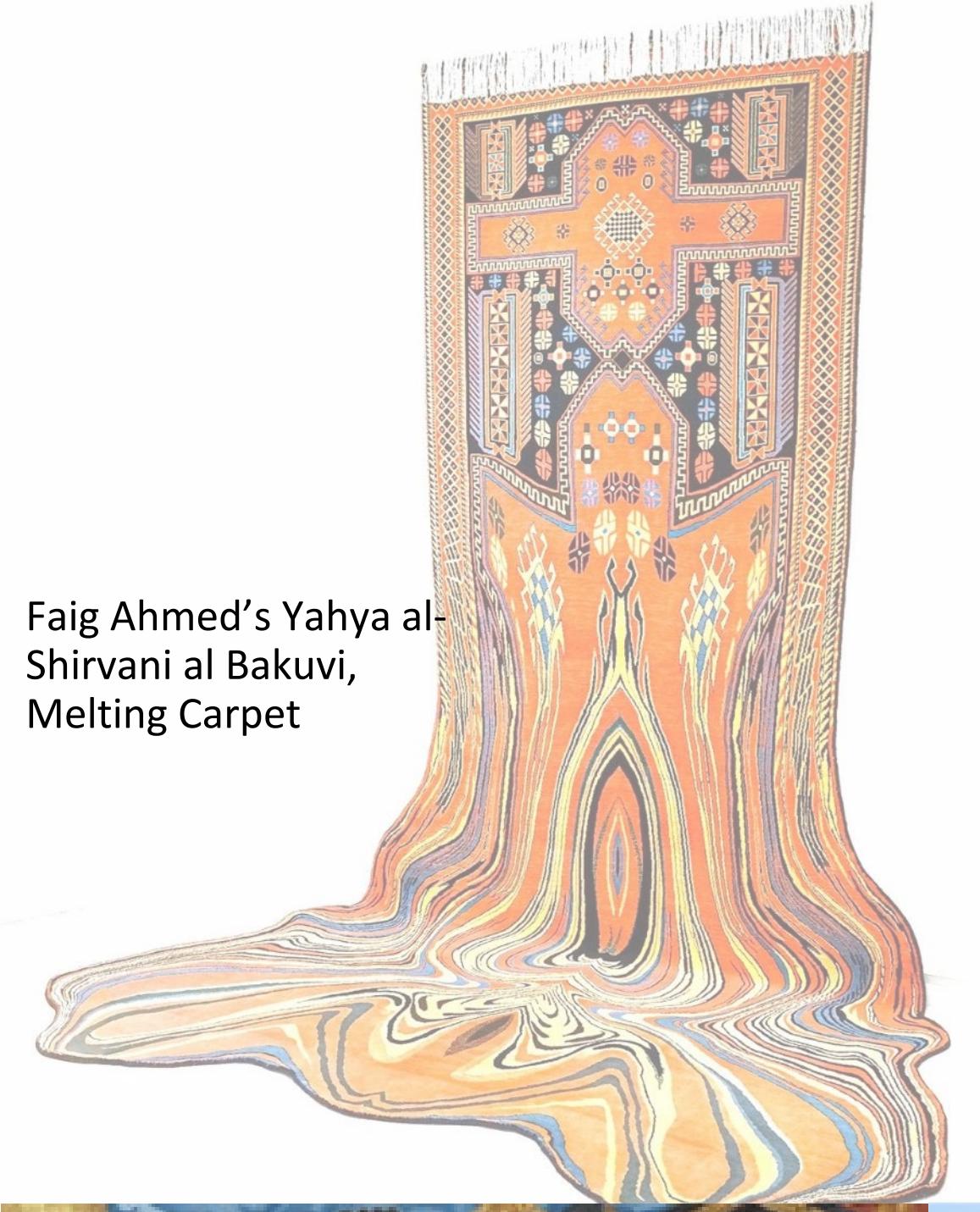
Textile Macroelectronics

Architecting Sensate and Computational Fabrics Across Scales

Irmandy Wicaksono (irmandy@mit.edu)

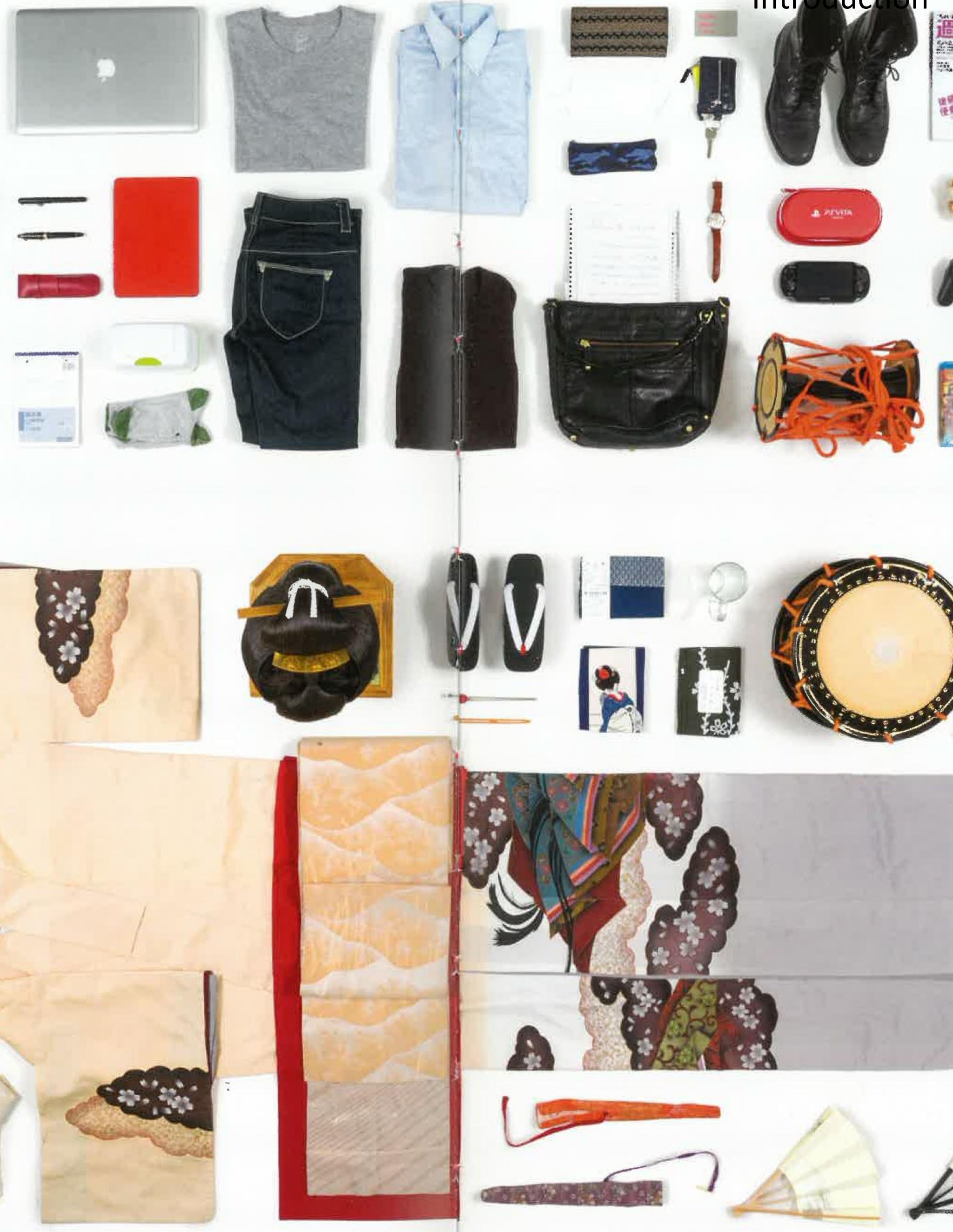
Research Affiliate, Responsive Environments, MIT Media Lab

Massachusetts Institute of Technology



Introduction

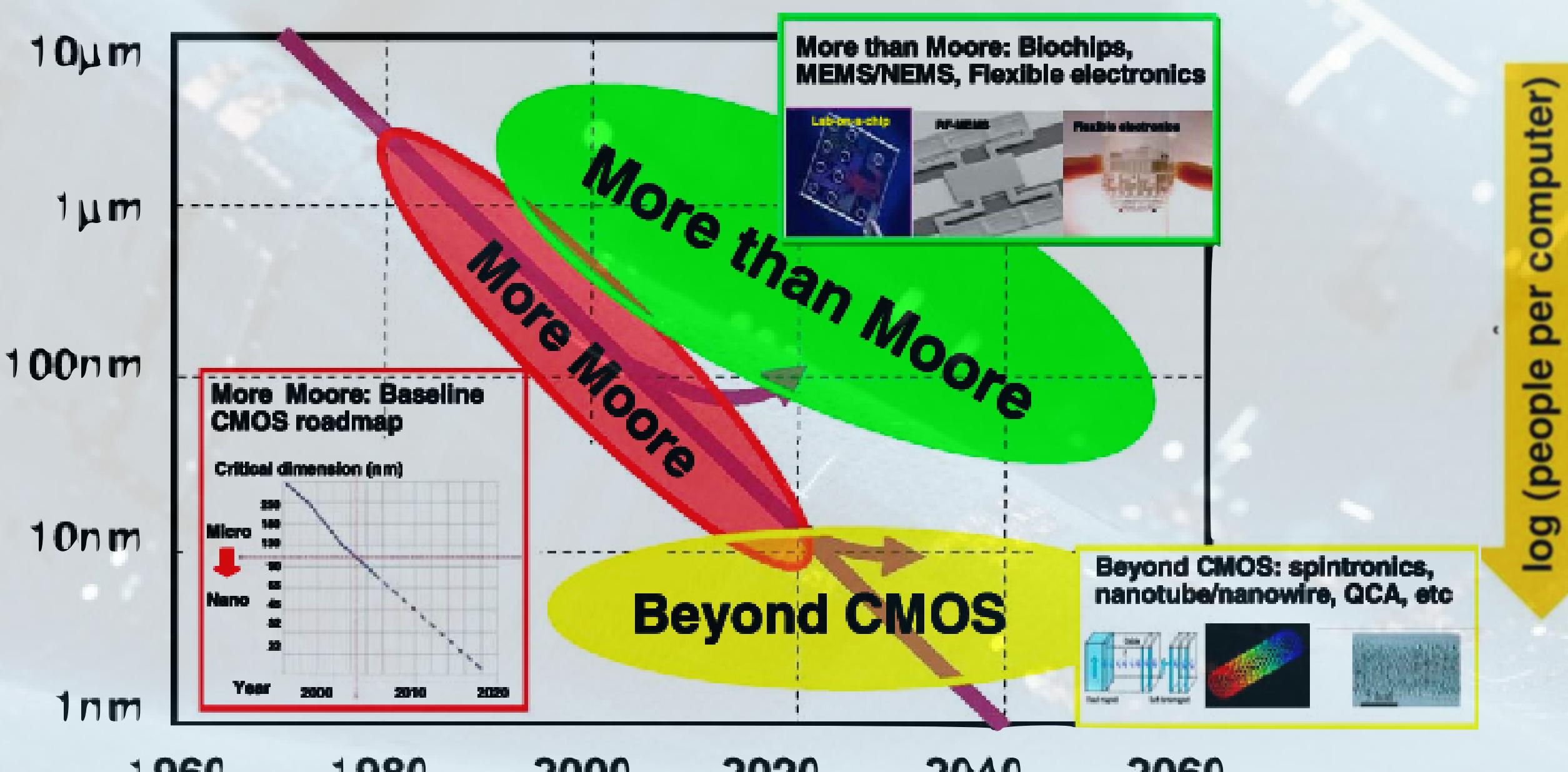
Paula Zuccotti Everything We Touch (2015)



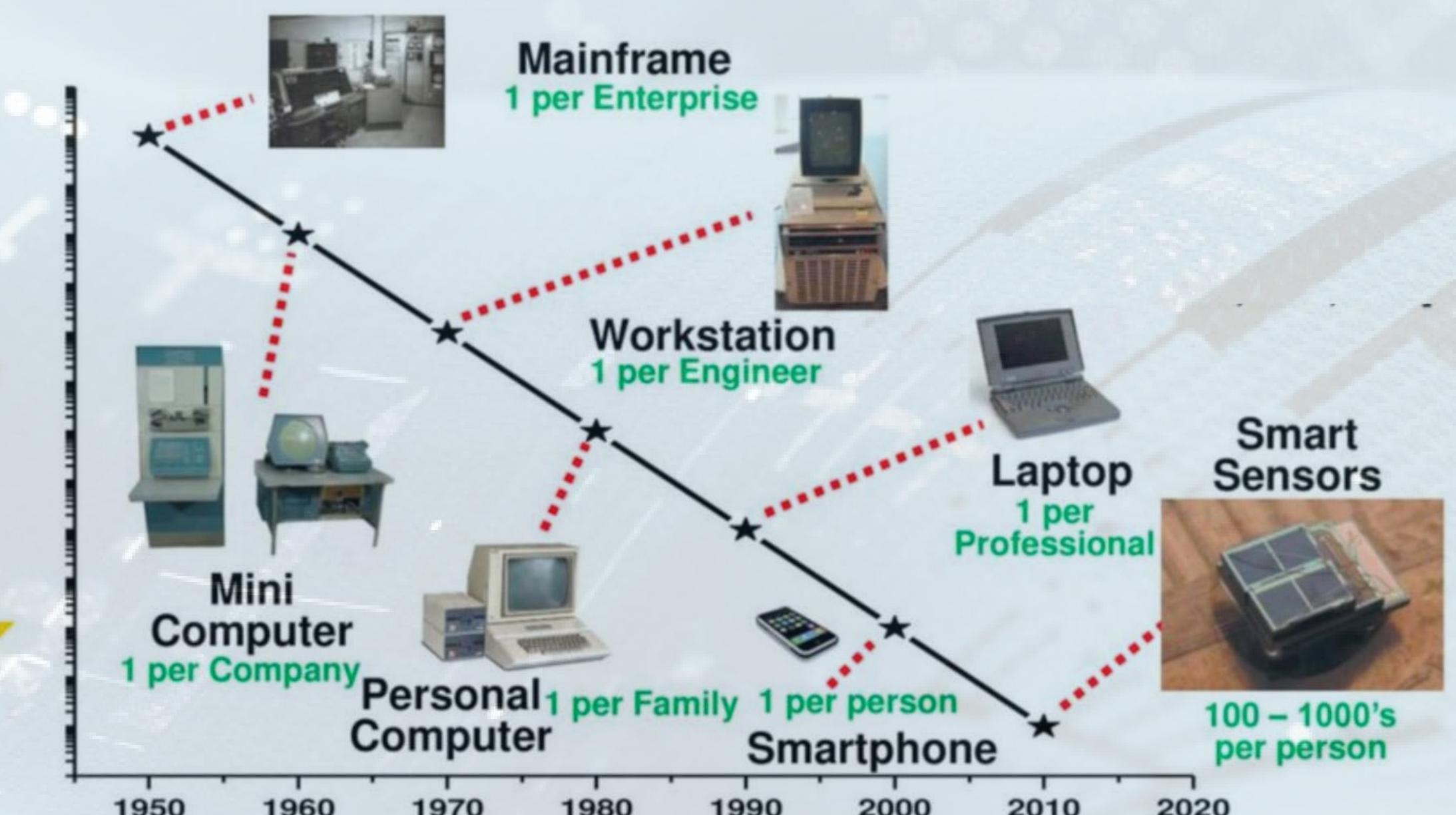
The Computer for the 21st Century (1991)

“The most profound technologies are those that disappear. They weave themselves into the *fabric of everyday life* until they are indistinguishable from it”. *Mark Weiser*

Moore's and Bell's Law: A Ubiquitous Computing Era



Roy et al., IEEE Design and Test (2013)



Macroelectronics

Robert H. Reuss, Darrel G. Hopper, and
Jae-Geun Park, Guest Editors

Abstract

As revolutionary as microelectronics has been as a technology, there are functions that it does not address. Microelectronics focuses on ever-smaller integrated circuits (ICs) in ever-fewer square millimeters of space to increase clock speeds and decrease the power required for computer processing functions. However, applications requiring control, communications, computing, and sensing over a large area are difficult or cost-prohibitive to achieve because of the material incompatibilities of traditional ICs with structures, materials, and manufacturing technology. Macroelectronics addresses these applications with the aim of providing active control circuitry *in situ* over areas of many square meters for displays, solar panels, x-ray imagers, surface measurements, structural shape control, vehicle health monitoring, and other large-system applications. The materials challenges of macroelectronics integrated circuits (MEICs) reviewed in this issue include lightweight flexible substrates, thin-film transistors (TFTs) with IC or near-IC performance, modeling, and manufacturing technology. Compatible component materials, flexible substrates, processing conditions, host system composition, and functionality provide grand challenges that are just beginning to be addressed by researchers.

Keywords: electronic material, lithography, sensor.

Electronic devices have become increasingly pervasive over the last 50 years. Advances have been driven primarily by microelectronics, based on the well-known Moore's law that describes the increasing complexity (and therefore performance) as feature size decreases over time. While there are many issues to be addressed, as described by ITRS roadmap,¹ the mainstream microelectronics industry continues to provide ever-increasing performance and functionality. However, other forms of electronics have also become important, as they address problems that conventional microelectronics cannot. The most significant of these is the display industry, which now rivals the integrated-circuit (IC) industry in terms of revenue. The technical drivers for these two major industries are essentially opposite. While the IC industry strives to make the smallest possible devices in the smallest possible area, the display industry is interested in large devices over the largest possible area. This drive to distribute the devices over large areas can be considered "macroelectronics," because neither the active devices nor the area they cover needs to be "micro" in scale.

Commercially viable macroelectronics began in 1988 with thin-film-transistor-based liquid-crystal displays (TFT-LCDs). Direct-view active-matrix liquid-crystal

displays (AMLCDs) based on inorganic TFTs on glass substrates represent the first commercial success of macroelectronics. Sales of AMLCDs have superseded the cathode-ray tube in both revenue (2002) and units (2004) to become the dominant display technology on the planet.² Examples include the demonstration by Samsung in 2005 of an 82-in.-diagonal screen with six million TFTs controlling the brightness of each of two million color pixels (see Figure 1); a 100-in. AMLCD, announced by LG.Philips LCD Co. in January 2006; and an IBM monitor product introduced in 2002 with a 22.2-in.-diagonal screen, 27 million TFTs controlling 9.1 million (3840 × 2400) color pixels, and a TFT vertical/horizontal pitch of 124.5/41.5 μm. These TFT pitches are about a thousand times larger than those found in ICs. This difference in transistor density may be used as one way to distinguish macroelectronics ICs (MEICs) from classical metal oxide semiconductor field-effect transistor ICs.

Beyond the dominant AMLCD technology, several niche display technologies also use TFT backplanes to drive pixels over large areas and thus are considered examples of macroelectronics. Examples include displays based on organic light-emitting devices, electroluminescent elec-

trophoretic ink, and field-emission mechanisms. Other large-area display technologies are not macroelectronics, as they do not have MEICs built into them. Examples include inorganic light-emitting diodes (LEDs), vacuum cathode-ray tubes (CRTs), and most plasma technologies. The LEDs now popular for jumbo-size outdoor displays in stadiums, billboards, and building facades are not macroelectronics, because they are driven externally by personal computers, not internally by TFT MEICs. The CRT vacuum technologies are driven by analog electronics (e-guns and deflection coils) and are not even digital, let alone macroelectronic. Drive voltages and power are also a distinguishing factor. TFT technologies typically operate at 3–5 V, drawing 1–10 W, compared with 1–20 keV and 1–10 kW, variously, for plasma, CRT, and LED displays. The pixel size in LEDs and plasma are also issues: millions of LEDs are separately packaged and hand-mounted with 10-mm pitch in arrays meant for viewing at hundreds of feet.

Some potential future application areas for macroelectronics are illustrated in Figure 2. These areas include displays (top left and top right), sensors (top right and bottom right), energy harvesting (top right and bottom left), electronics embedded into gear (radios, range finders, computers) and clothing (bottom left), and structural health monitoring of vehicles or humans (bottom right). Structural health monitoring involves a range of sensors, processors, and transmitters built with flexible MEICs within vehicle composite materials to actively sense and report faults, or mounted on/in human biomaterials (skin/tissues) to continuously sense and transmit physiological and cognitive status. The weight and materials integration issues with ICs make these applications impossible or unlikely with a purely microelectronics approach and thus require macroelectronics.

The biggest challenge for macroelectronics technology is to enable applications beyond displays that involve large areas and volumes that cannot be cost-effectively achieved through traditional packaged-chip fabrication followed by pick-and-place assembly and that nonetheless require sophisticated, high-performance circuits. The large scale of macrosystems gives rise to the requirement for properties heretofore not associated with IC applications, such as thinness, ductility, and elasticity of electronic components, even during operation. Depending on specific applications, some design rules for traditional ICs must be maintained (e.g., length of transistor channels) and others relaxed (e.g., area of circuit layout).

As revolutionary as microelectronics and functional devices have been a focus in the last decade, there are challenges that it does not address to incorporate them into our everyday products.

"Applications requiring control, communications, computing, and sensing over a large area are difficult or cost prohibitive to achieve because of the material incompatibilities of traditional ICs with structures, materials, and manufacturing technology."

Reuss, Hopper, and Parl, MRS Bulletin (2006)

www.mrs.org/bulletin

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Wicaksono, Cherston, and Paradiso, IEEE PvC (2021)

THEME ARTICLE: COMPUTATIONAL MATERIALS

Electronic Textile Gaia: Ubiquitous Computational Substrates Across Geometric Scales

Irmandy Wicaksono , Juliana Cherston, and Joseph A. Paradiso , MIT Media Lab, Massachusetts Institute of Technology, Cambridge, MA, 02139-4307, USA

From in-body implantables to geotextiles and large-area spacecraft blankets, electronic fabric is now poised to operate across geometric scales that span many orders of magnitude, and thus across operational contexts with divergent material resiliency requirements, reaching far beyond the wearable device regime that is typically considered. This article reviews the key technical trends and lingering hurdles that are relevant to using functional fibers and e-textiles for operating at disparate scales—from microns to kilometers. We focus in particular on leveraging the unique material properties of a textile and the miniaturization of electronic devices in concert with the revolution in mass-manufacturing and digital fabrication technologies used to customize the device at the level of polymer, fiber, fabric, three-dimensional form, and system. We also offer a personal perspective on interdisciplinary collaboration between engineers, scientists, designers, and manufacturers for tackling some of the challenges in scaling and translation of electronic textiles.

Today, we have up to 39 000 km long deep-sea optical fibers supporting communication between four continents, and we have deployed up to 30-km-long electrodynamic tethers on orbit around Earth to harvest power from the magnetosphere. We have developed hundred micron-scale multisensory neural probes and millimeter-scale sensory meshes that can be injected into the body, alongside mesoscale fabrics with sensing, communication, and even locomotive capabilities. Functionalized fabrics now touch the full range of scales from microns to kilometers, with active and computational capability achieved at the level of fiber, yarn, fabric, and system. We consider our current place on the roadmap toward realizing an *electronic textile gaia* in which the living, nonliving, and increasingly the built environments operate as a single, harmonious, self-regulating organism, as imagined in Figure 1.

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Date of publication 8 June 2021; date of current version 30 July 2021.

The textile has achieved ubiquity for its manufacturing scalability and myriad beneficial properties—protection, three-axis conformability, abrasion resilience, tensile strength, heat retention, high packing density, and aesthetic and cultural appeal all serve to motivate adoption of this material form.

While most textiles have remained electrically passive, one may still claim that computational textiles had an early start—the Apollo spacecraft guidance and control software developed in the 1960s at MIT was stored in a woven substrate called core rope memory.

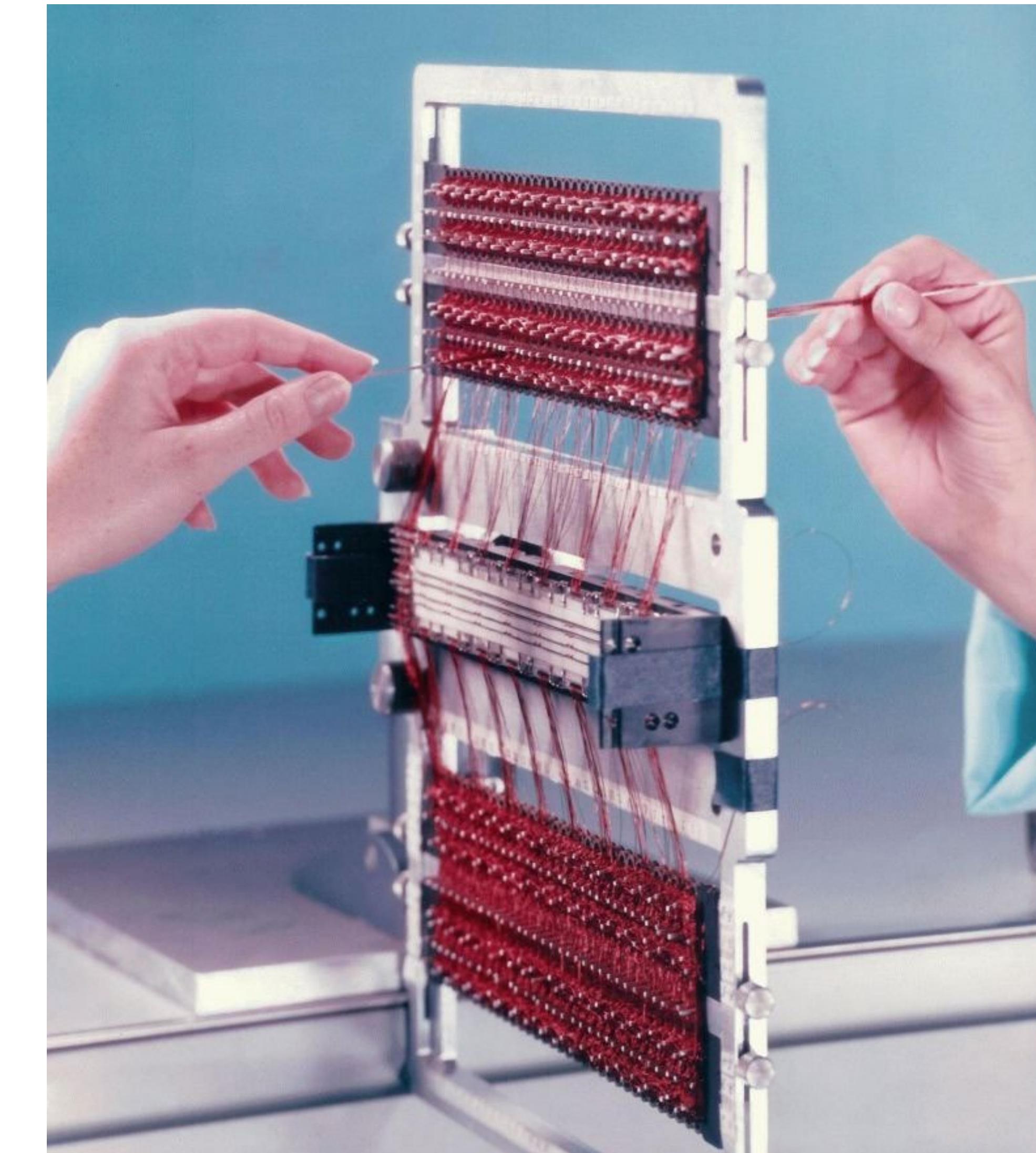
Around the same time, a company called Woven Electronics was spawned to develop fabric circuit board prototypes that were evidently well ahead of their time. For a fleeting moment in these early days of printed circuit board (PCB) manufacturing, woven fabric circuits and core rope memory were competitive with silicon semiconductor technology.

Early fabric-based electronics hint at deep links between manufacturing processes used in the textile and electronics industries that in some cases continue into the present era: dies draw down both electrical wires and fibers, lithography, and screen-printing

Textiles and Computation



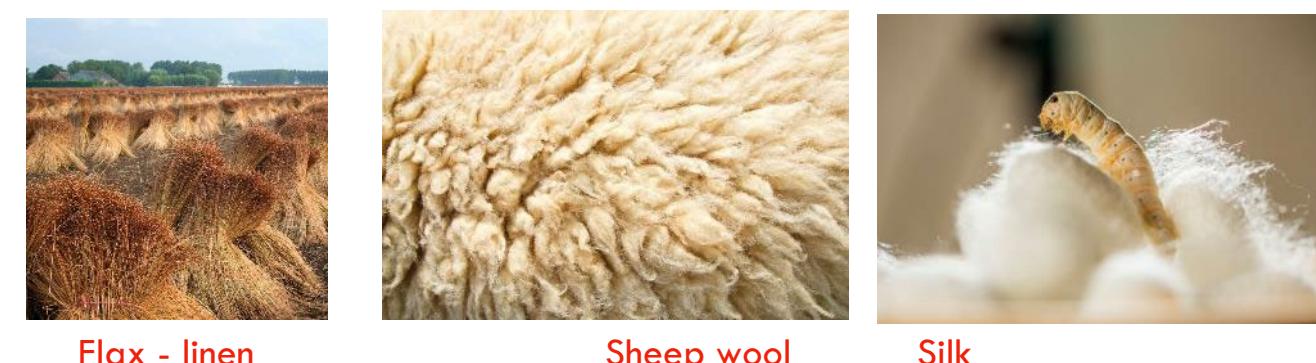
Jacquard Loom (1700)



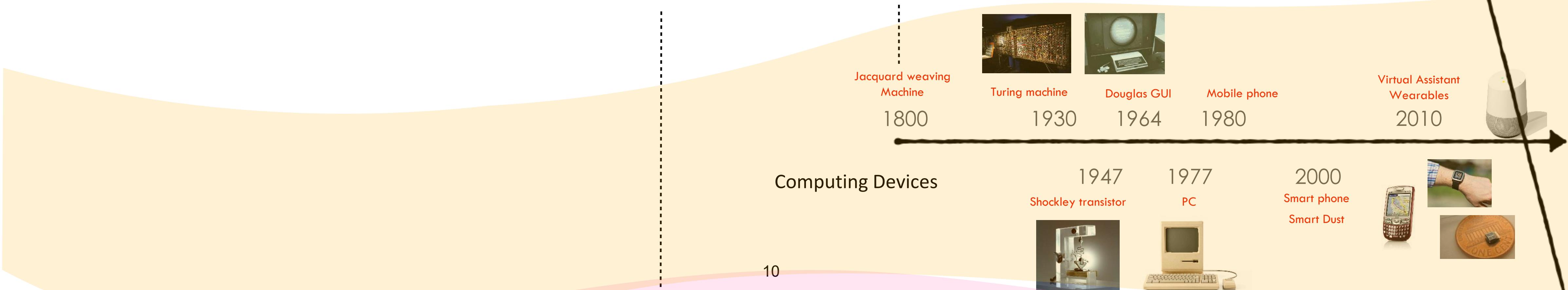
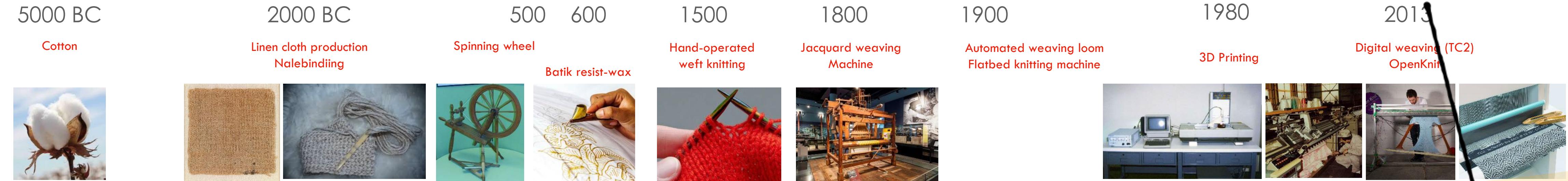
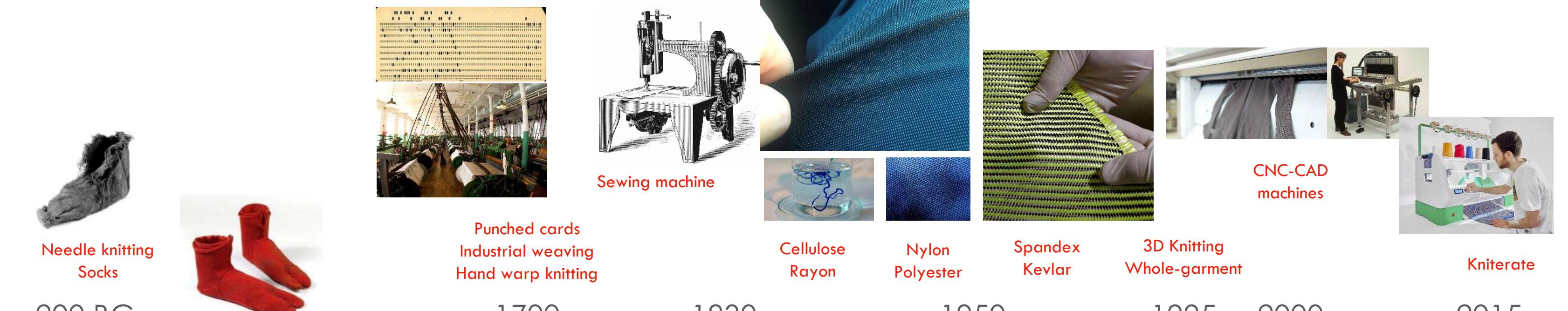
Core-rope Memory, MIT Project Apollo (1972)

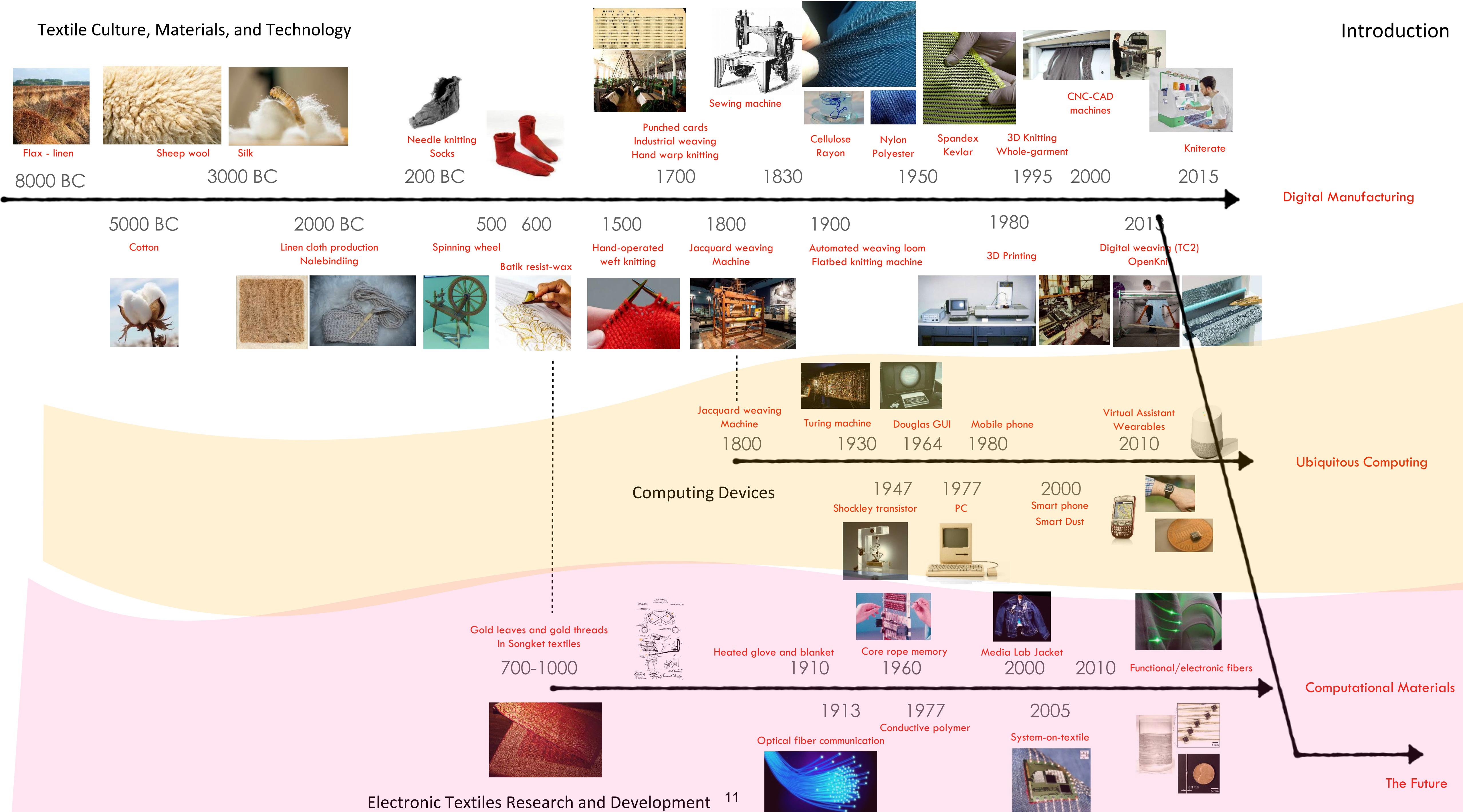
Textiles and Computation

Textile Culture, Materials, and Technology

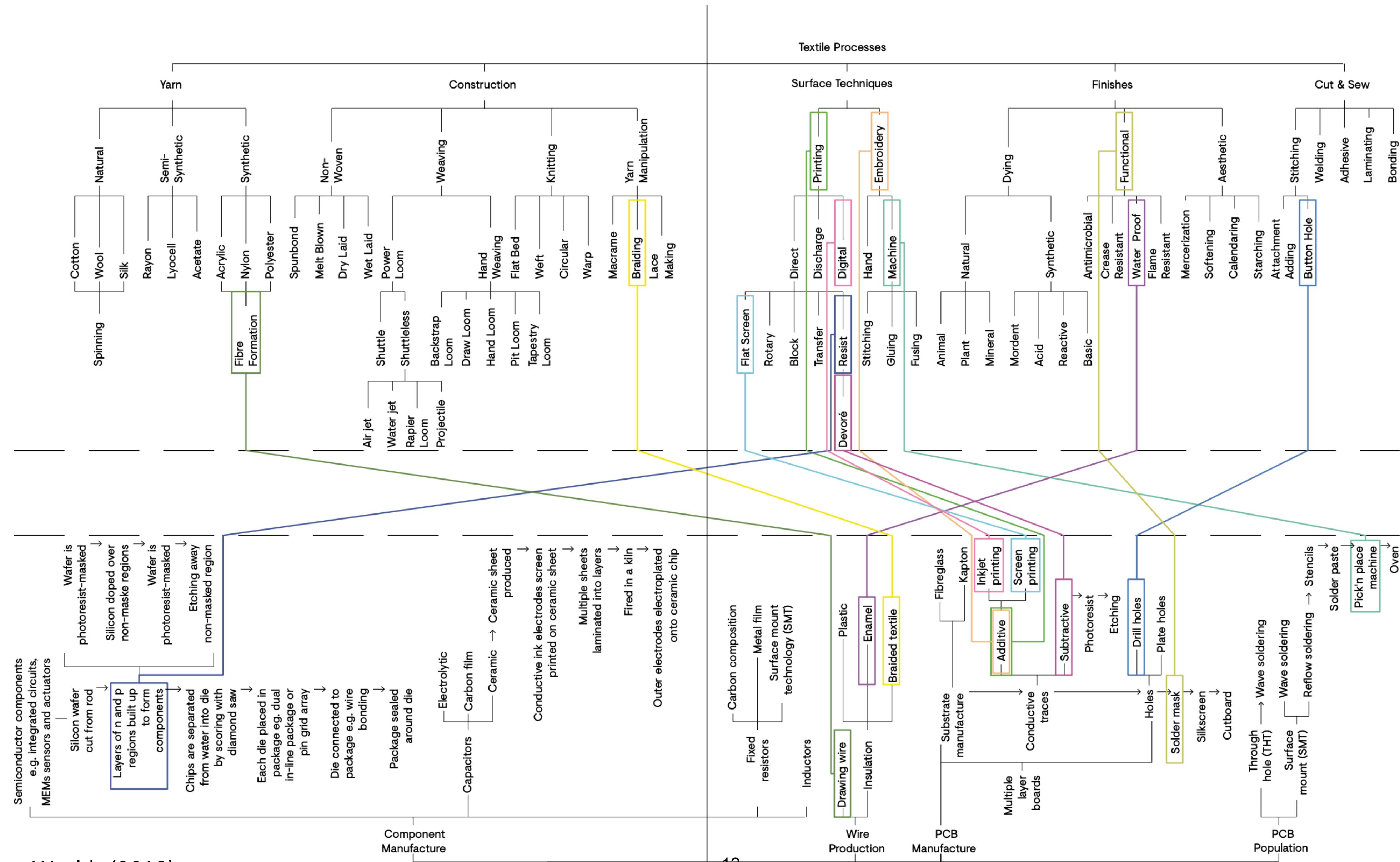


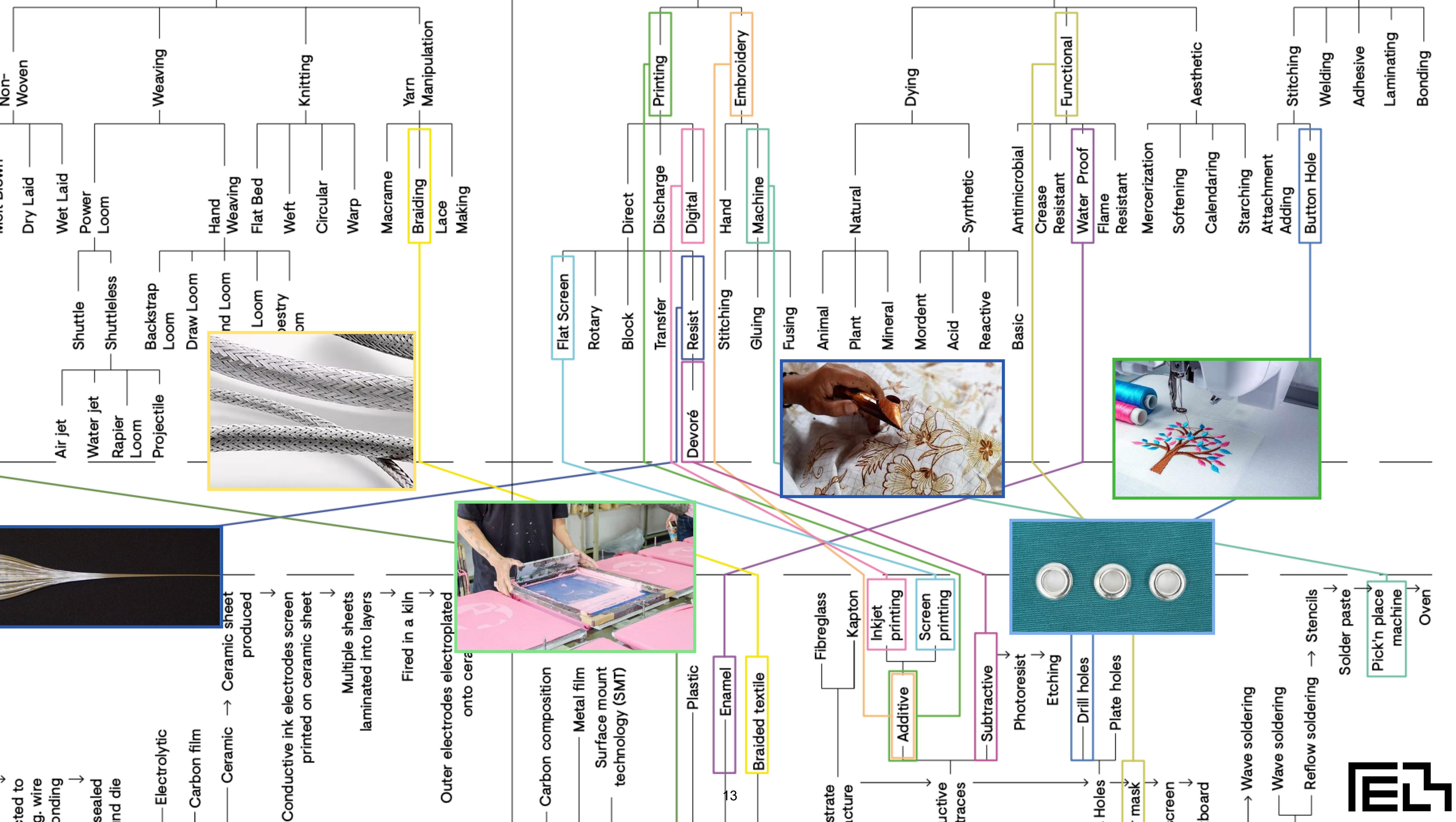
8000 BC 3000 BC 200 BC 1700 1830 1950 1995 2000 2015





Industrial Cross-Pollination Map (Textiles x Electronics)

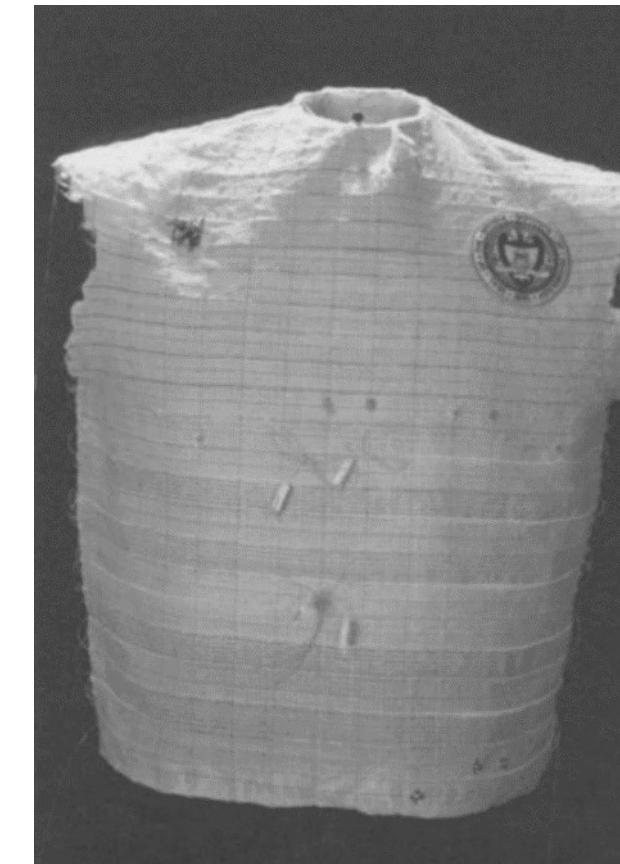




E-textiles: hand-crafted at the fabric-level



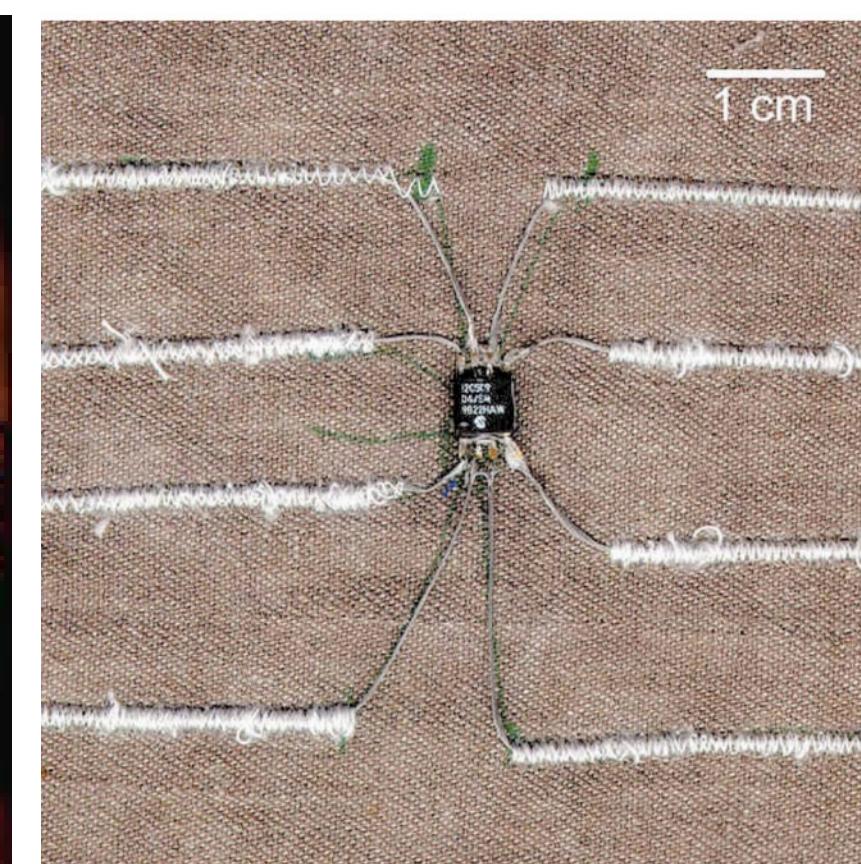
Musical Jacket
Orth, M *et al.*, SIGGRAPH (1998).



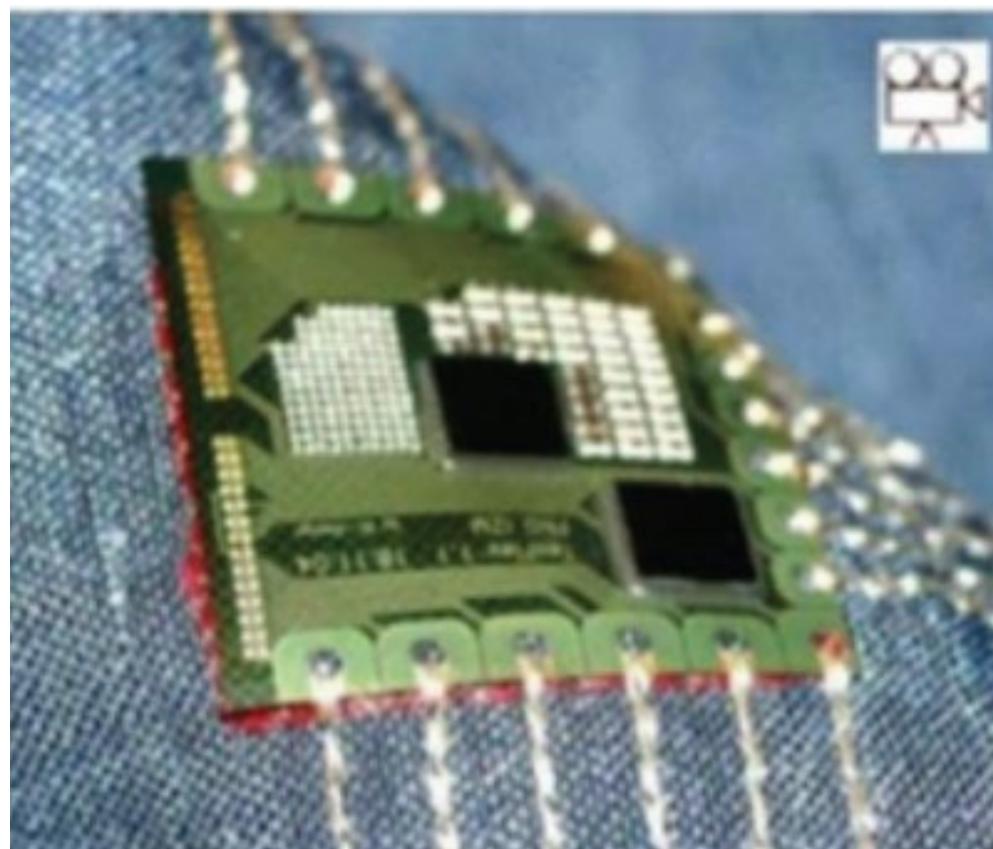
Wearable Motherboard
Gopalsamy, M *et al.*, (1999)



Musical Balls
Weinberg, G *et al.*, CHI (2000).



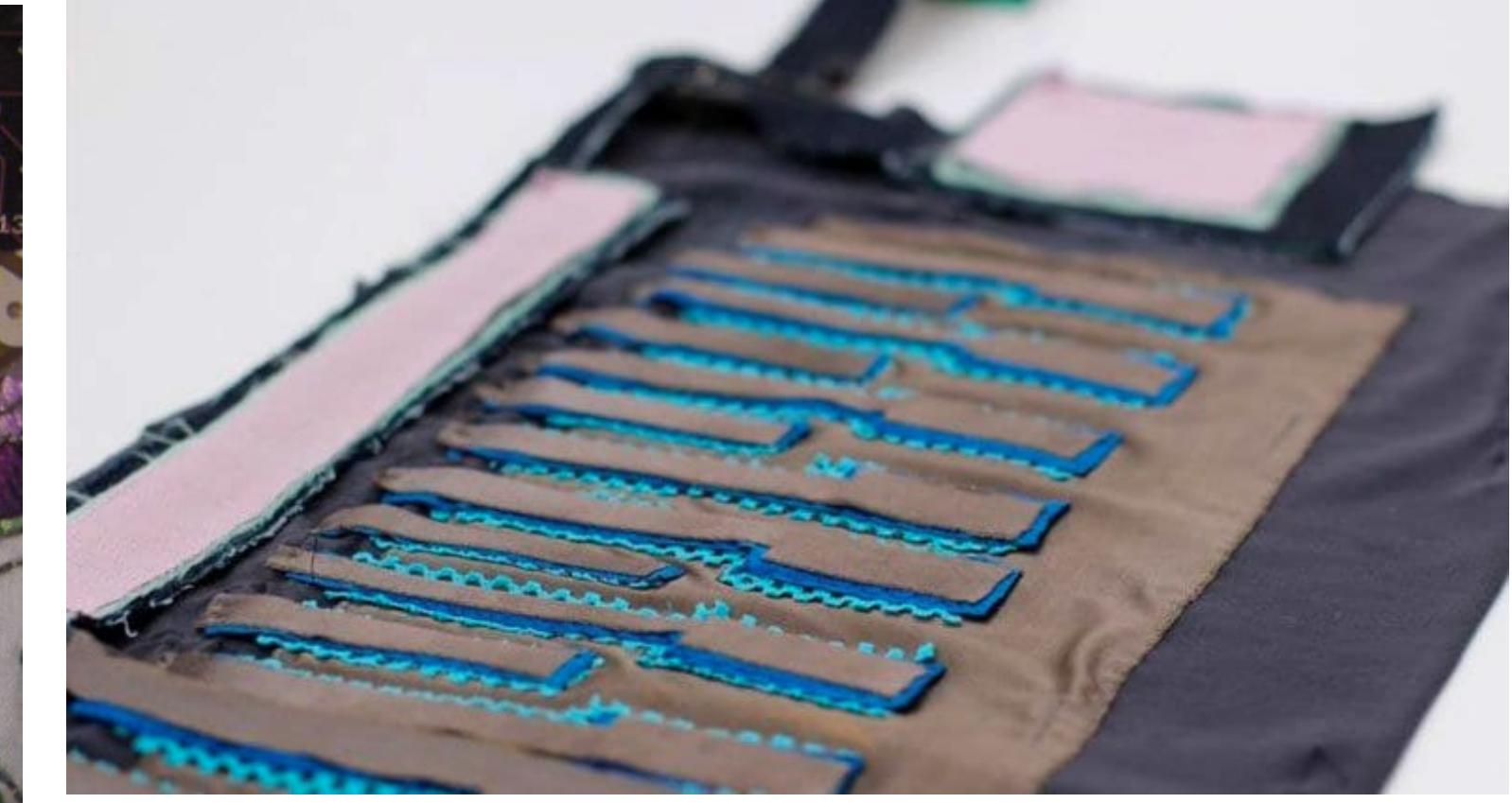
E-broidery: textile-based computing
Post, E.R. *et al.*, IBM Sys (2000).



Fully-integrated EKG Shirt
Linz *et al.*, BSN (2006).

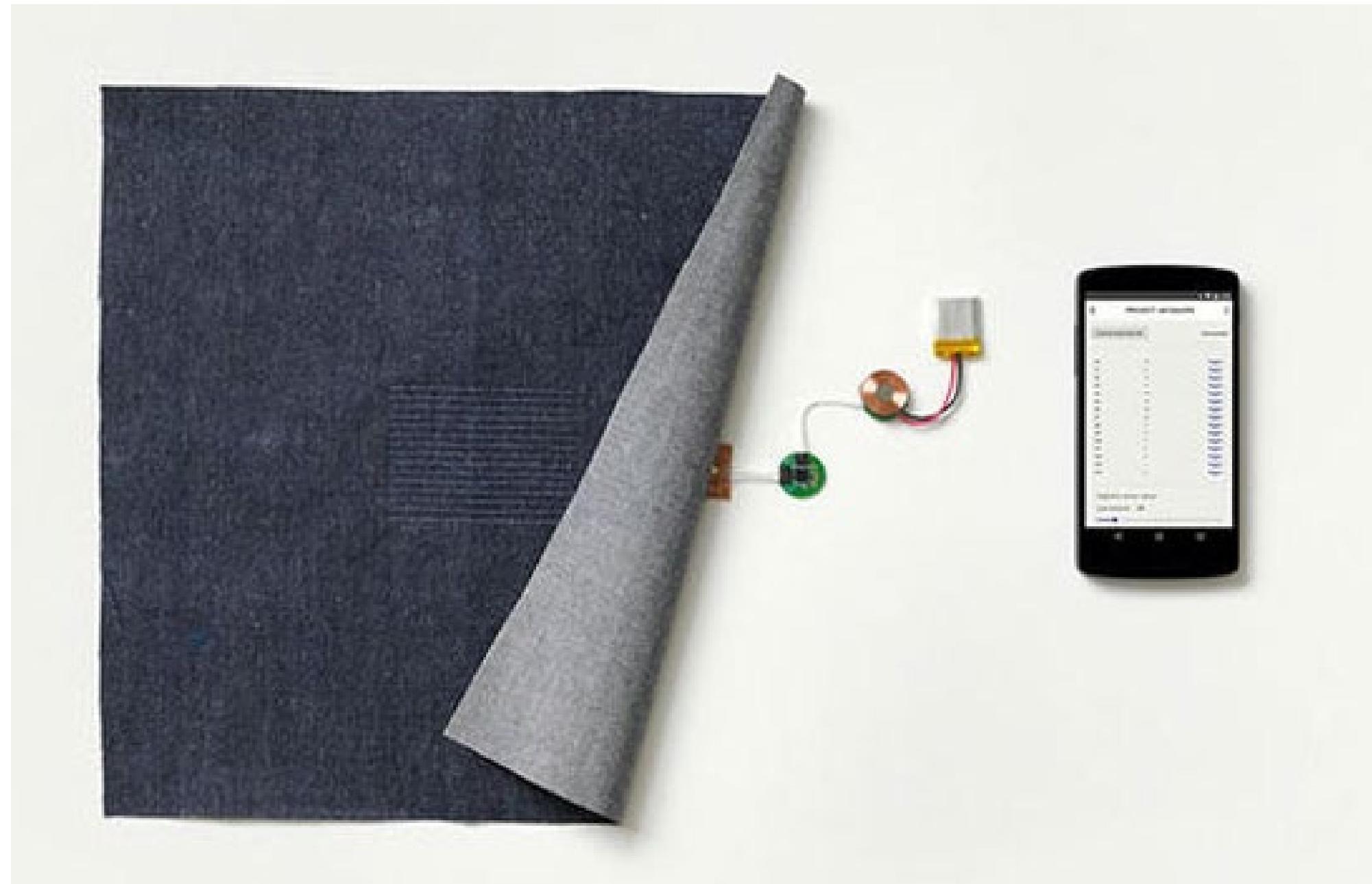


Fabric PCBS: e-textile craft
Buechley and Eisenberg, UbiComp (2009).

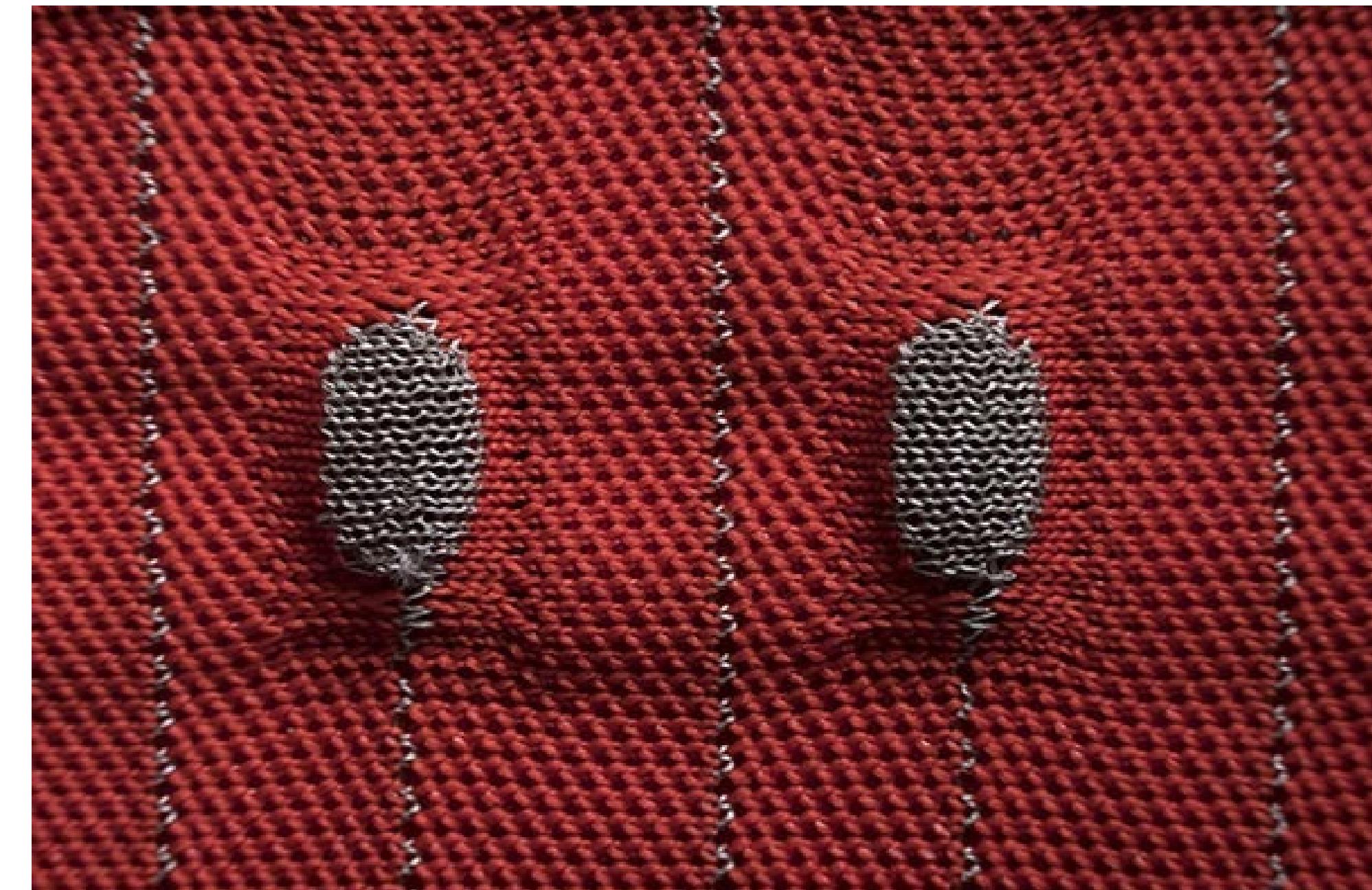


FabricKeyboard: Multi-modal E-textile Musical Interface
Wicaksono and Paradiso, NIME (2017).

E-textiles: industrial manufacturing from the yarn

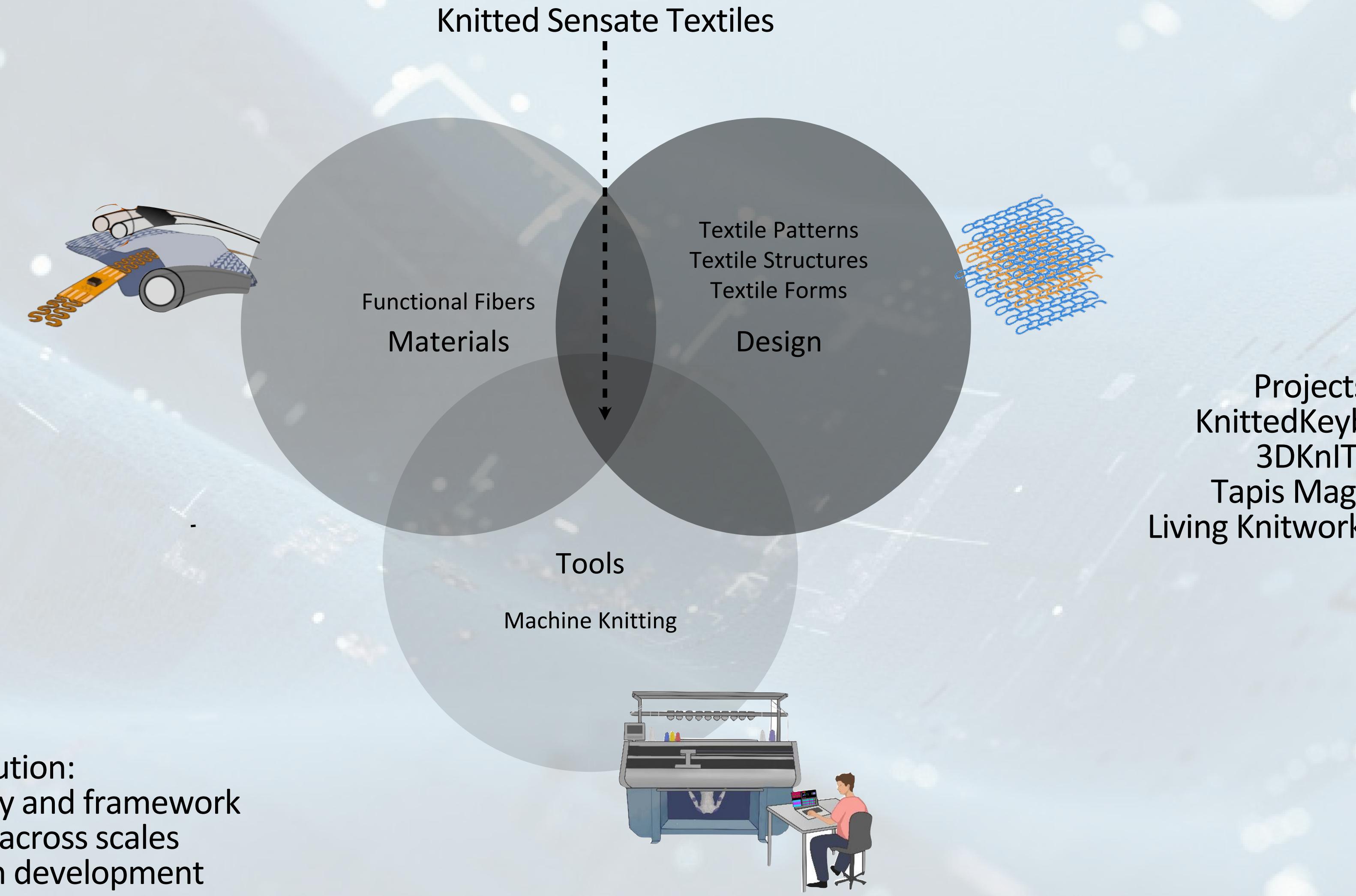


Project Jacquard
Poupyrev, I et al. ACM CHI (2016)

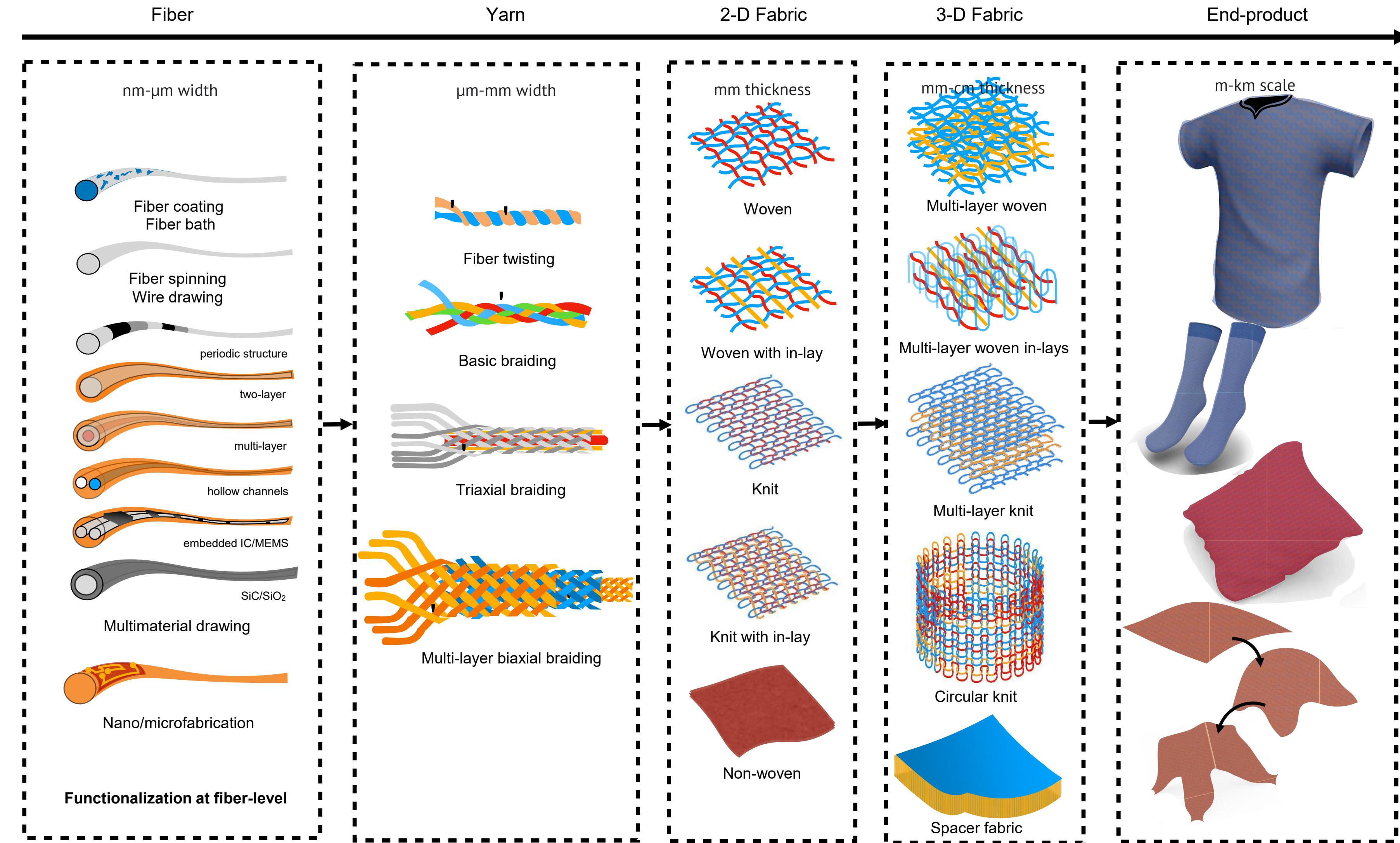


SensorKnit
Ou et al. 3DP (2019)

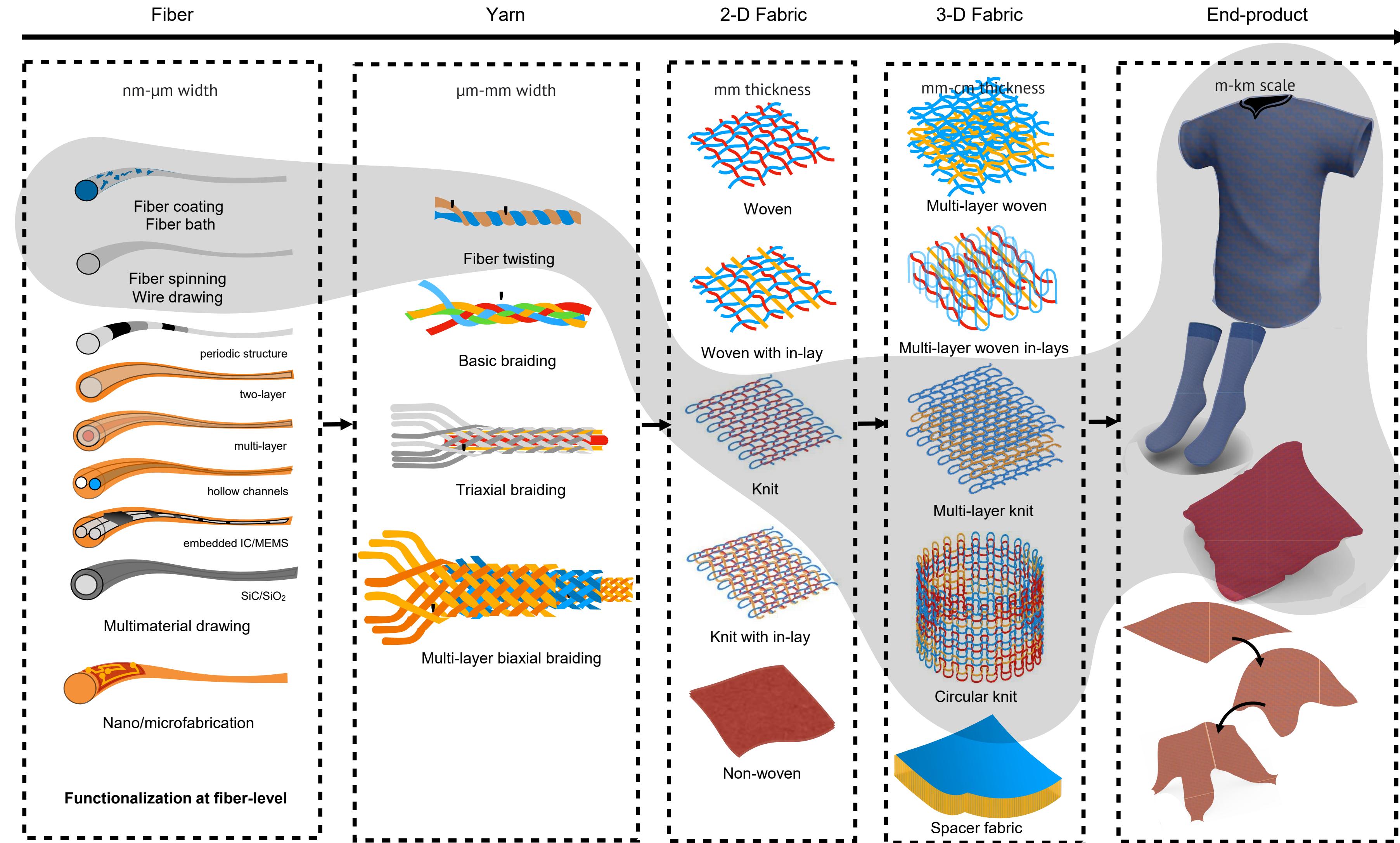
Digital Knitting of Sensate Textiles

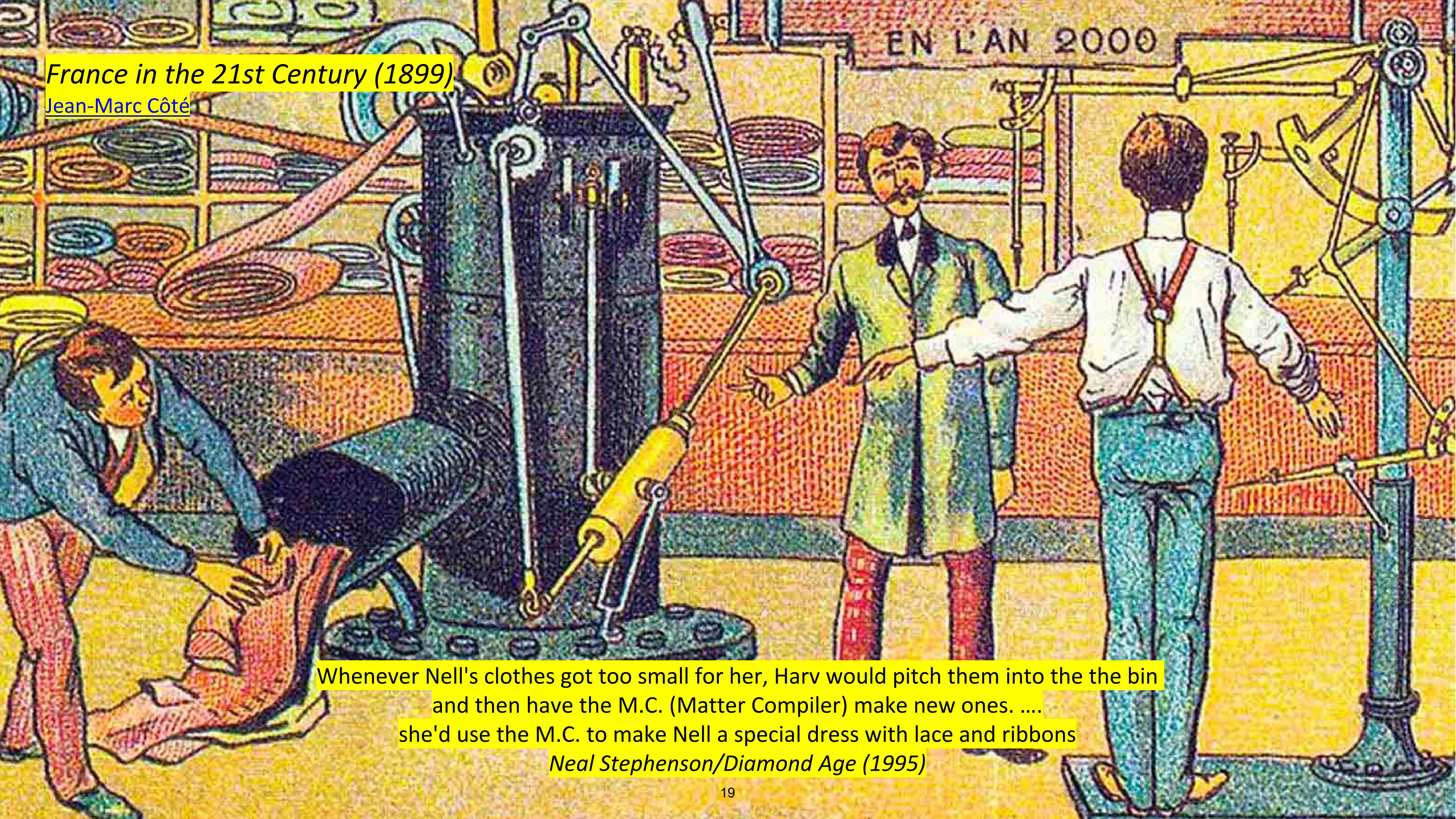


E-textiles: hierarchical architecture



E-textiles: hierarchical architecture





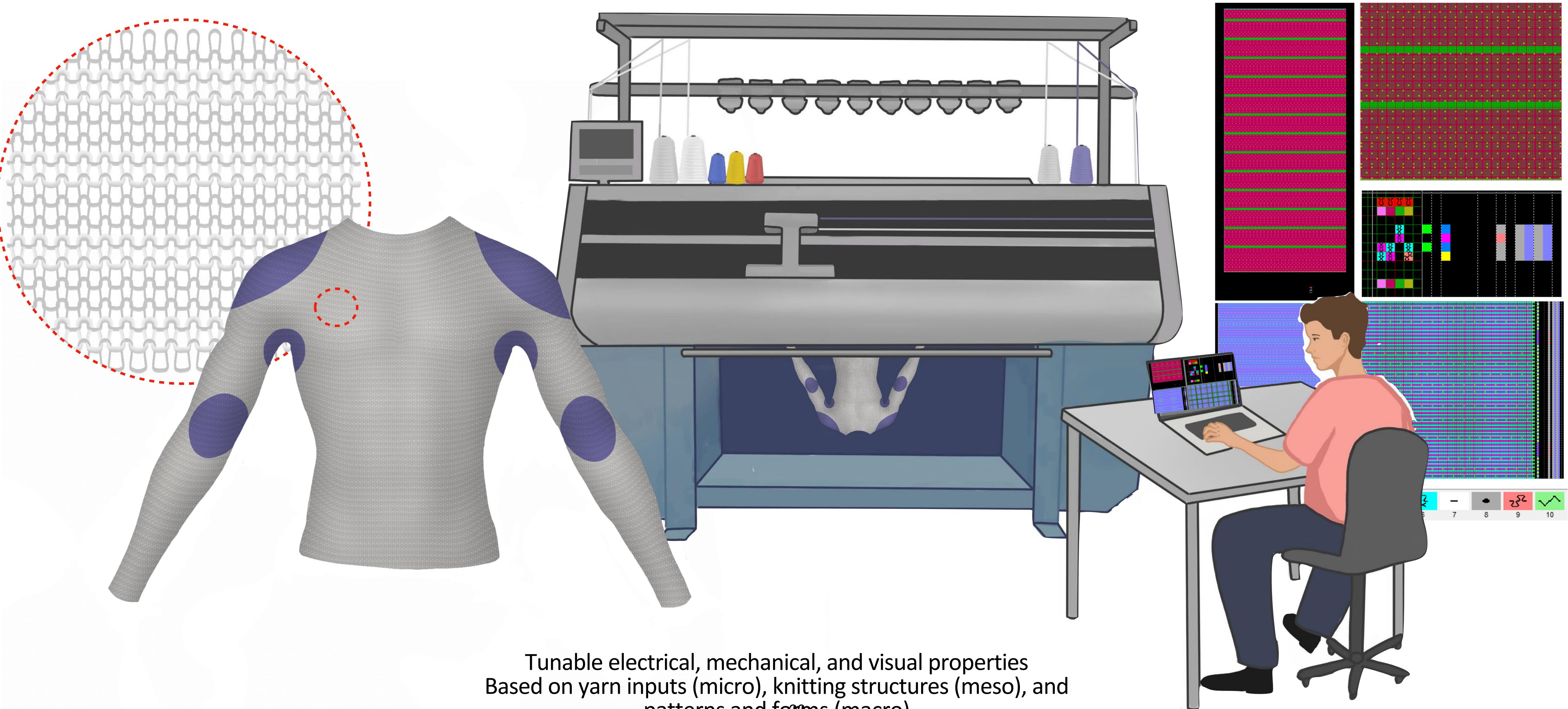
France in the 21st Century (1899)

Jean-Marc Côté

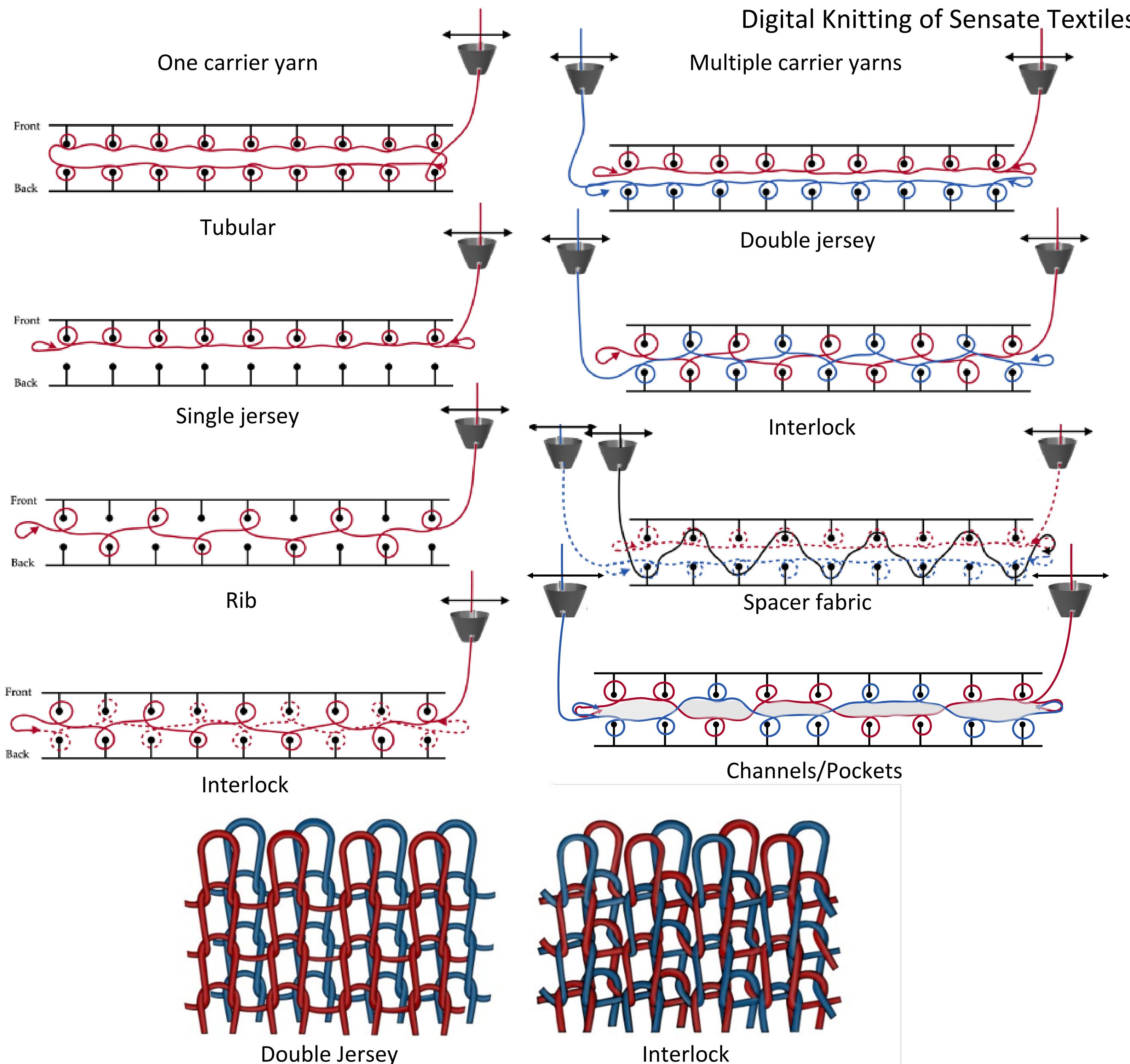
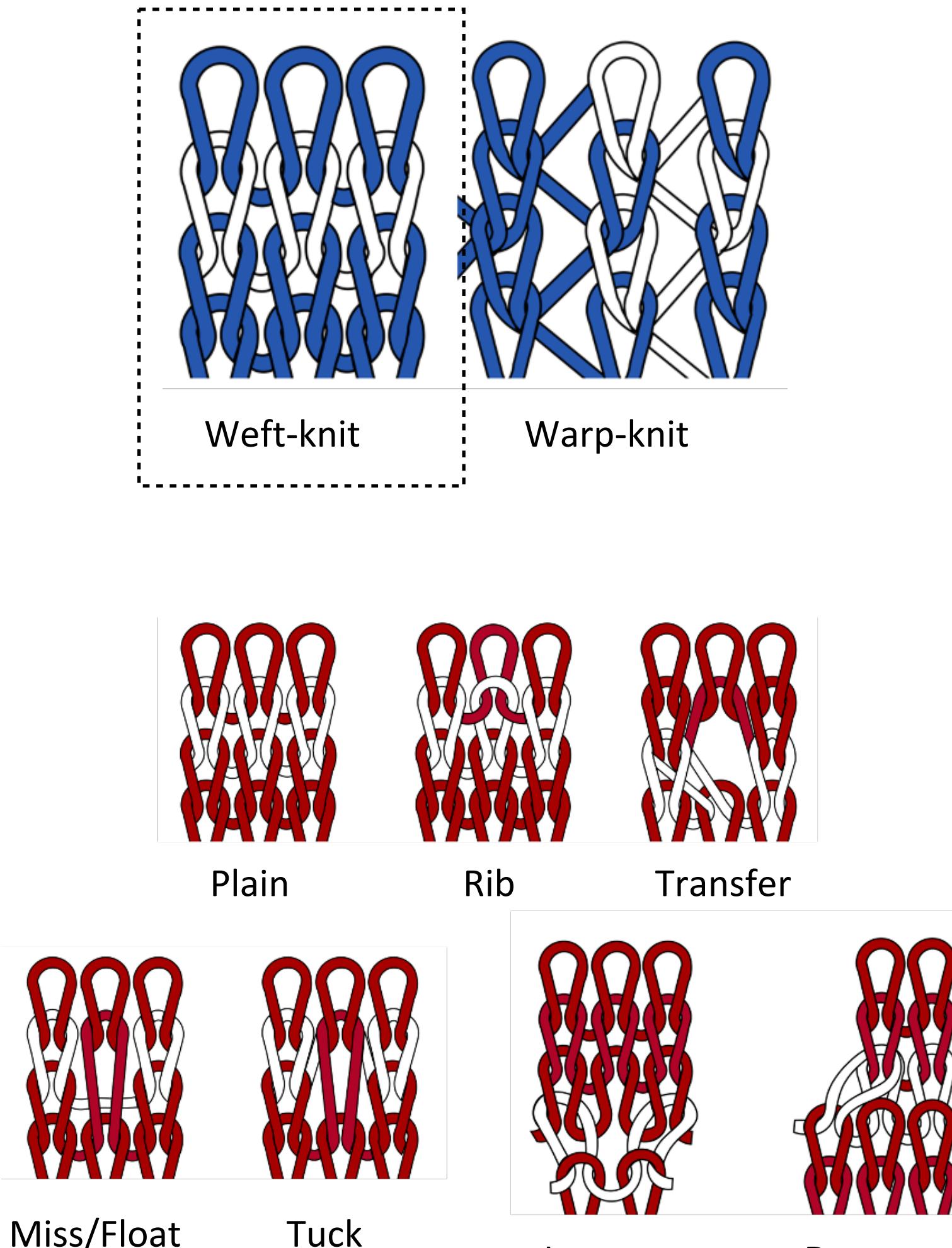
Whenever Nell's clothes got too small for her, Harv would pitch them into the bin
and then have the M.C. (Matter Compiler) make new ones.
she'd use the M.C. to make Nell a special dress with lace and ribbons

Neal Stephenson/Diamond Age (1995)

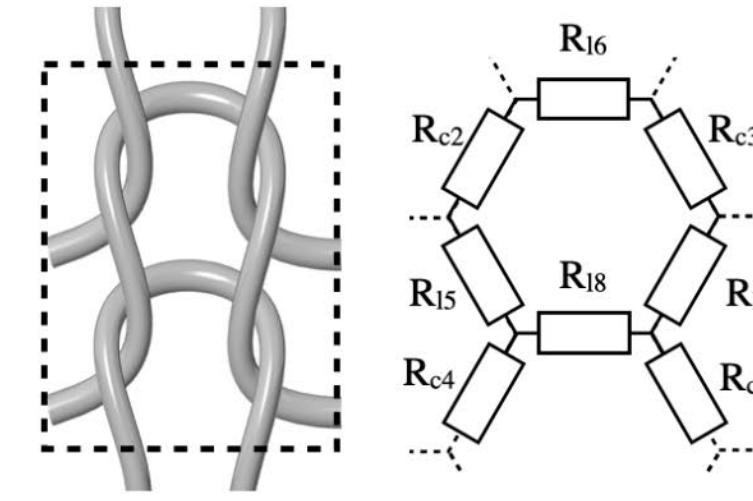
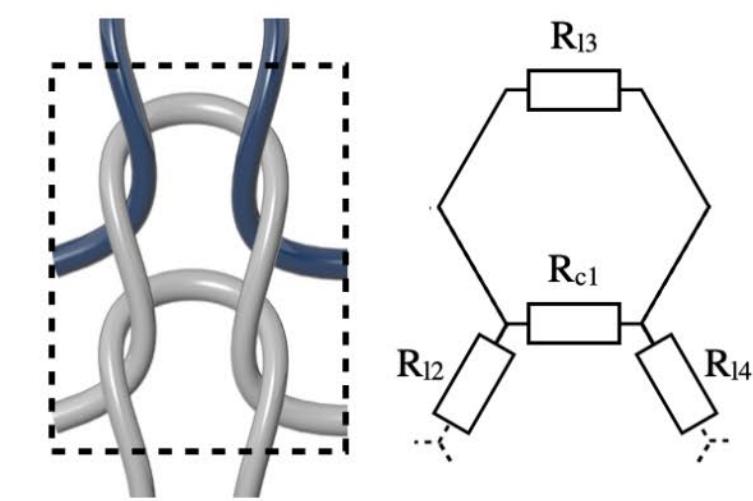
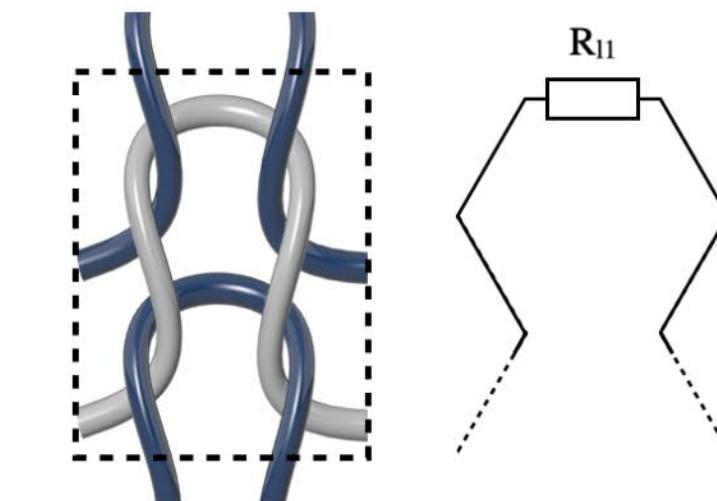
Digital machine knitting - a versatile fabrication process



Knitting operations



Knitted conductive yarns resistance modeling

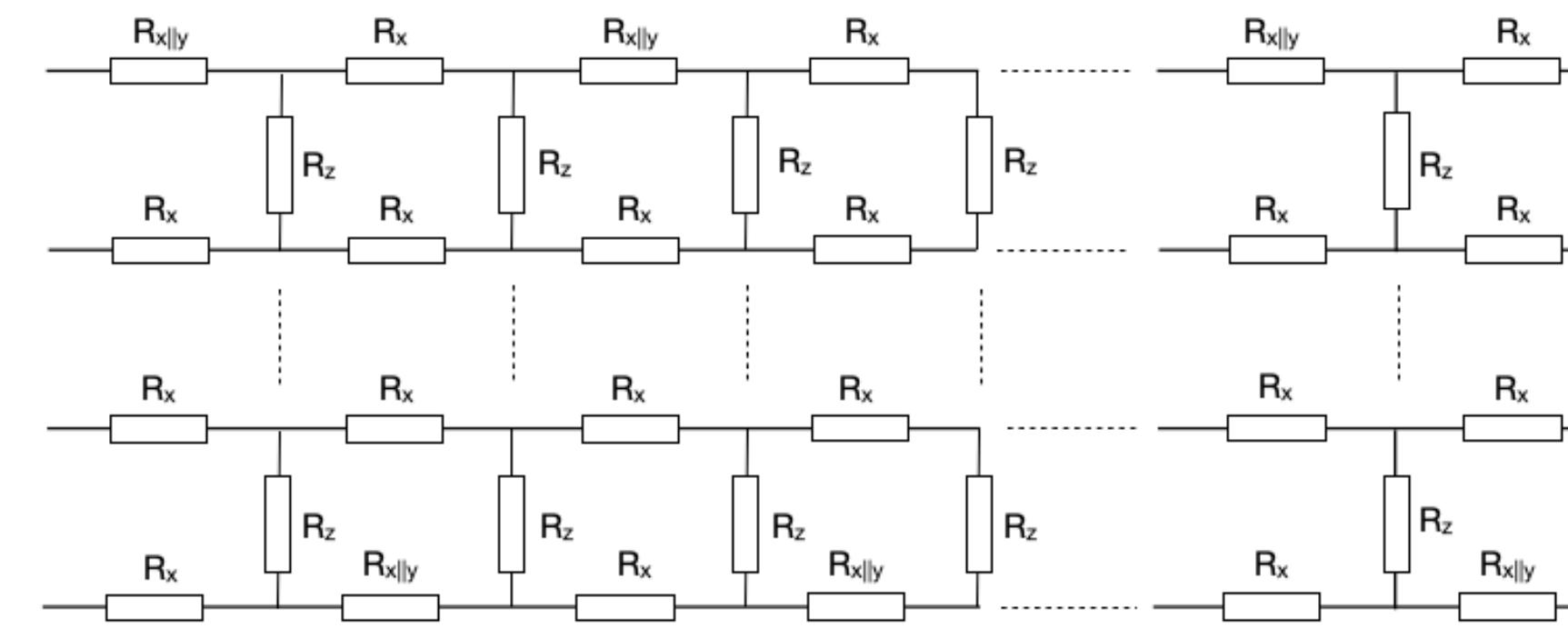
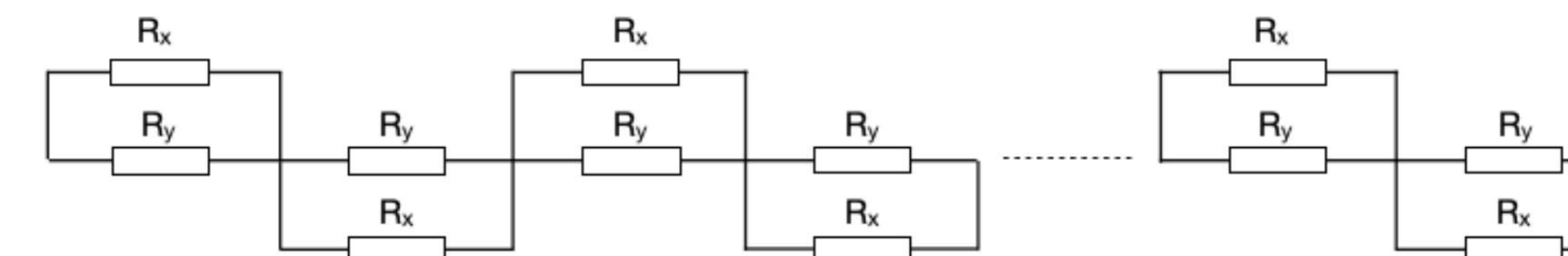
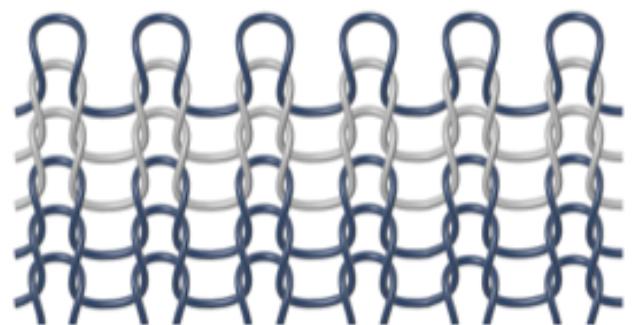


Resistive network + signal flow theory

$$R_x = R_{l3} + 0.5R_c$$

$$R_y = R_{l6} + 0.5R_c$$

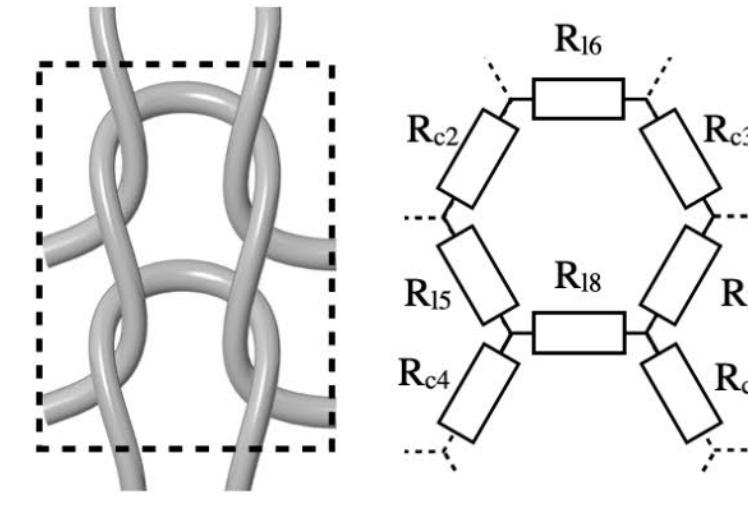
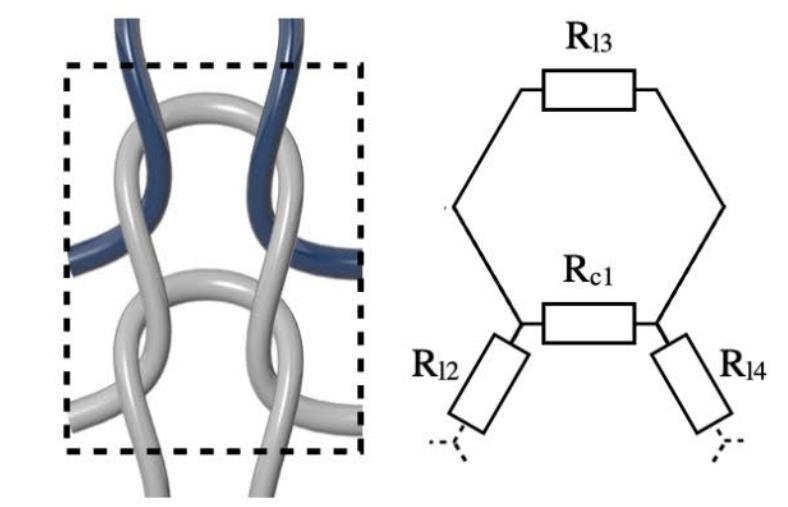
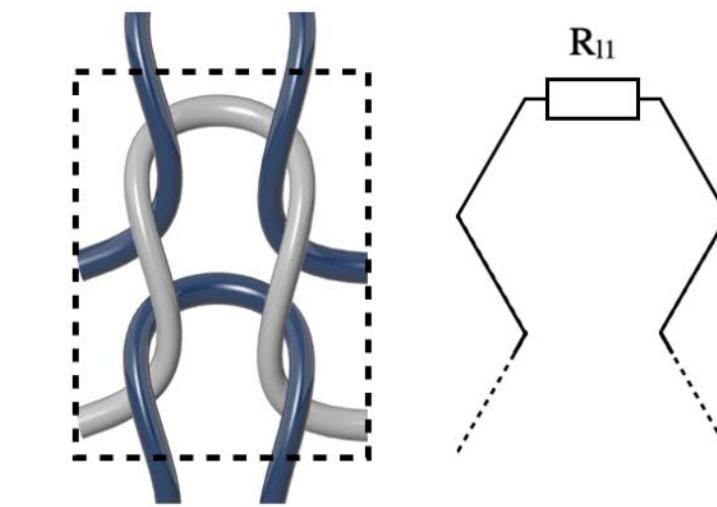
$$R_z = R_{l5} + 0.5R_c = R_{l7} + 0.5R_c$$



$$R_{x||y} = \frac{(kR_l^2 + 0.5(k+1)R_cR_l + 0.25R_c^2)}{(k+1)R_l + R_c}$$

$$R_{total(m>2)} = \frac{2NR_x(R_x + R_{x||y})}{(M+1)R_x + (M-3)R_{x||y}}$$

Knitted conductive yarns resistance modeling

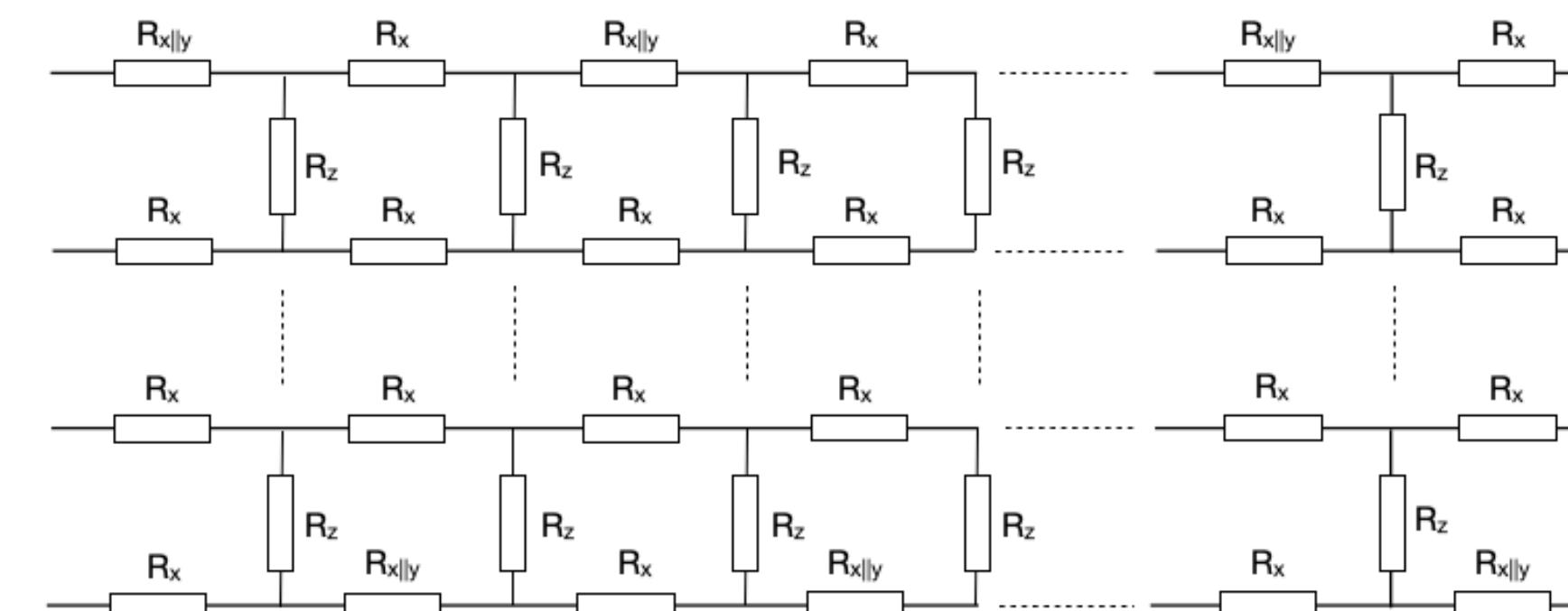
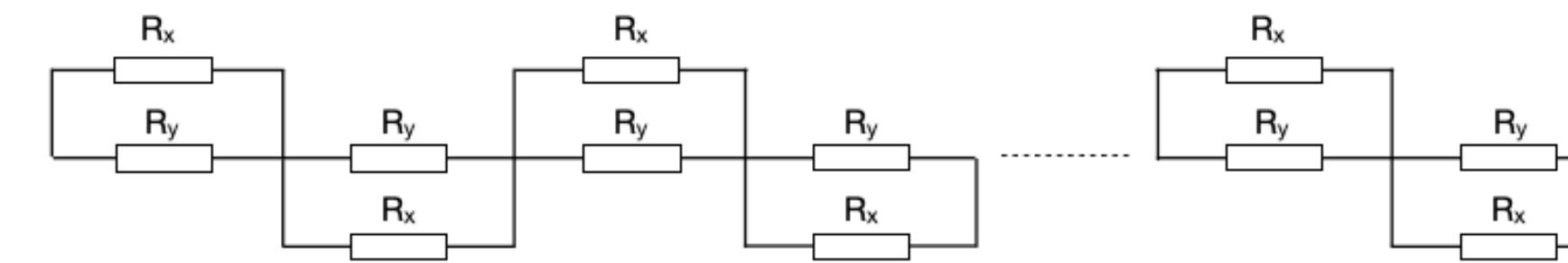
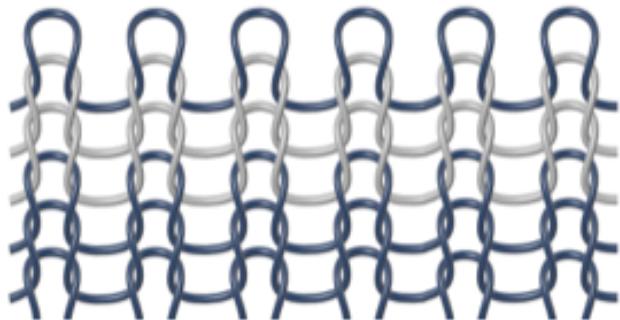


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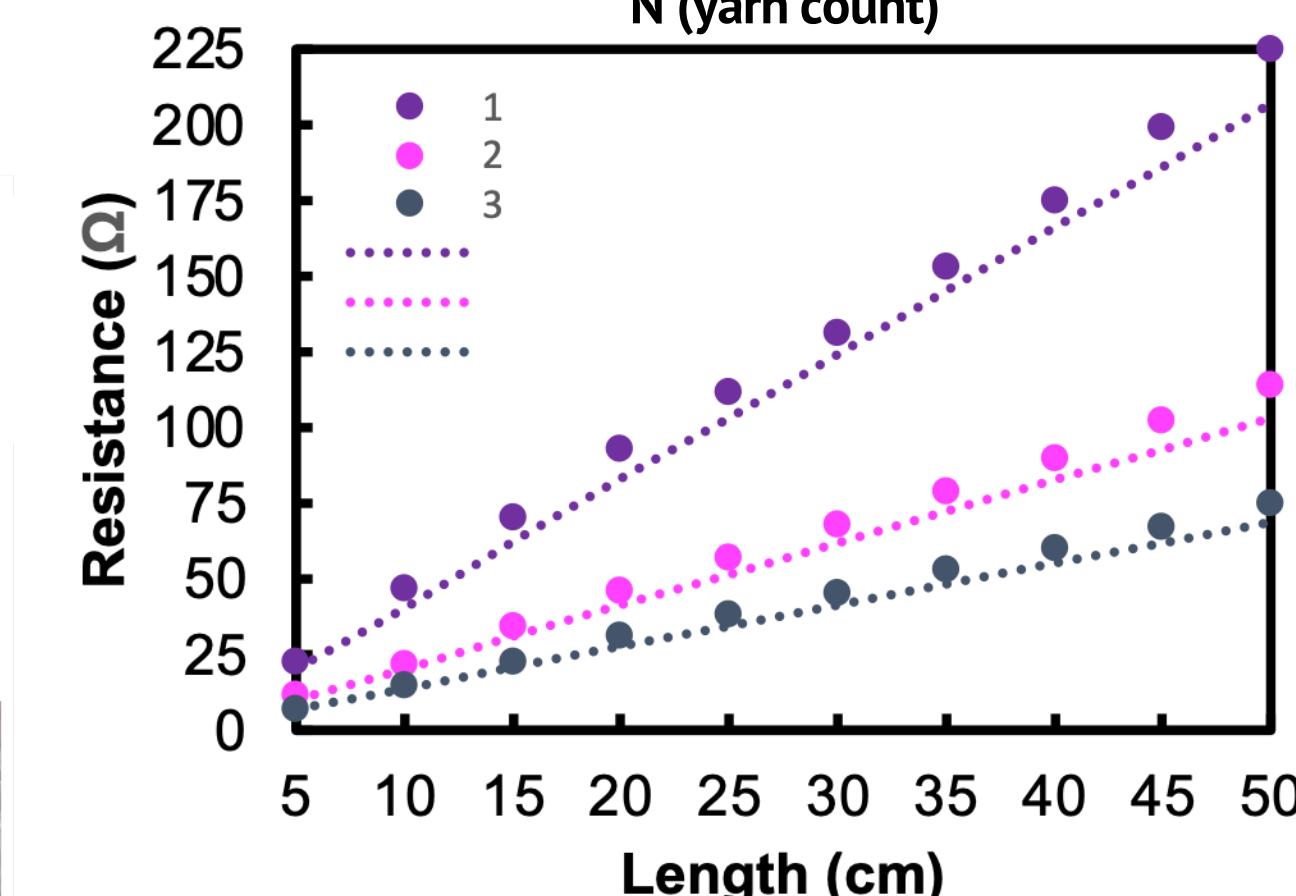
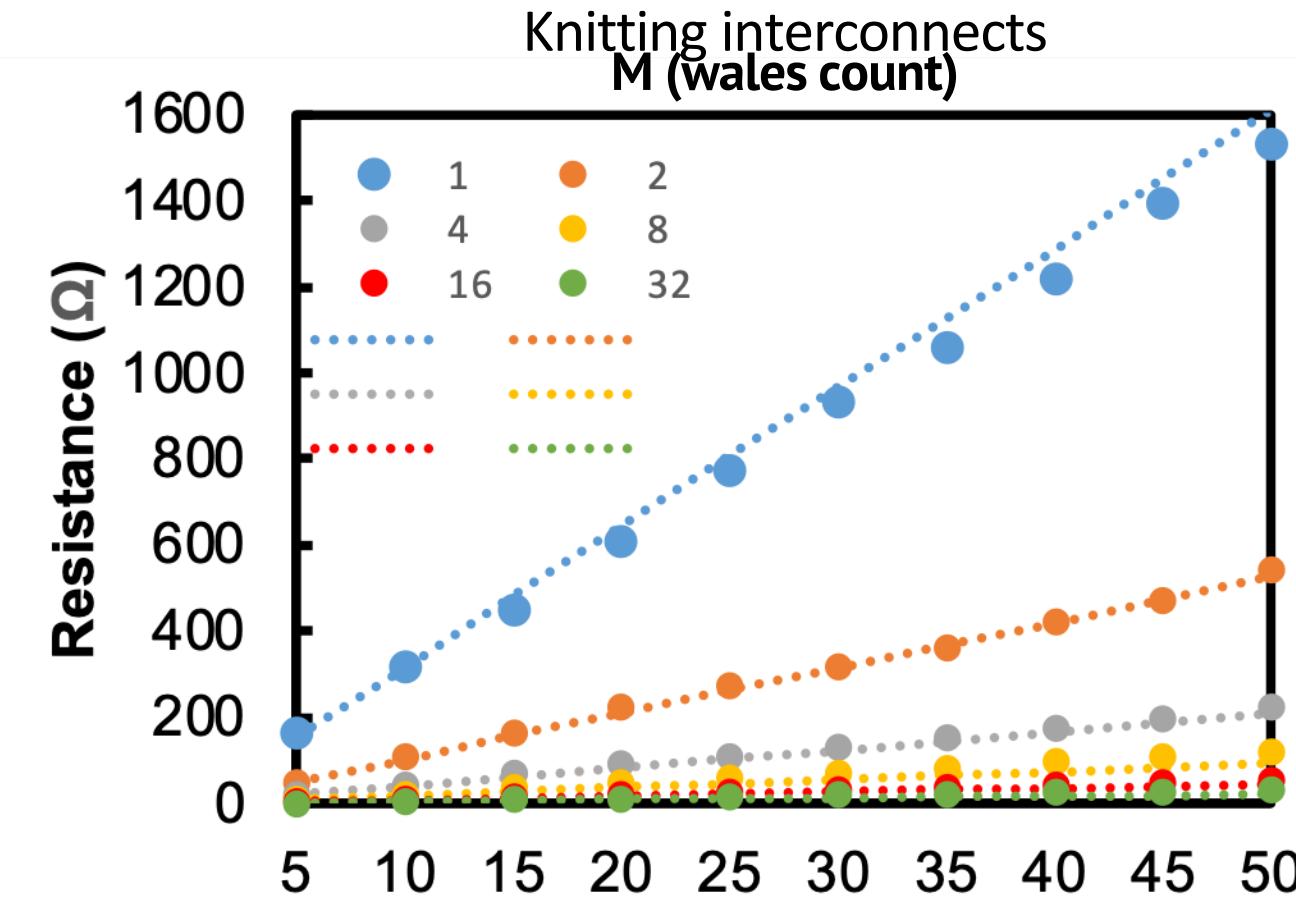
$$R_y = R_{l6} + 0.5R_c$$

$$R_z = R_{l5} + 0.5R_c = R_{l7} + 0.5R_c$$

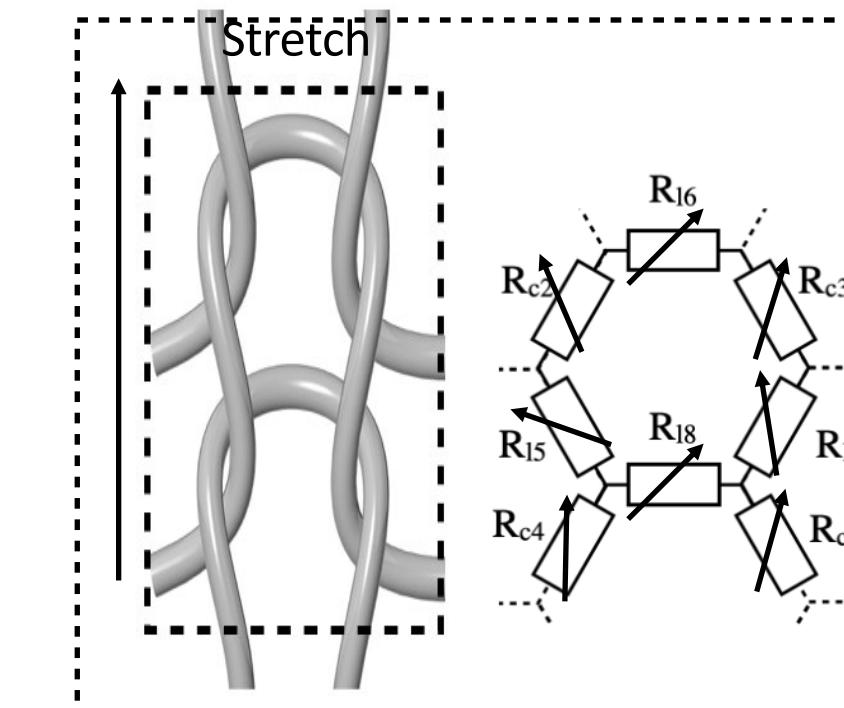
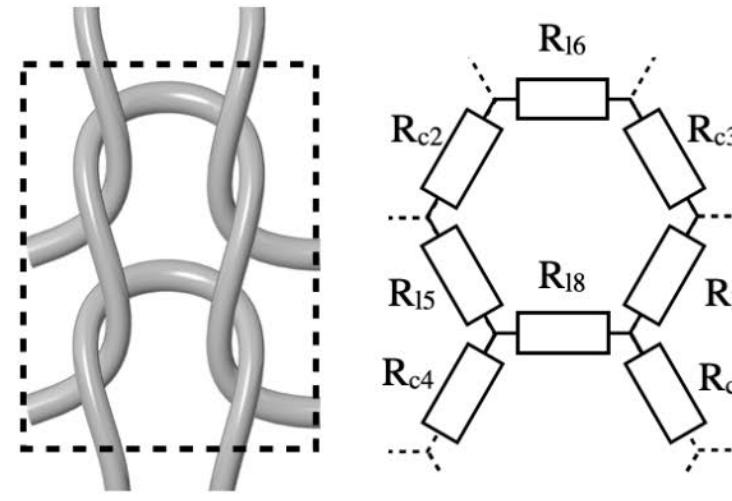
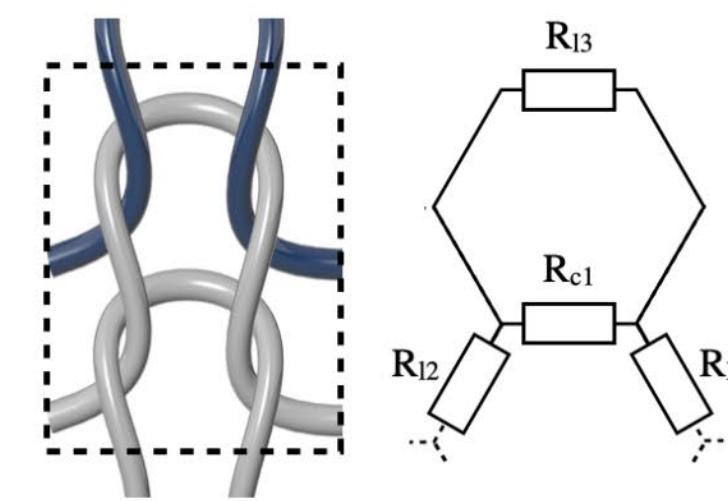
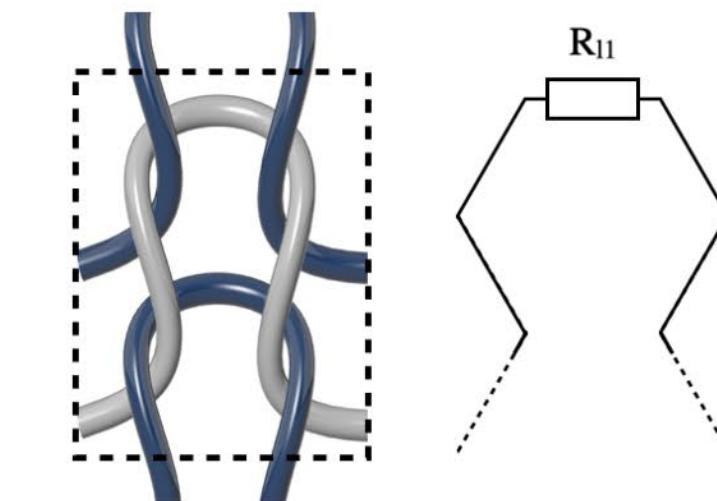


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$$R_{total(m>2)} = \frac{2NR_x(R_x + R_{x||y})}{(M+1)R_x + (M-3)R_{x||y}}$$



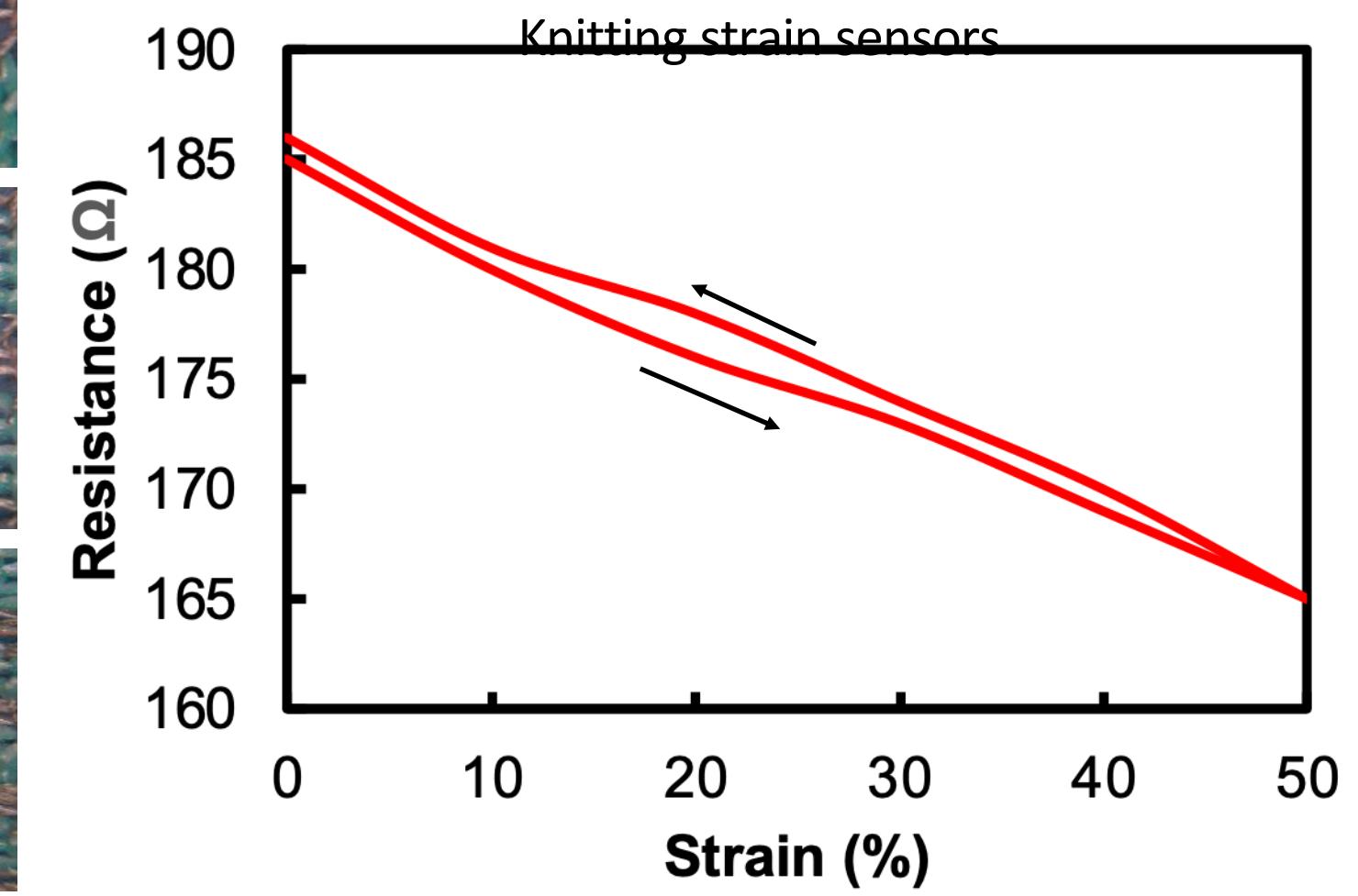
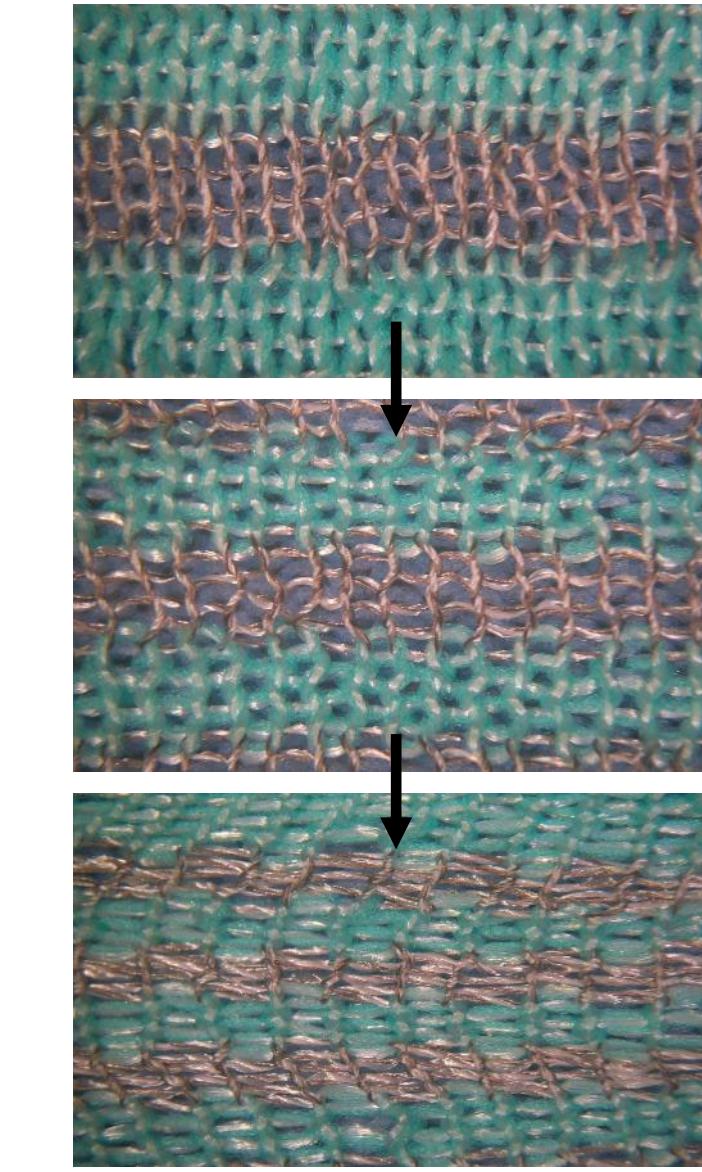
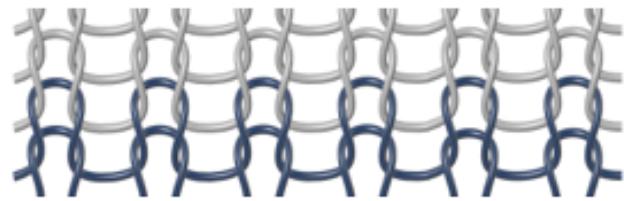
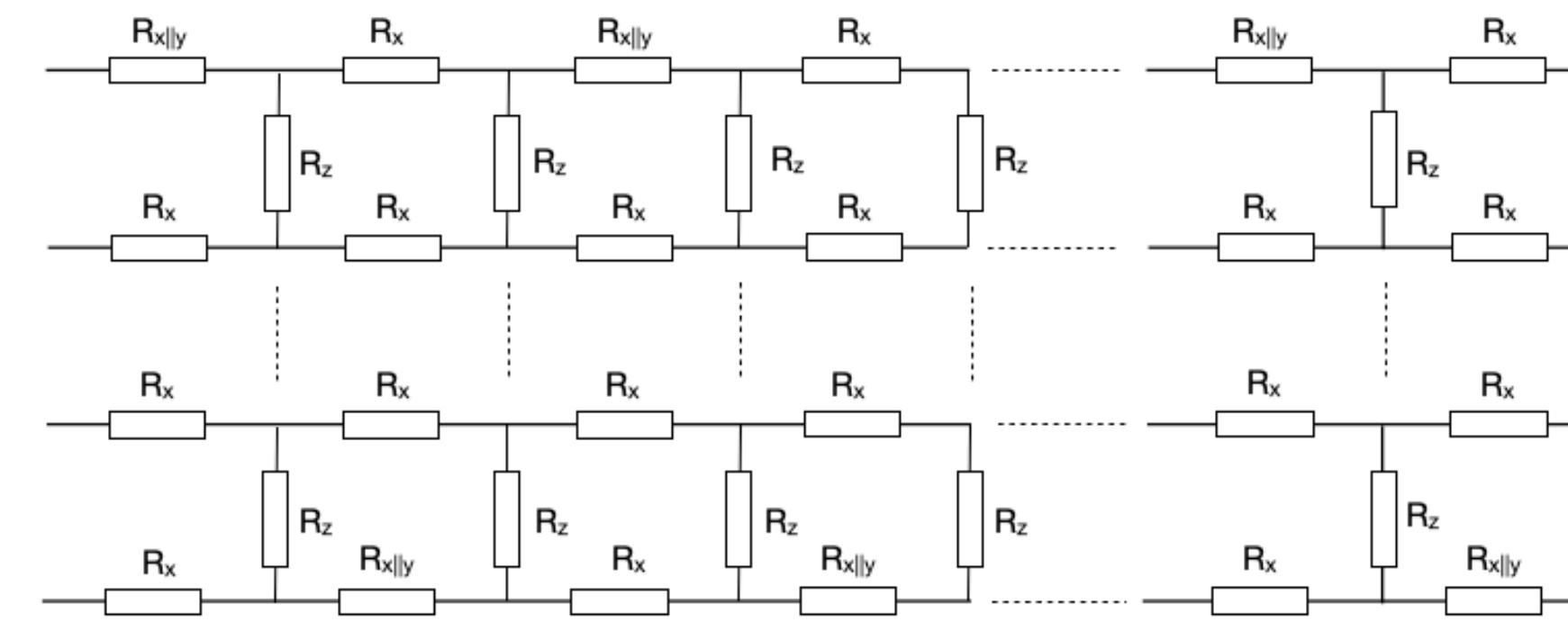
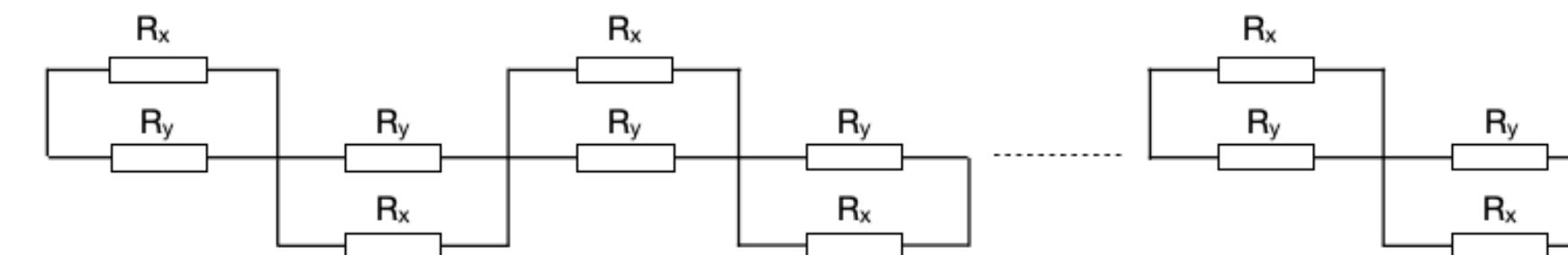
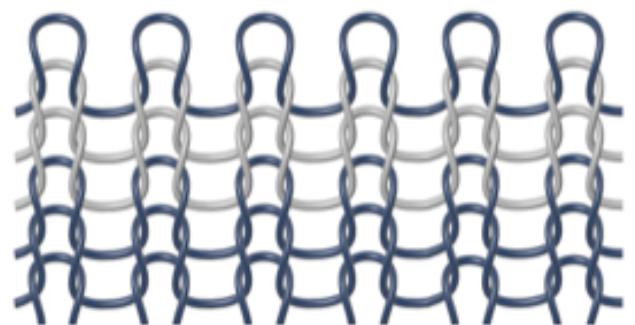
Knitted conductive yarns resistance modeling



Holm's contact theory
(contact pressure resistance due to strain/pressure)

$$R_C = \frac{\rho}{2} \sqrt{\frac{\pi H}{np}}$$

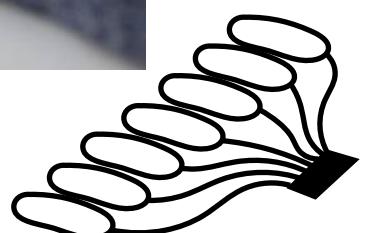
R_C = contact resistance;
 ρ = electrical resistivity;
 H = material hardness;
 n = number of contact points;
 p = contact pressure.



Architecting sensate textiles across scales

Objects

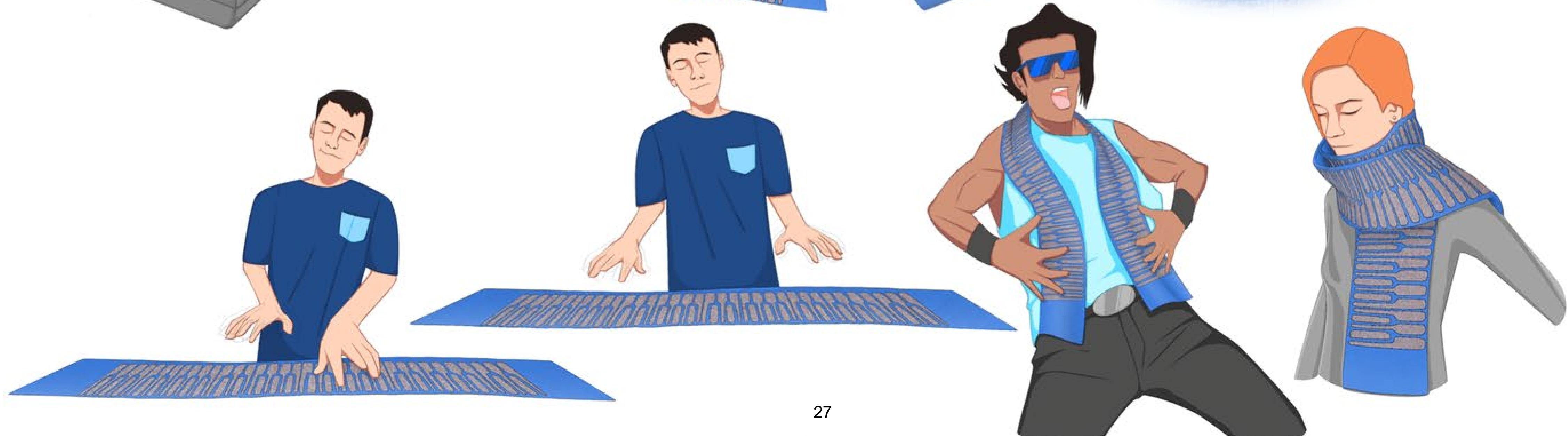
60 touch + 5 stretch + 1 pressure
Capacitive and piezoresistive array
72 connections
0.15m² active area



KnittedKeyboard
Musical expression



KnittedKeyboard



KnittedKeyboard



FabricKeyboard to KnittedKeyboard

From manual, to seamless and automated integration



FabricKeyboard (2017)

12 keys/1 octave

- 12 capacitive touch sensing elements,
- 12 proximity sensing elements (1 multiplexed possible)
- 12 pressure sensing elements,
- 1 stretch across the keys
- 12 electric field elements (different board)

KnittedKeyboard v1 (machine-produced, 2020)

60 keys/5 octave

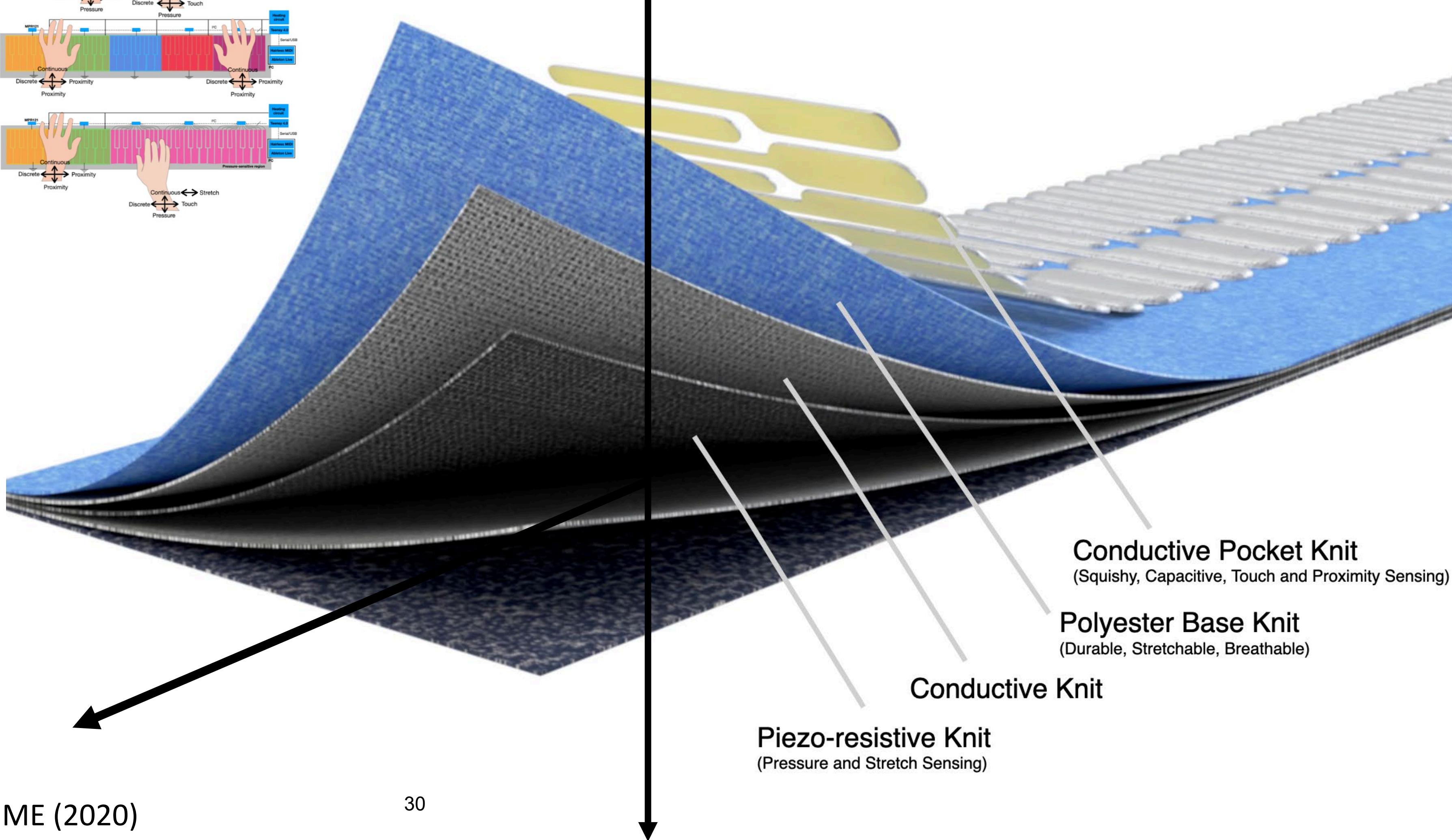
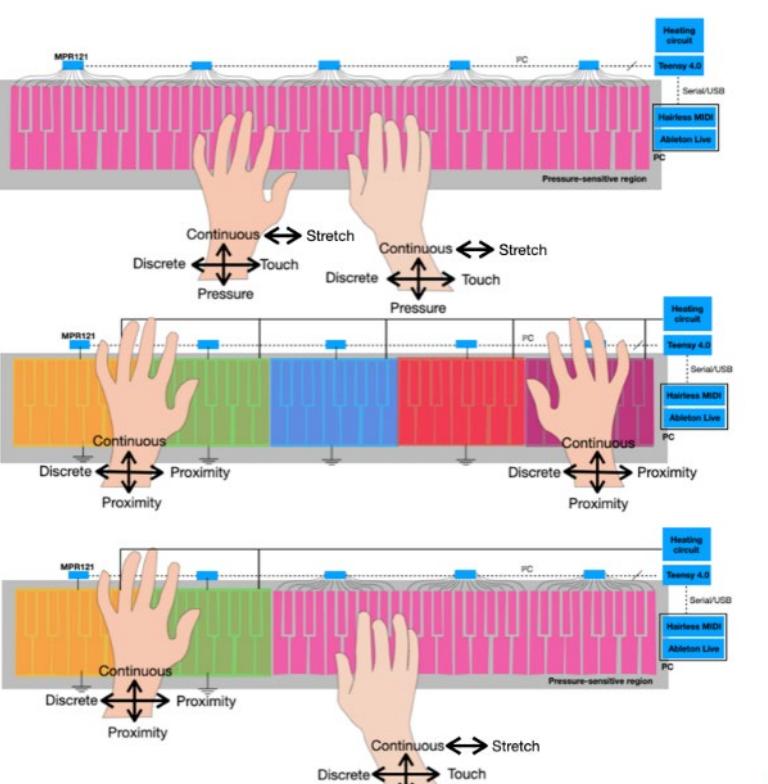
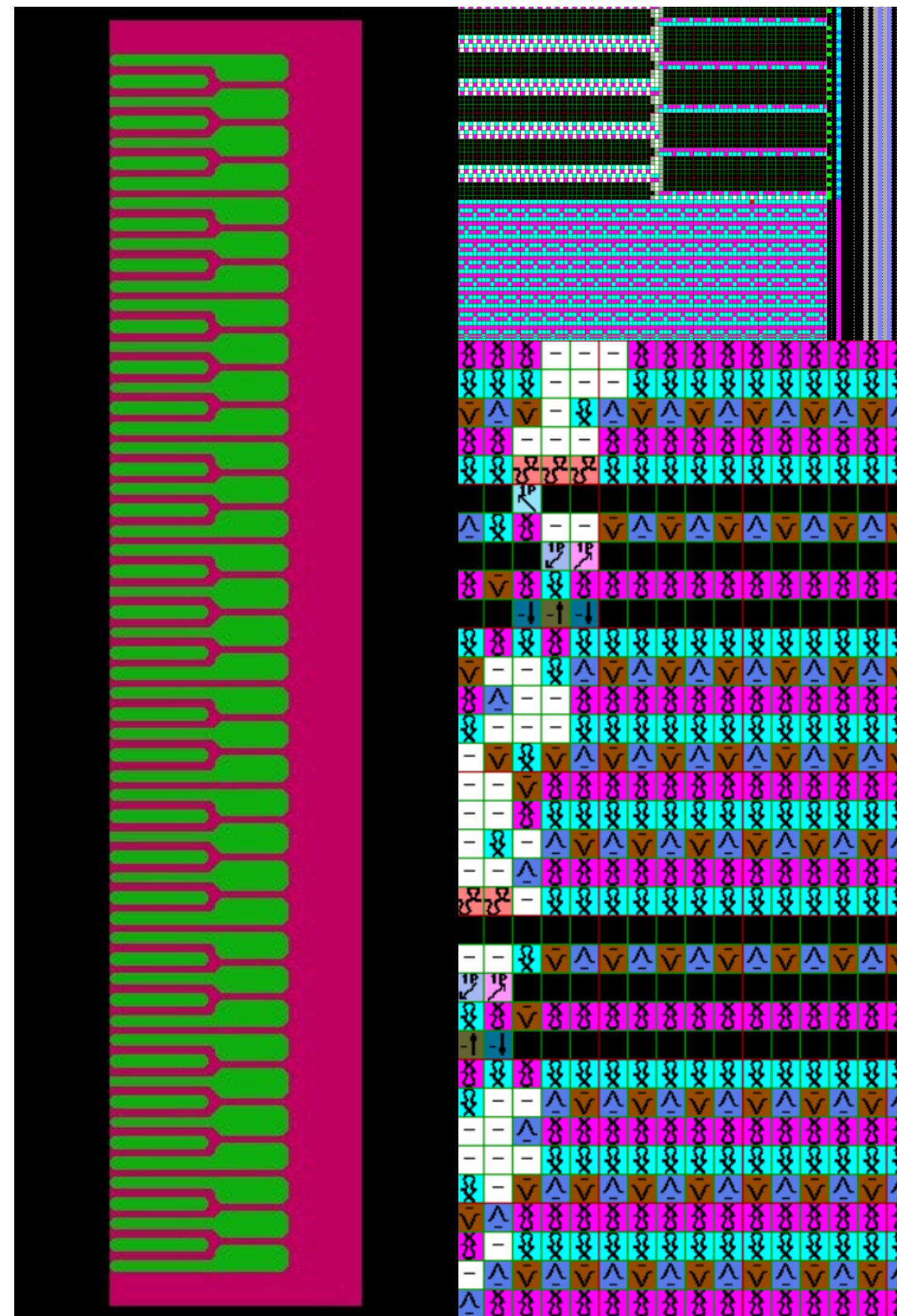
- 60 capacitive touch sensing elements,
- 60 proximity sensing elements (5 multiplexed)
- 1 pressure sensing elements,
- 5 thermochromic color change (per octave)

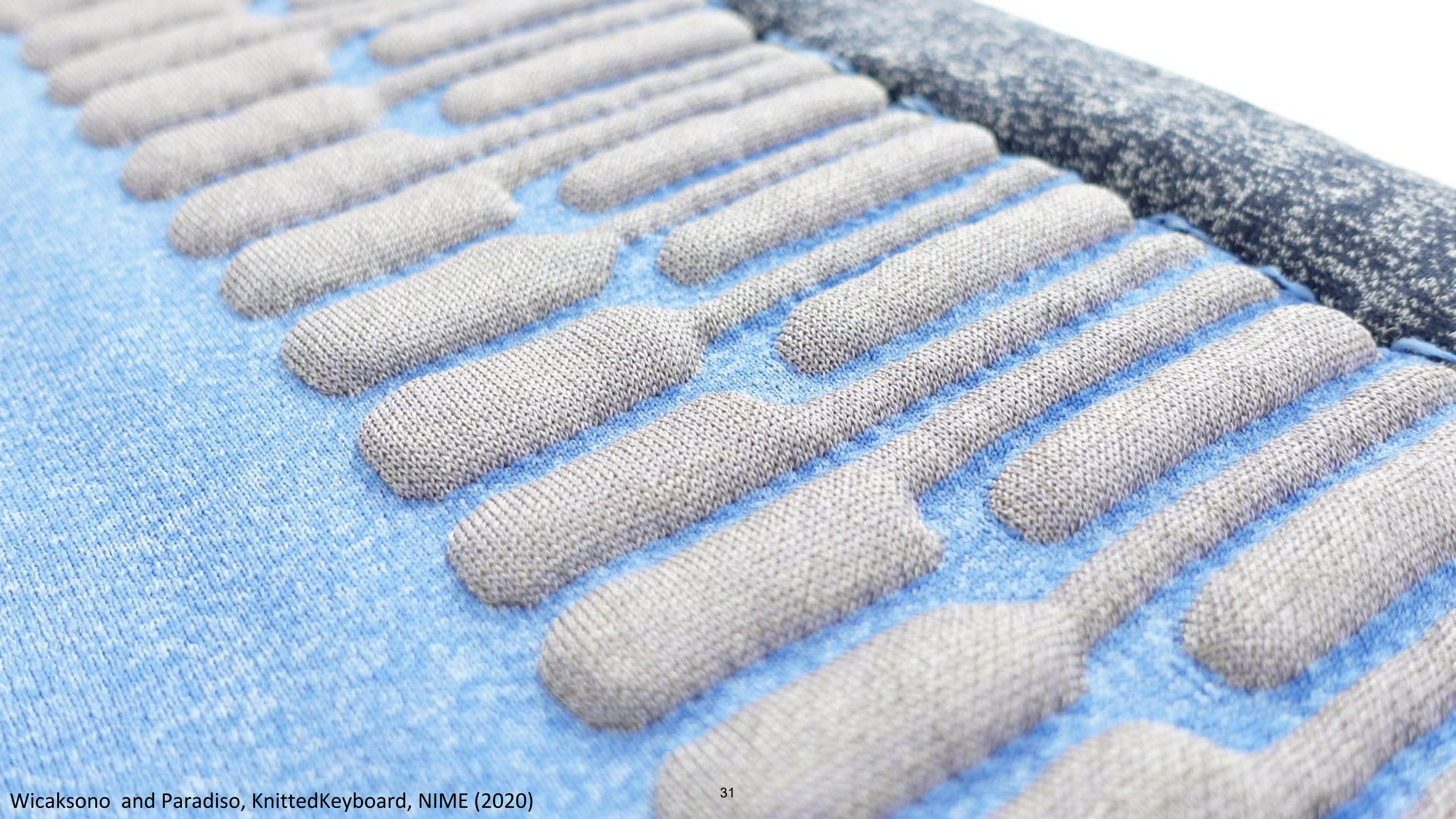
KnittedKeyboard v2 (2021, improved design)

60 keys/5 octave

- 60 capacitive touch sensing elements,
- 60 proximity sensing elements (5 multiplexed)
- 1 pressure sensing elements,
- 1 stretch across the keys

KnittedKeyboard

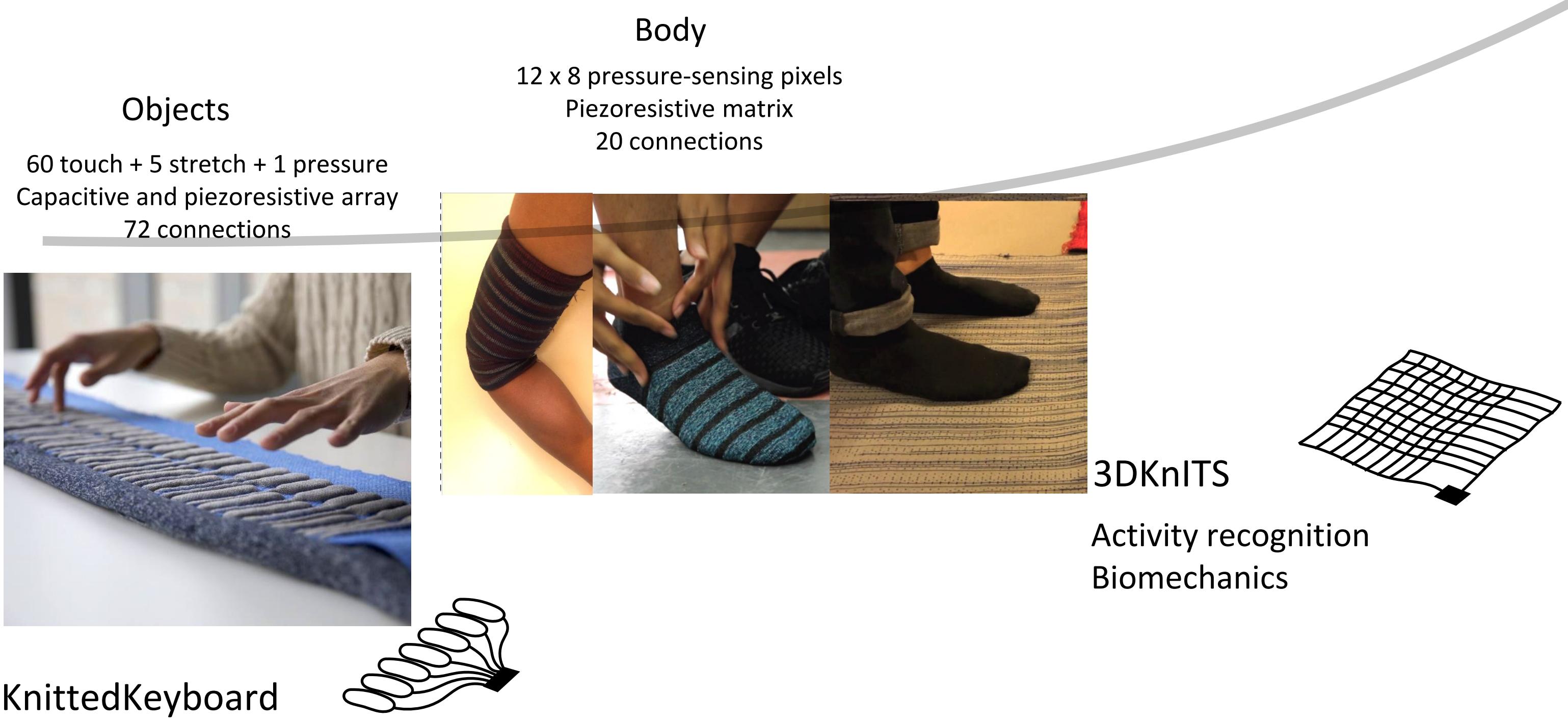




Jordan Rudess, Dream Theater



Architecting sensate textiles across scales



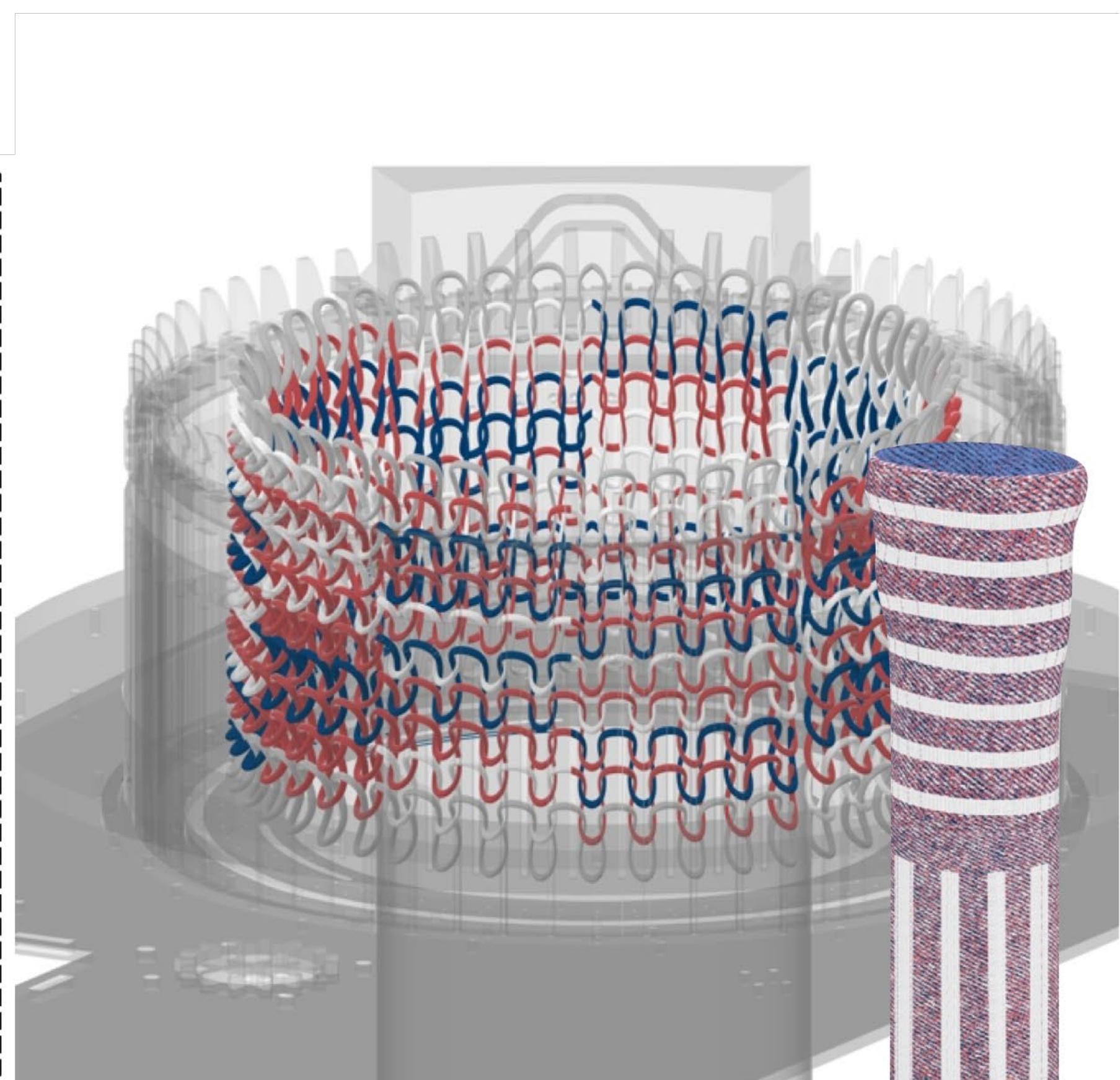
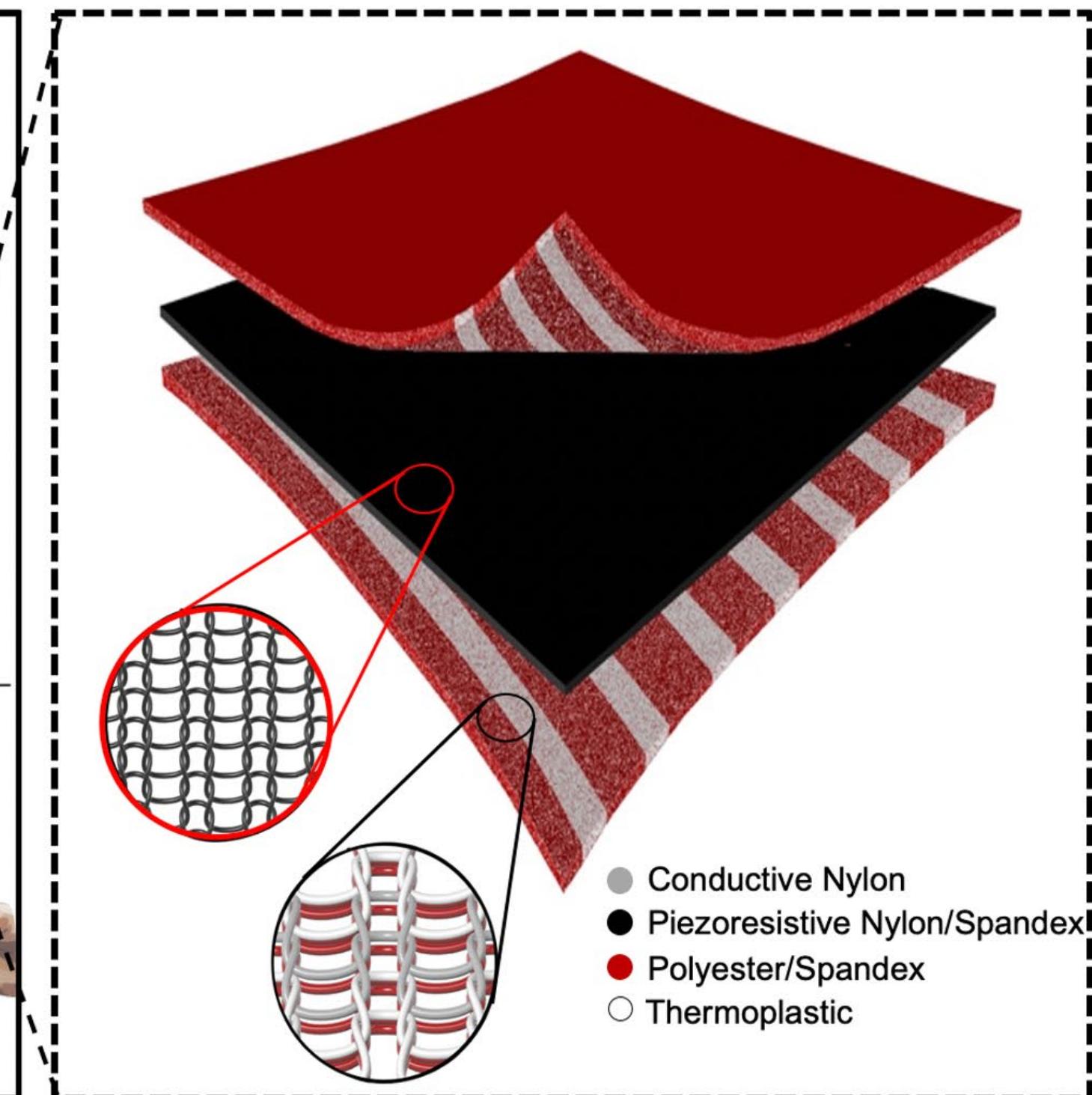
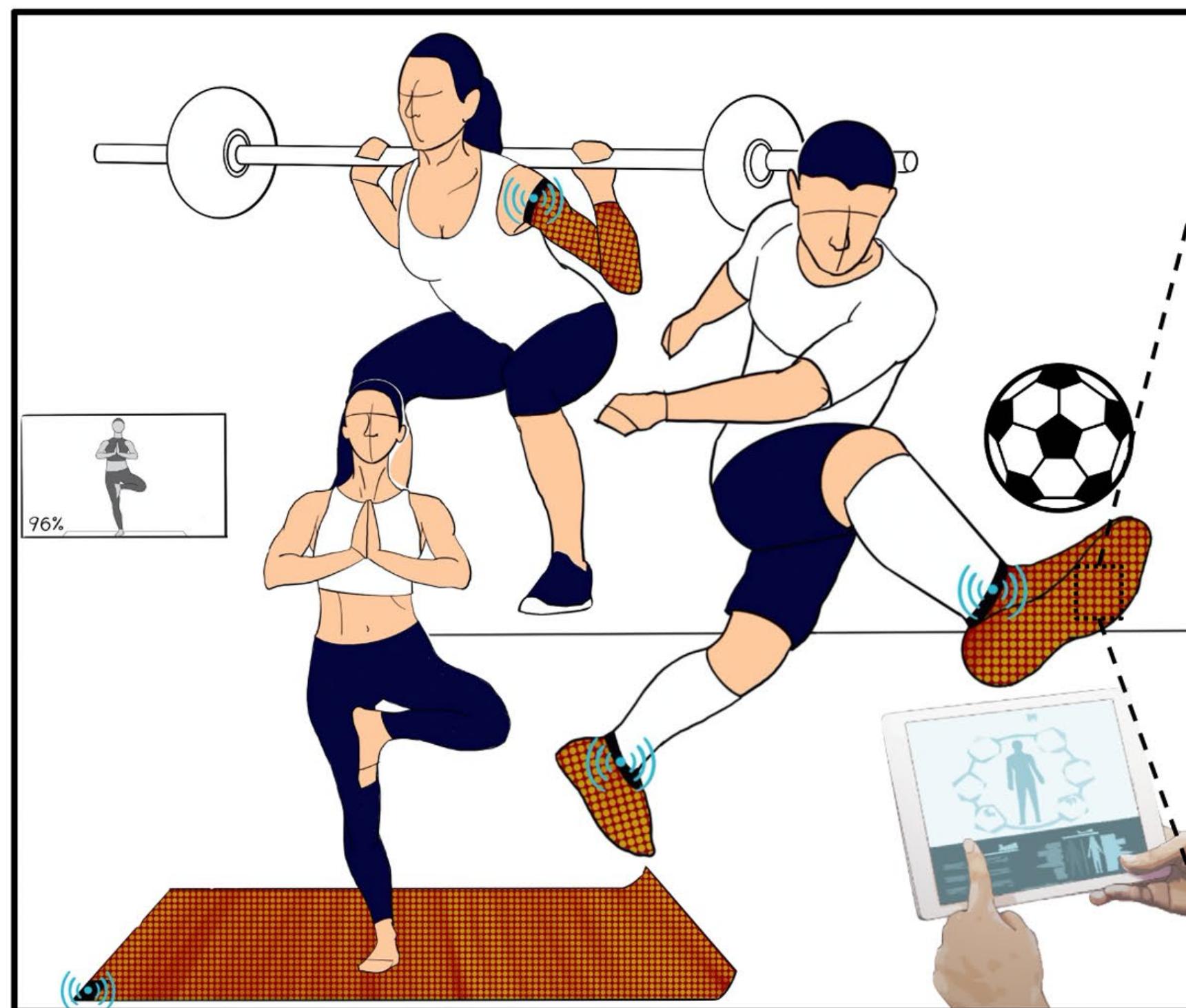
3DKnITS: 3-D Knitted Intelligent Textile Sensor



3DKnITS: 3-D Knitted Intelligent Textile Sensor

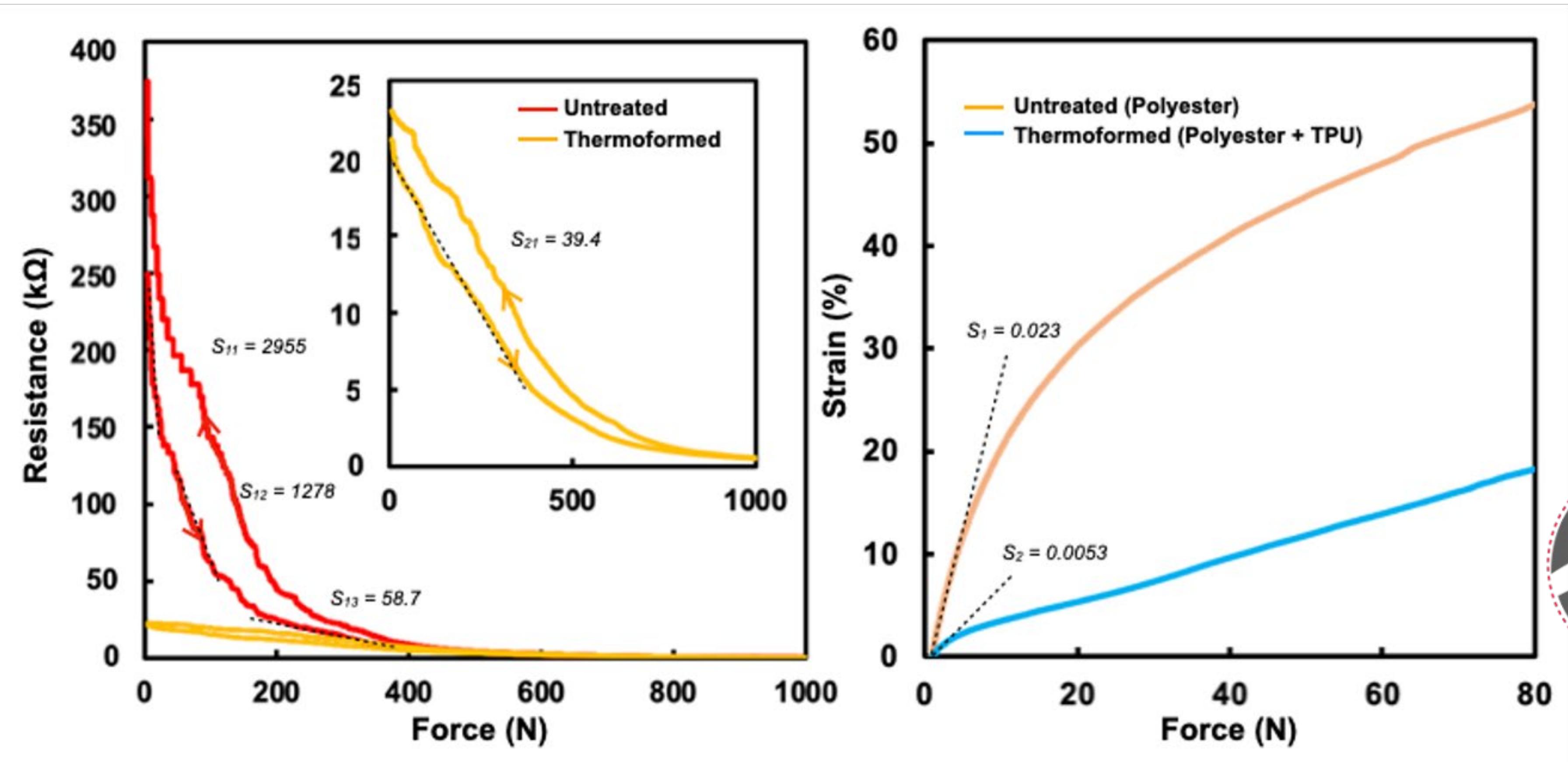


3DKnITS: 3-D Knitted Intelligent Textile Sensor

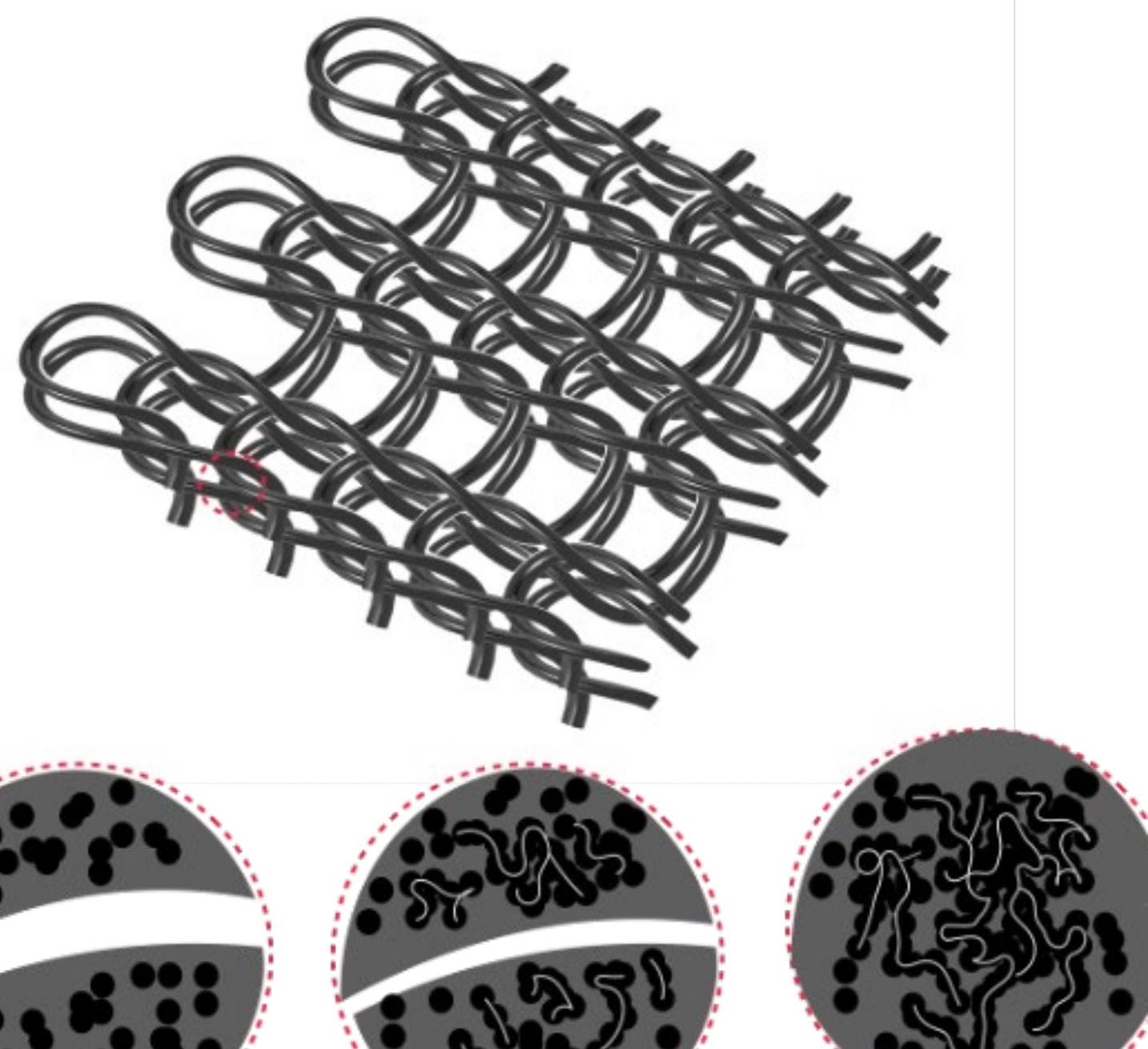


Electromechanical characterization

Designing knitted e-textile for robust pressure-sensing



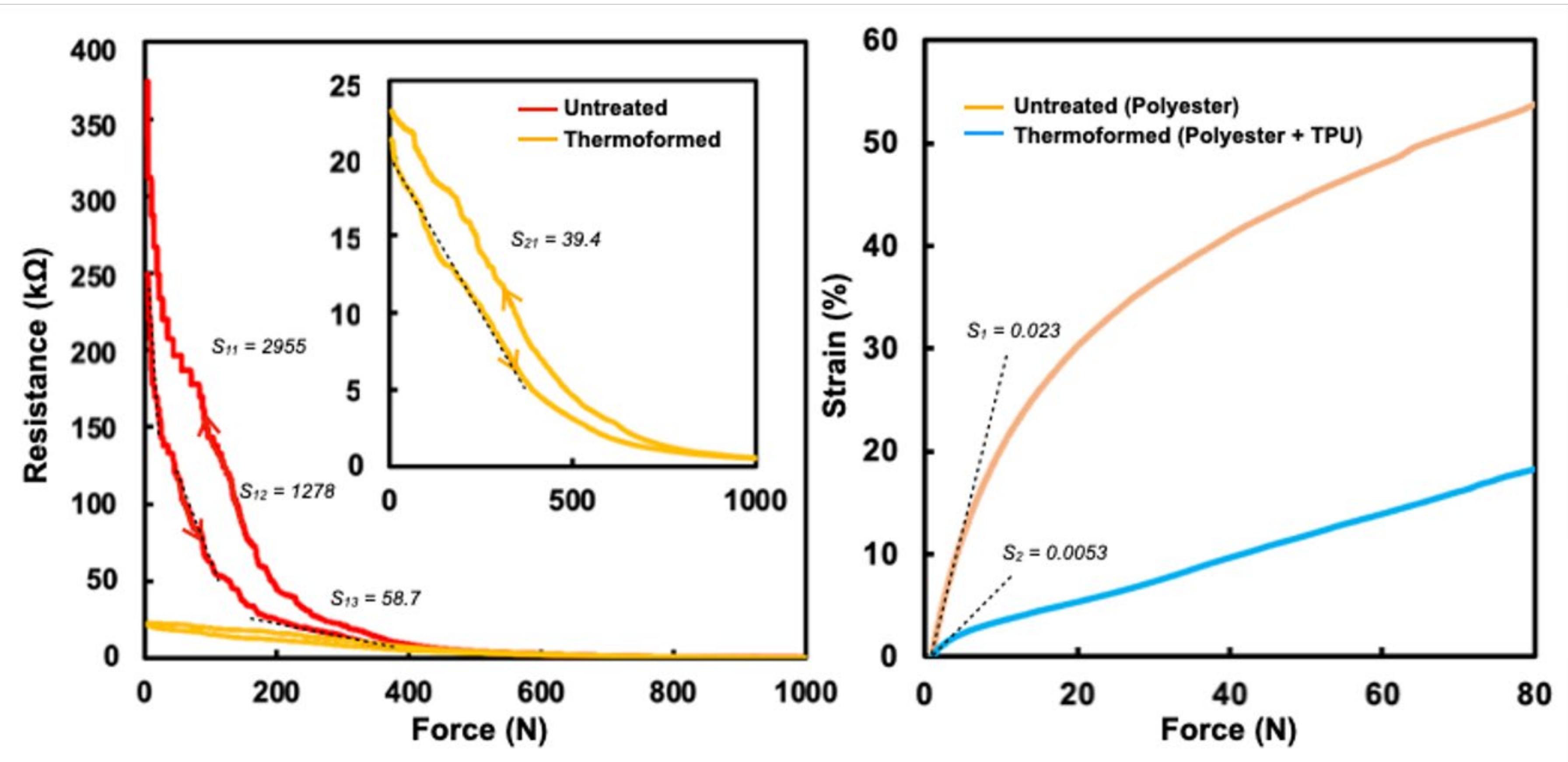
Force vs resistance and stress-strain tensile characterization of both the untreated and thermoformed knit textiles.



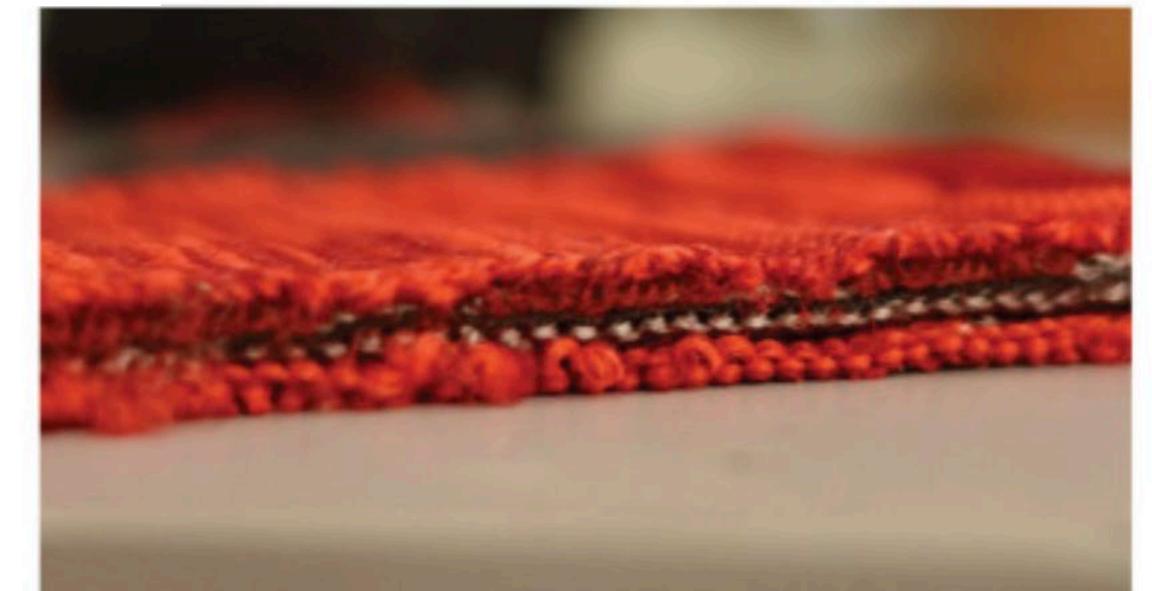
Percolation network of conductive molecules
in pressure-sensitive textiles

Electromechanical characterization

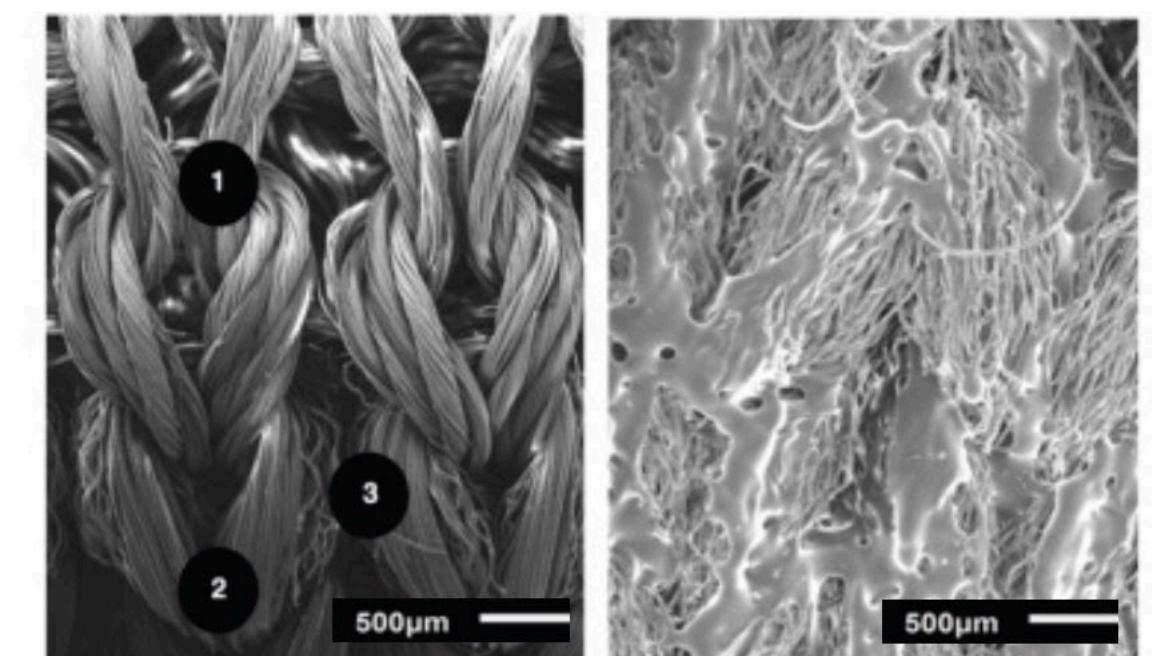
Designing knitted e-textile for robust pressure-sensing



Force vs resistance and stress-strain tensile characterization of both the untreated and thermoformed knit textiles.



Multi-layer textiles

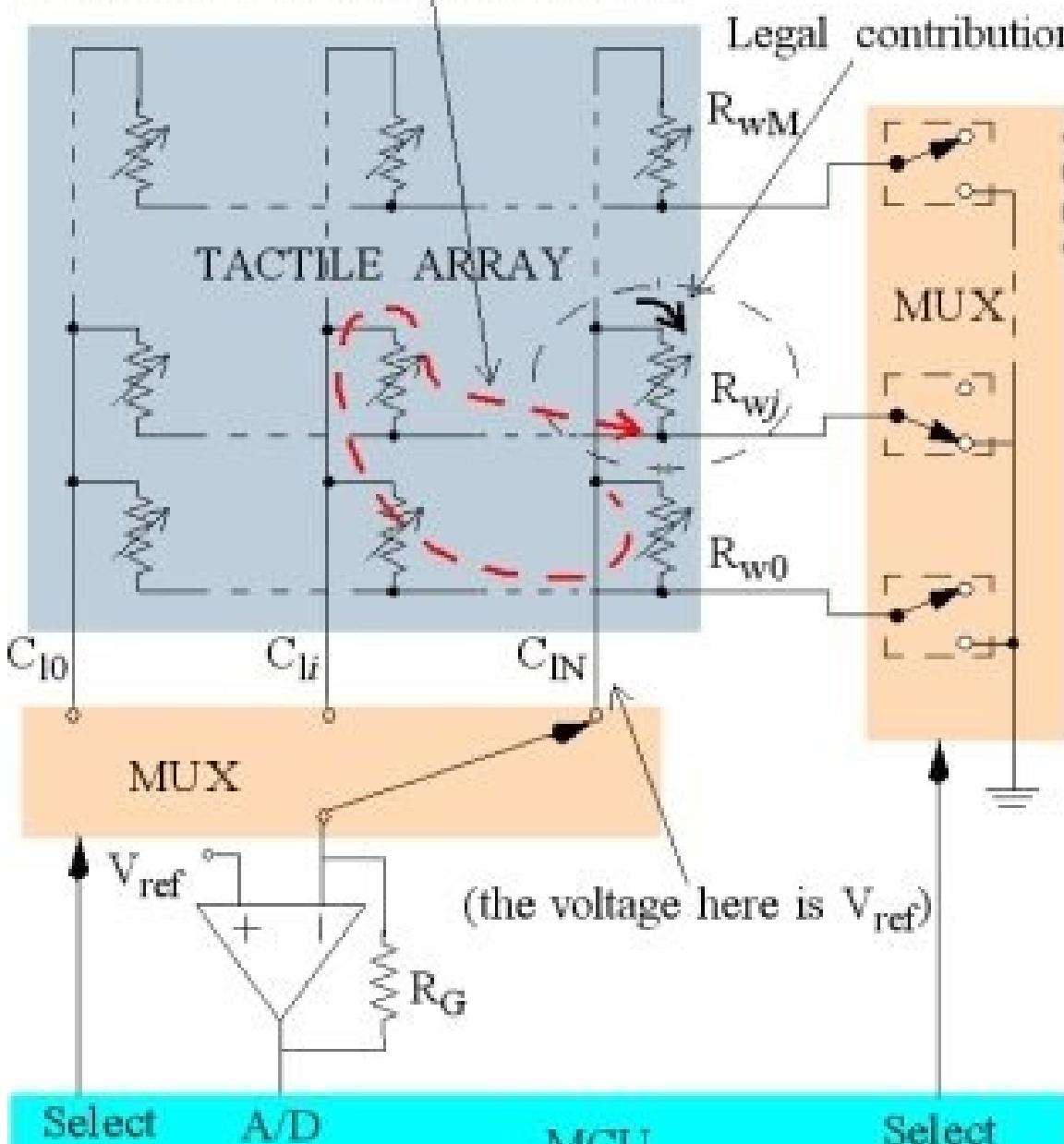


Thermoformed

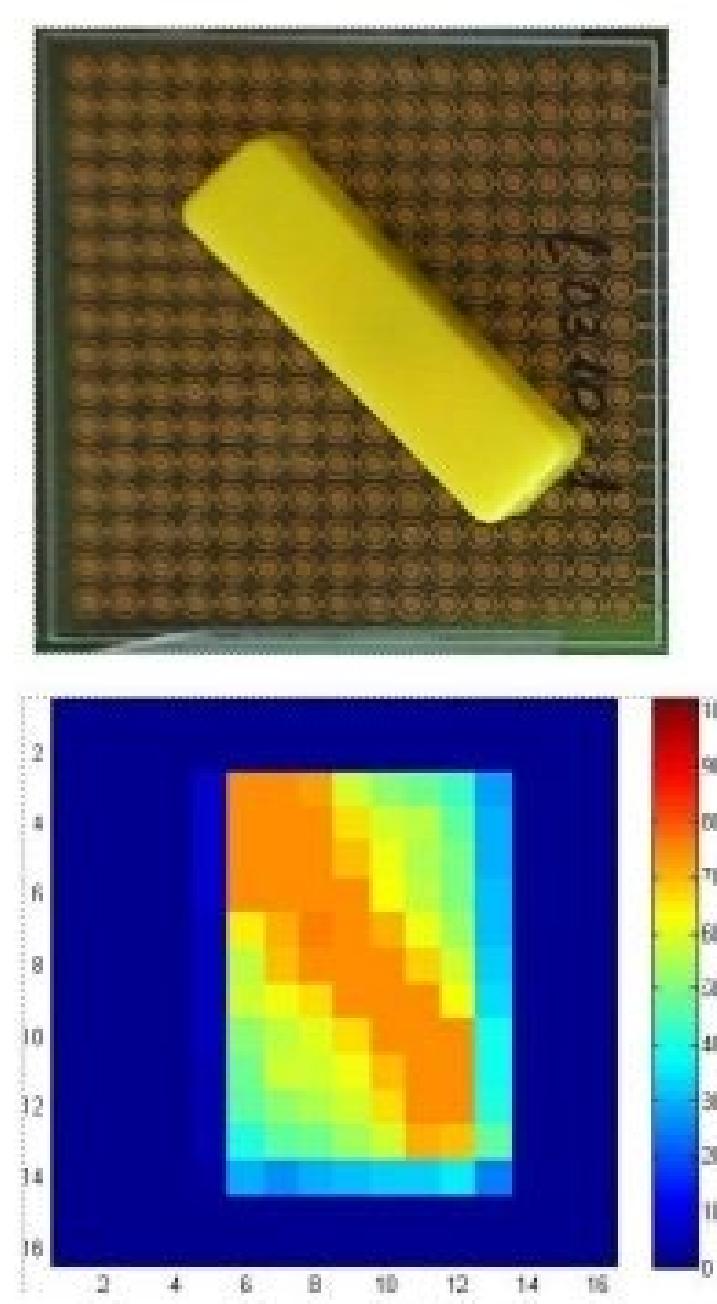
Multiplexing circuits

Designing knitted e-textile hardware for robust pressure-sensing

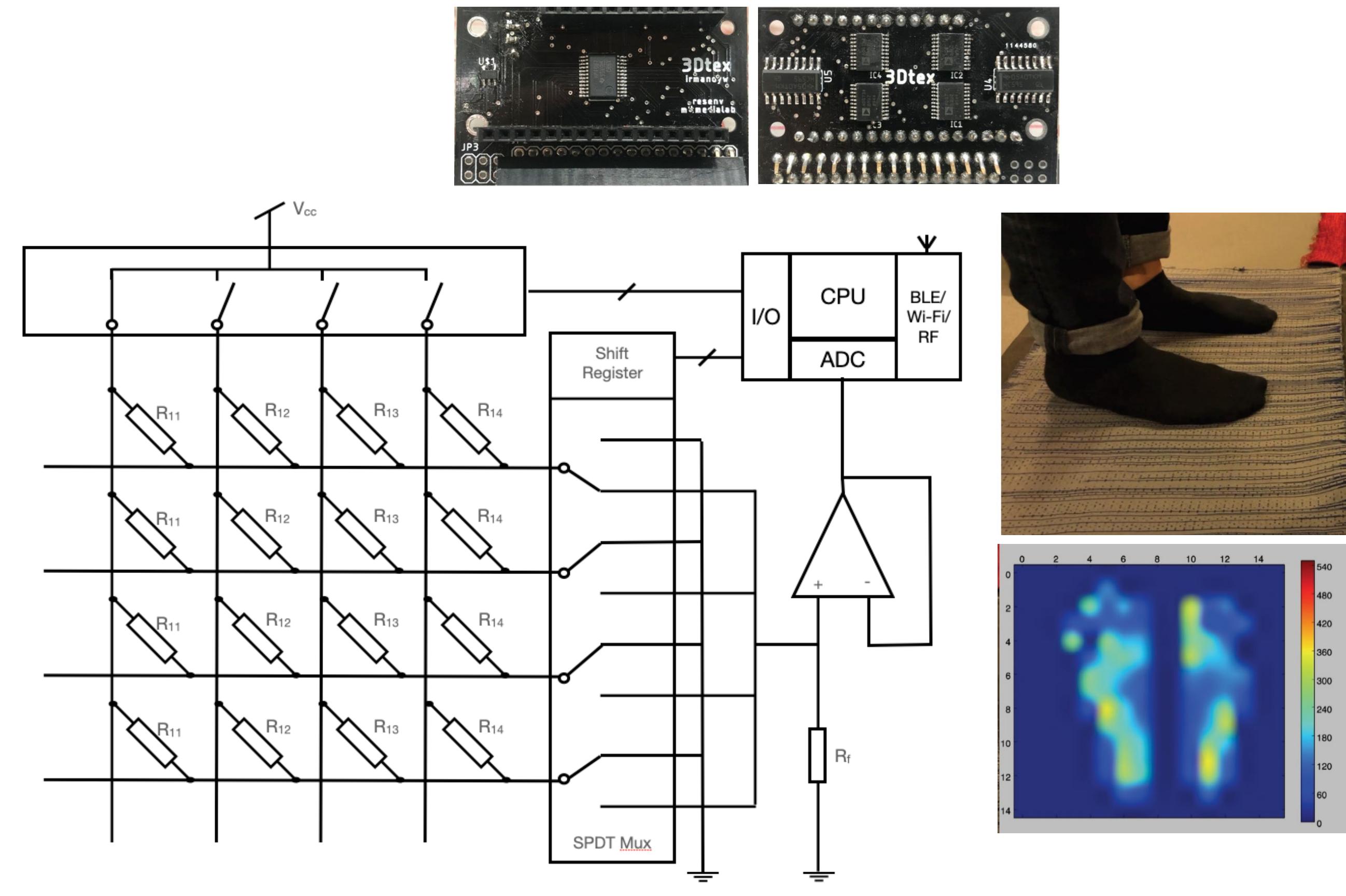
Example of parasitic resistive path



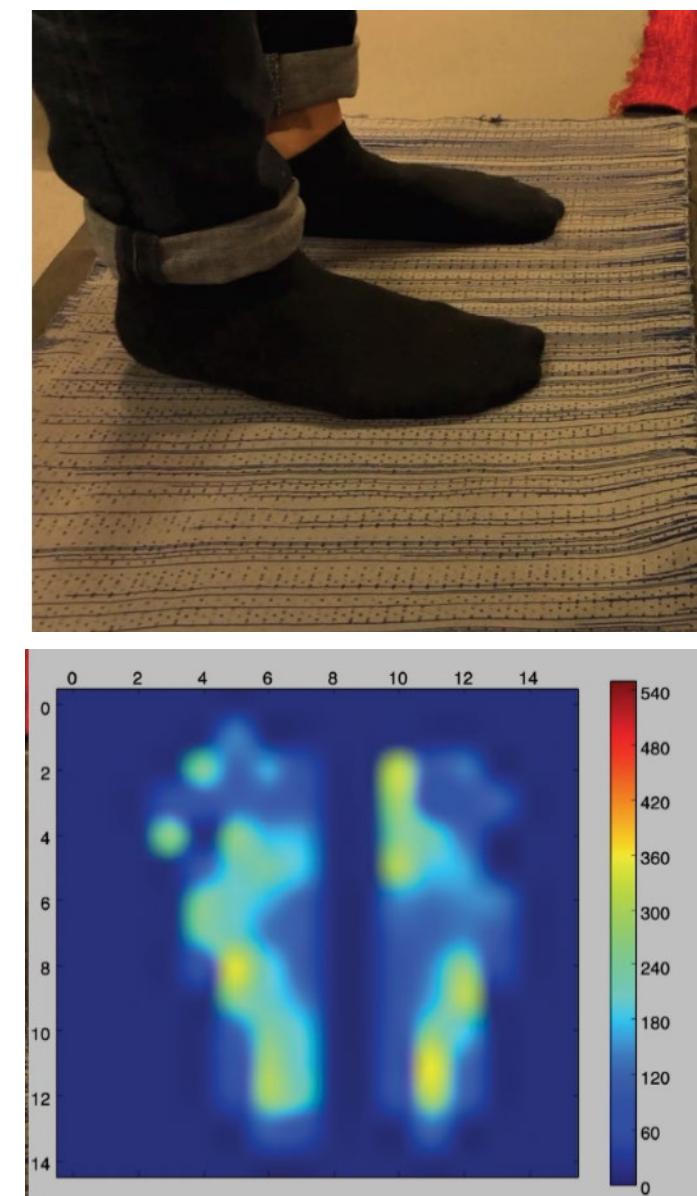
(a)



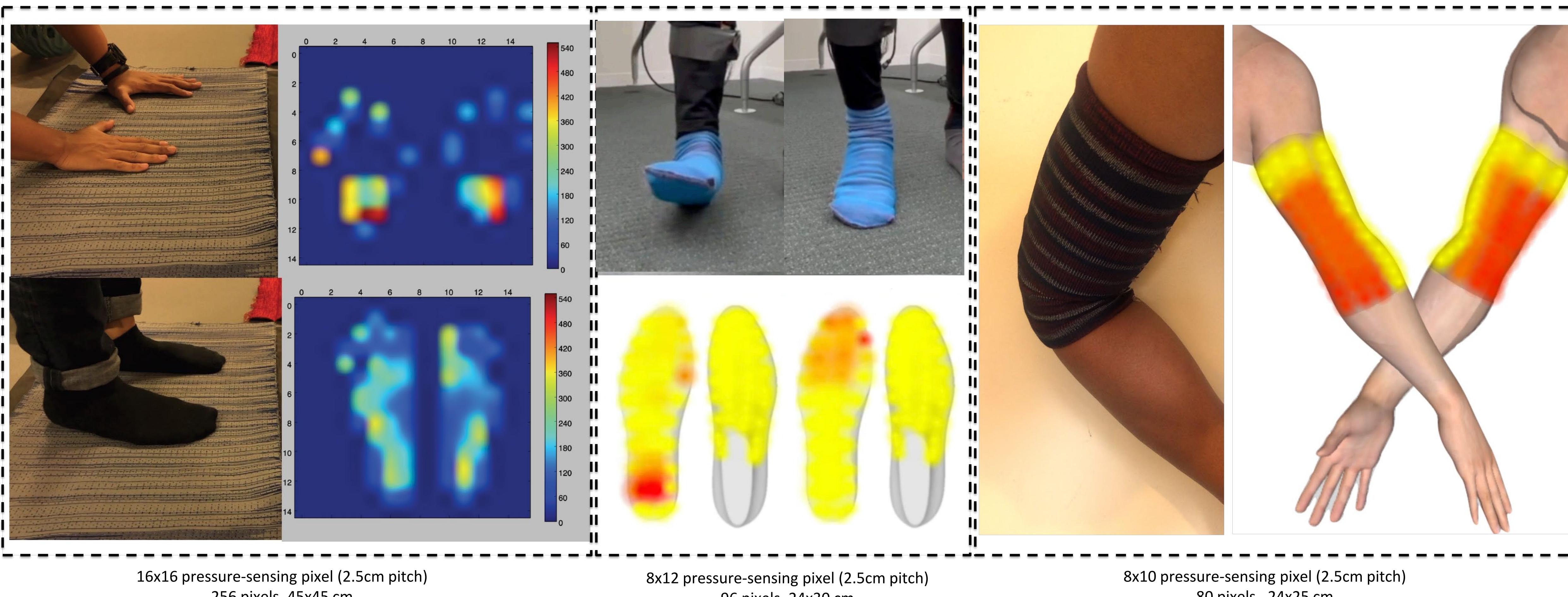
Vidal-Verdu et al., Sensors (2011)



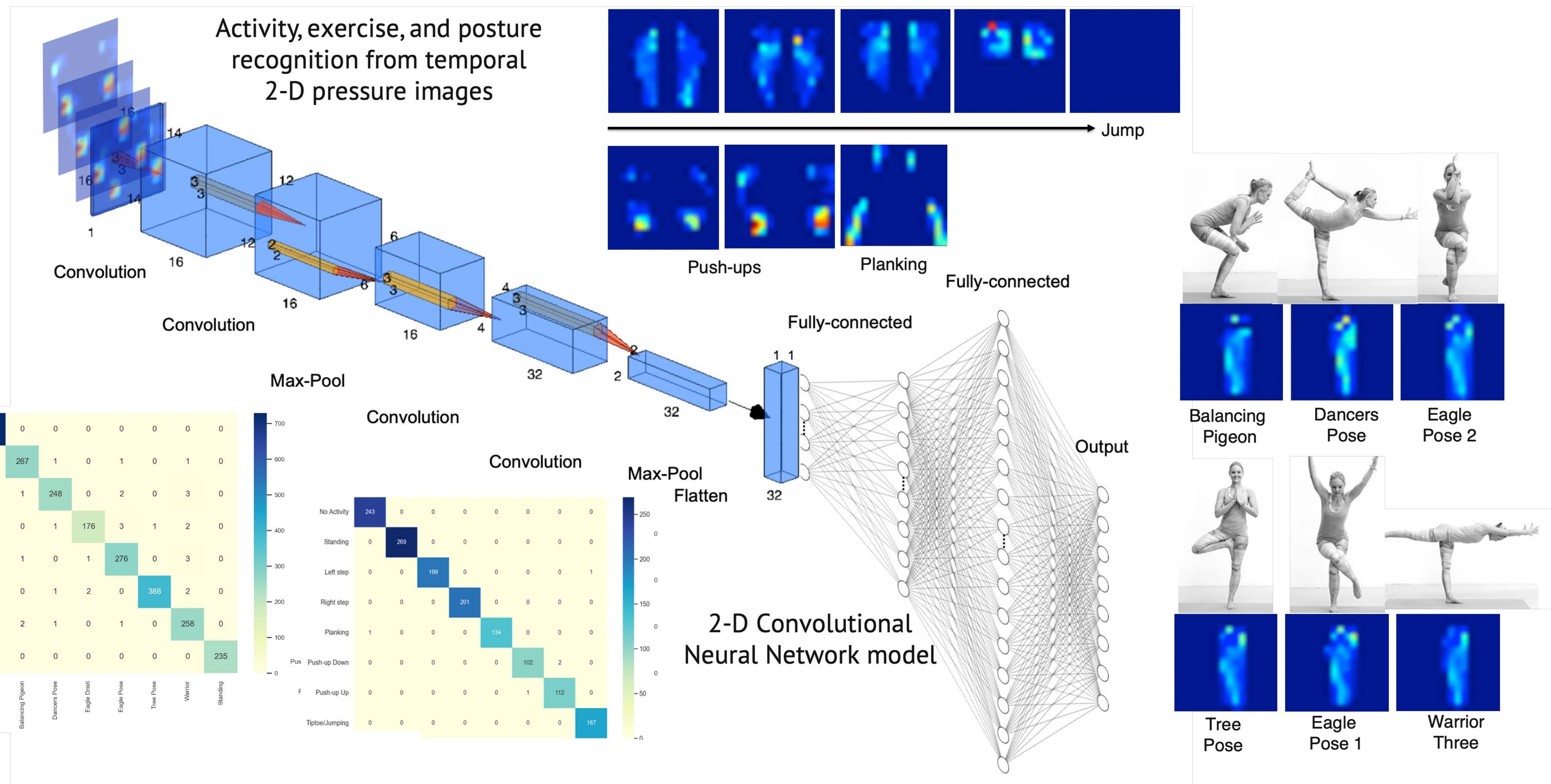
Our multiplexing circuit (16x16)

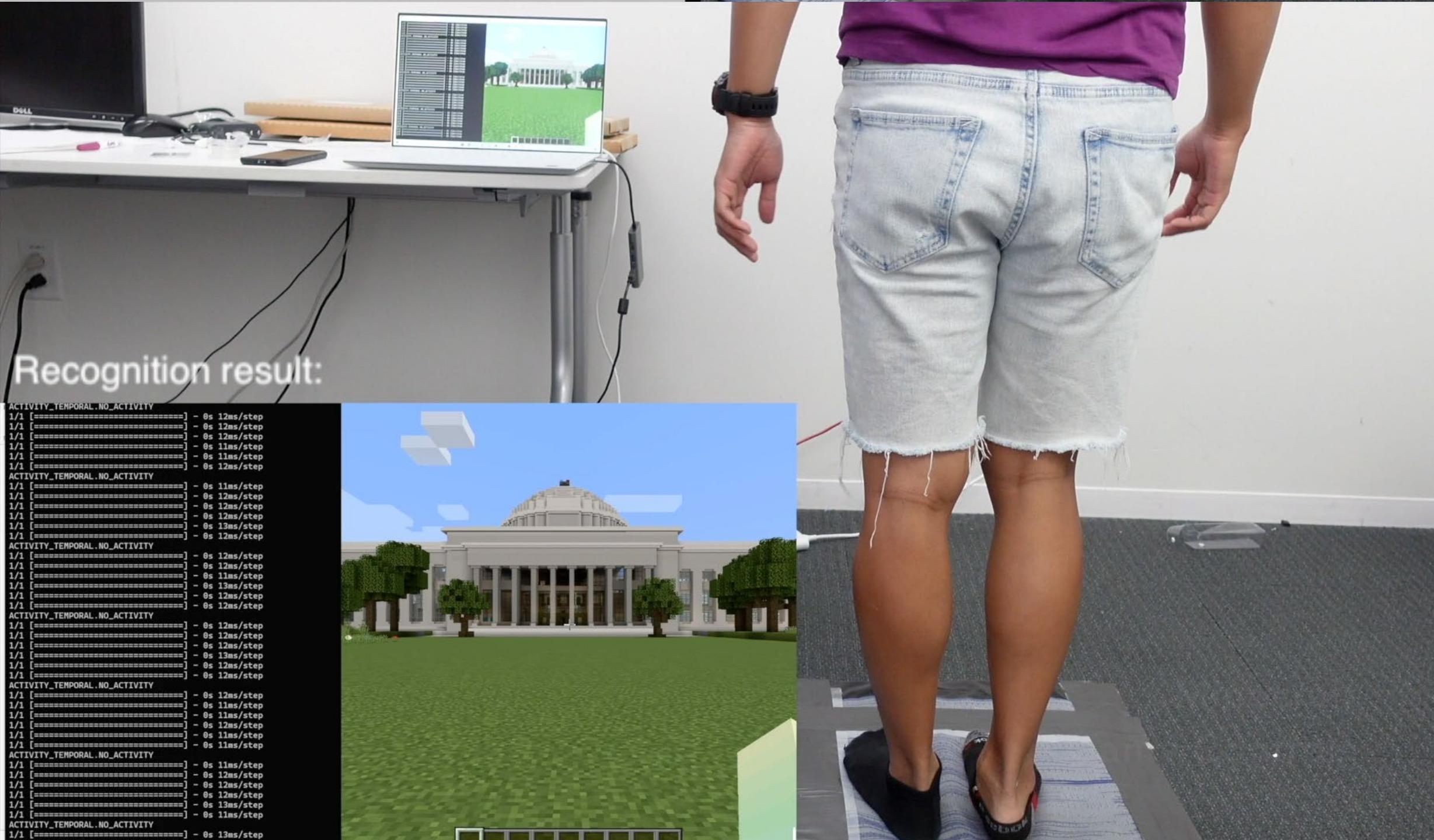
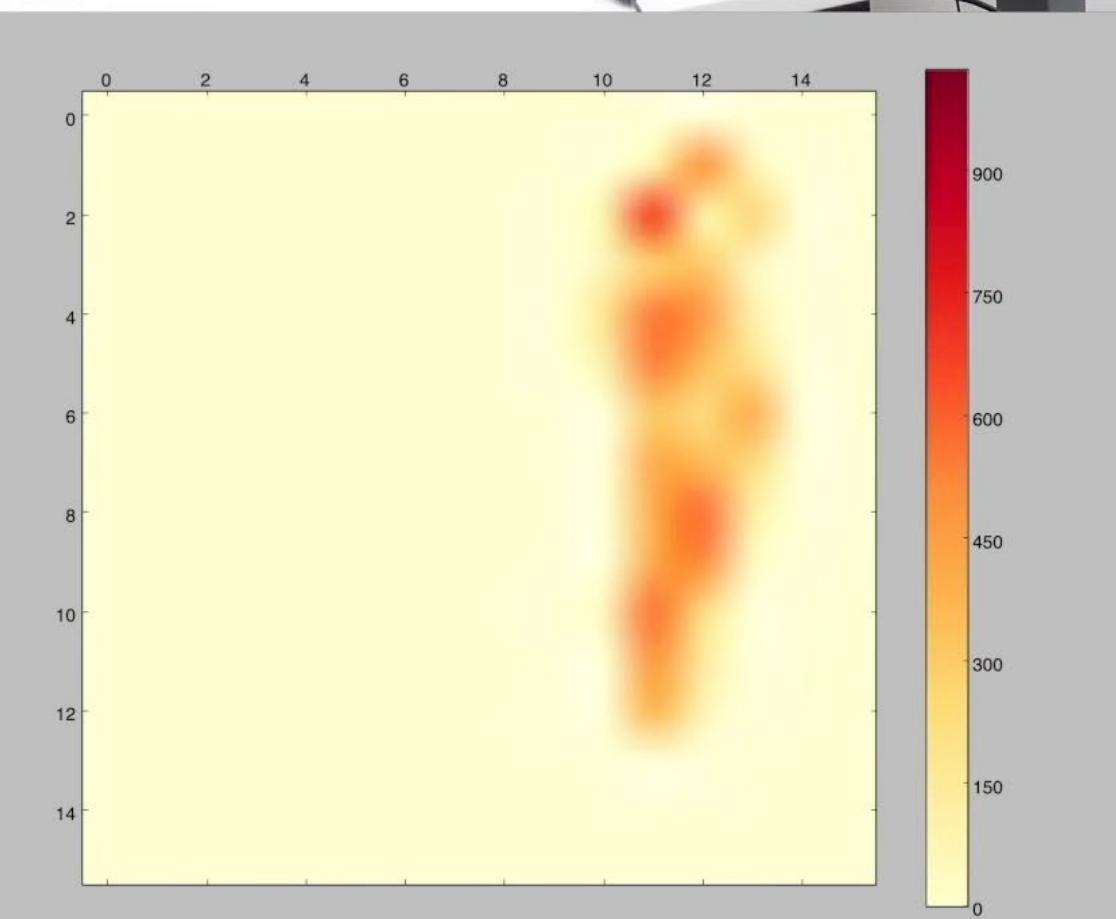


Dense spatiotemporal pressure-imaging

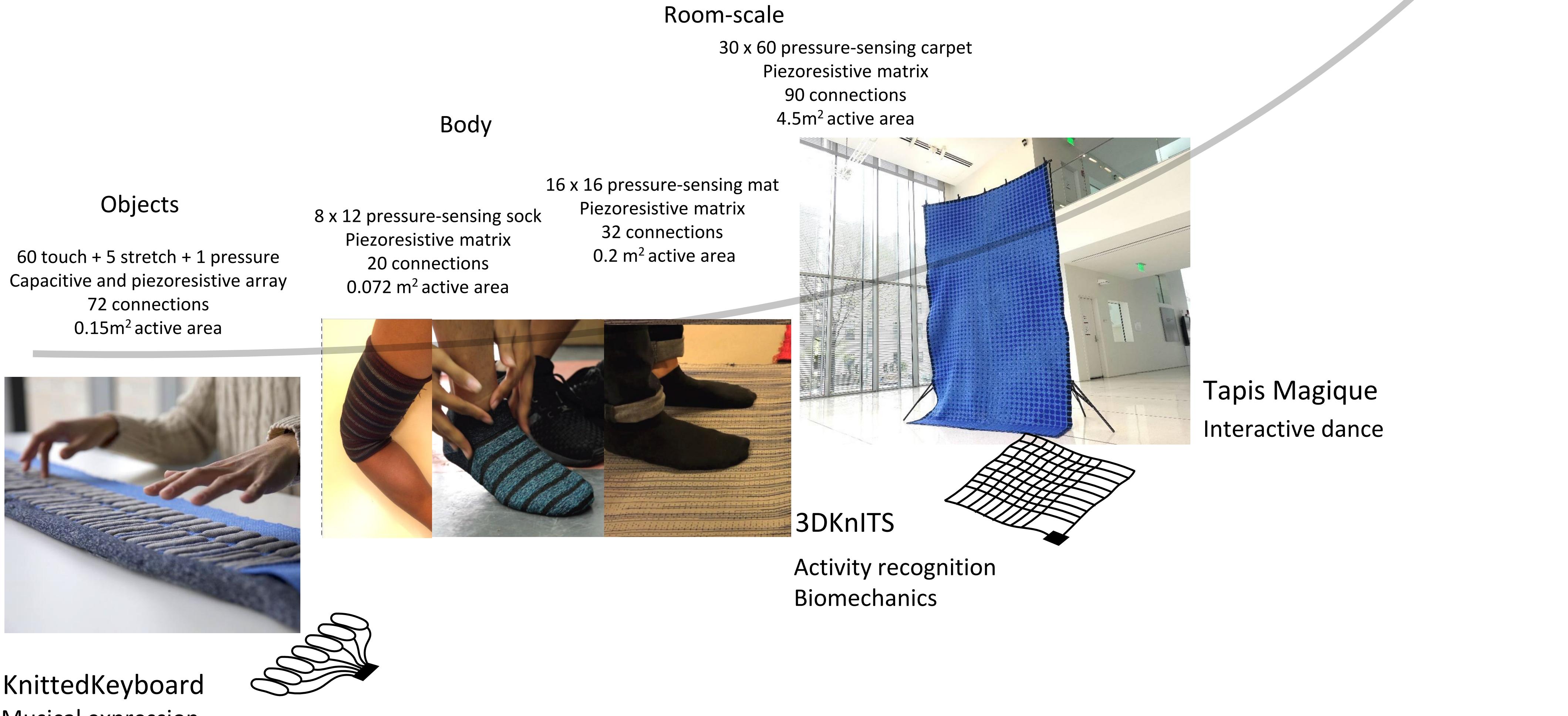


Deep learning-enabled applications





Architecting sensate textiles across scales



Cage/Cunningham Variations V

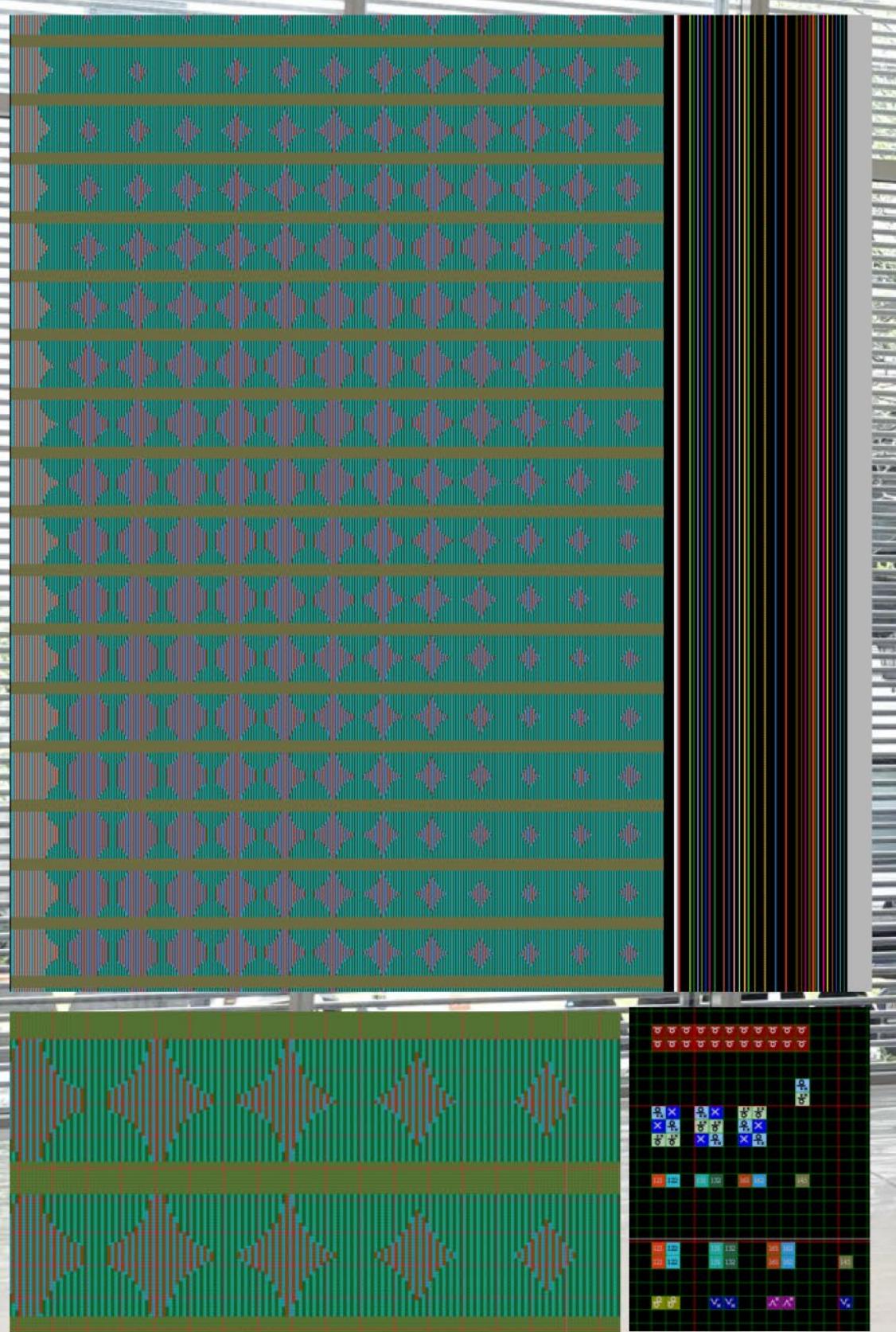


Related Work



Magic Carpet (1997)
Paradiso, Hsiao, Greenworld

Tapis Magique







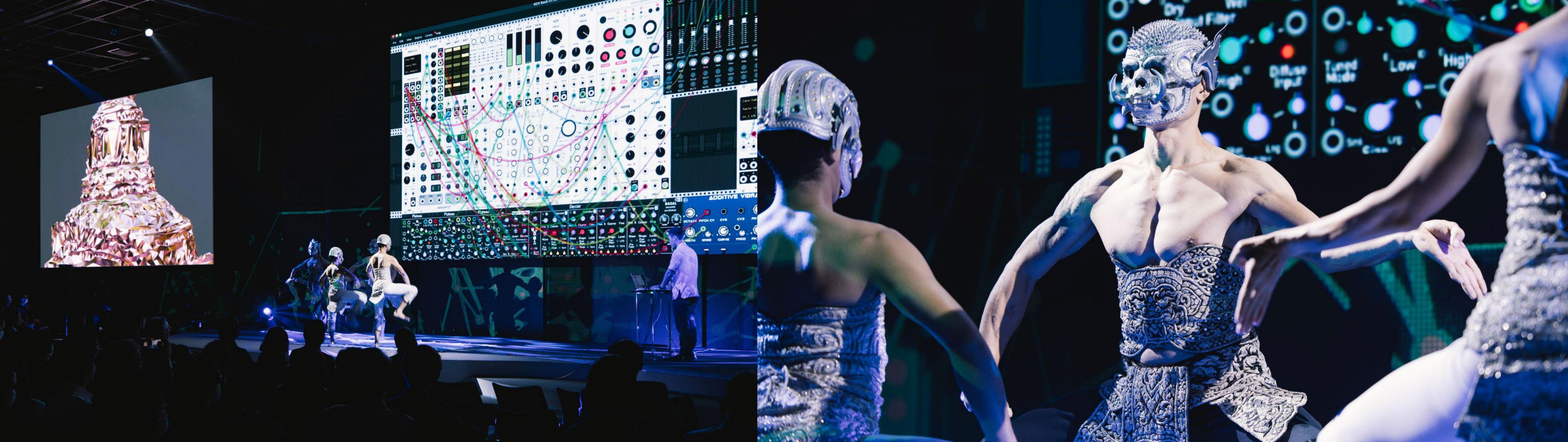
Choreographer, Dancer: Loni Landon, Sound Mapping: Don Derek Haddad

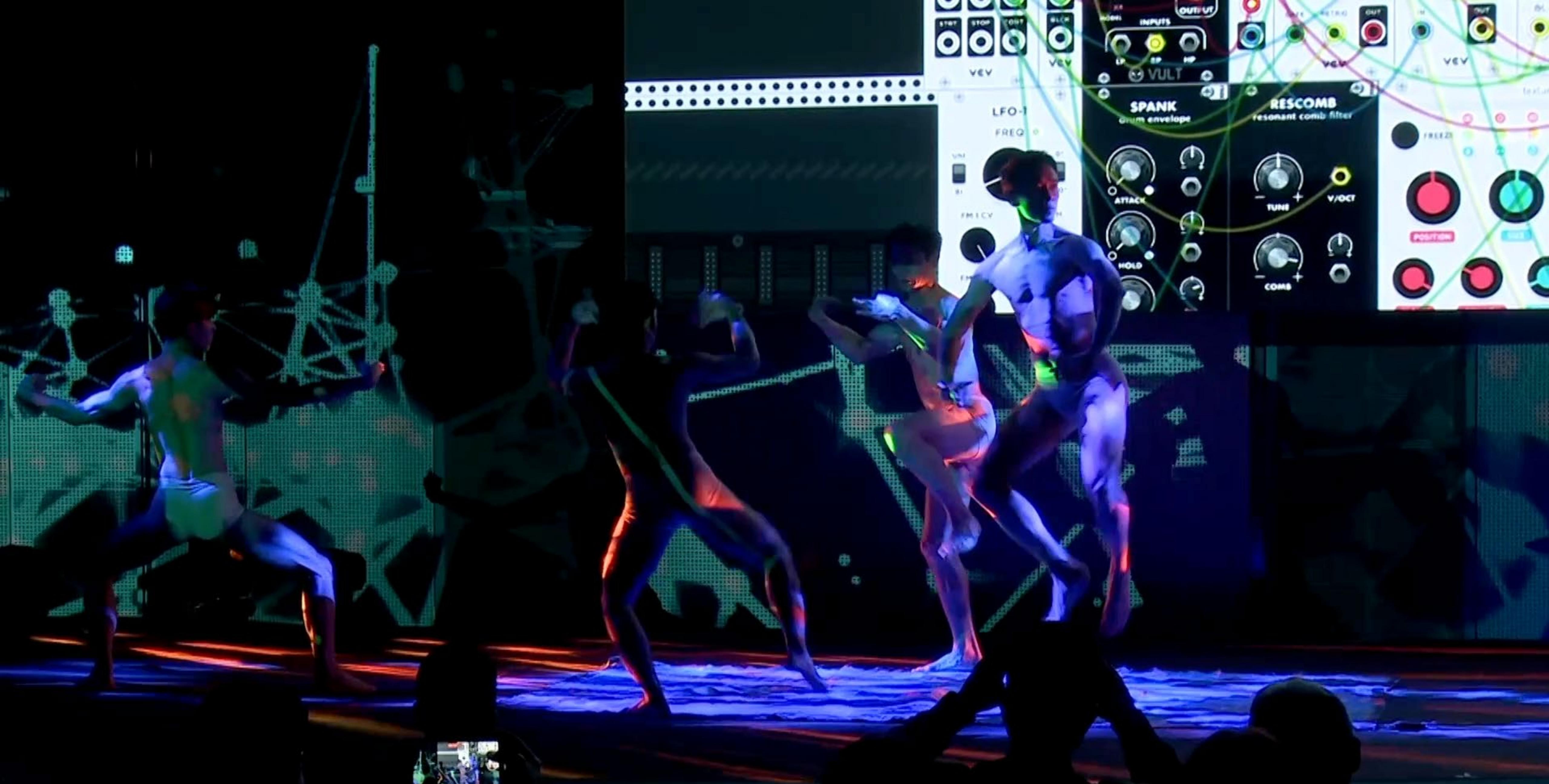


Choreographer, Dancer: Loni Landon, Sound Mapping: Don Derek Haddad



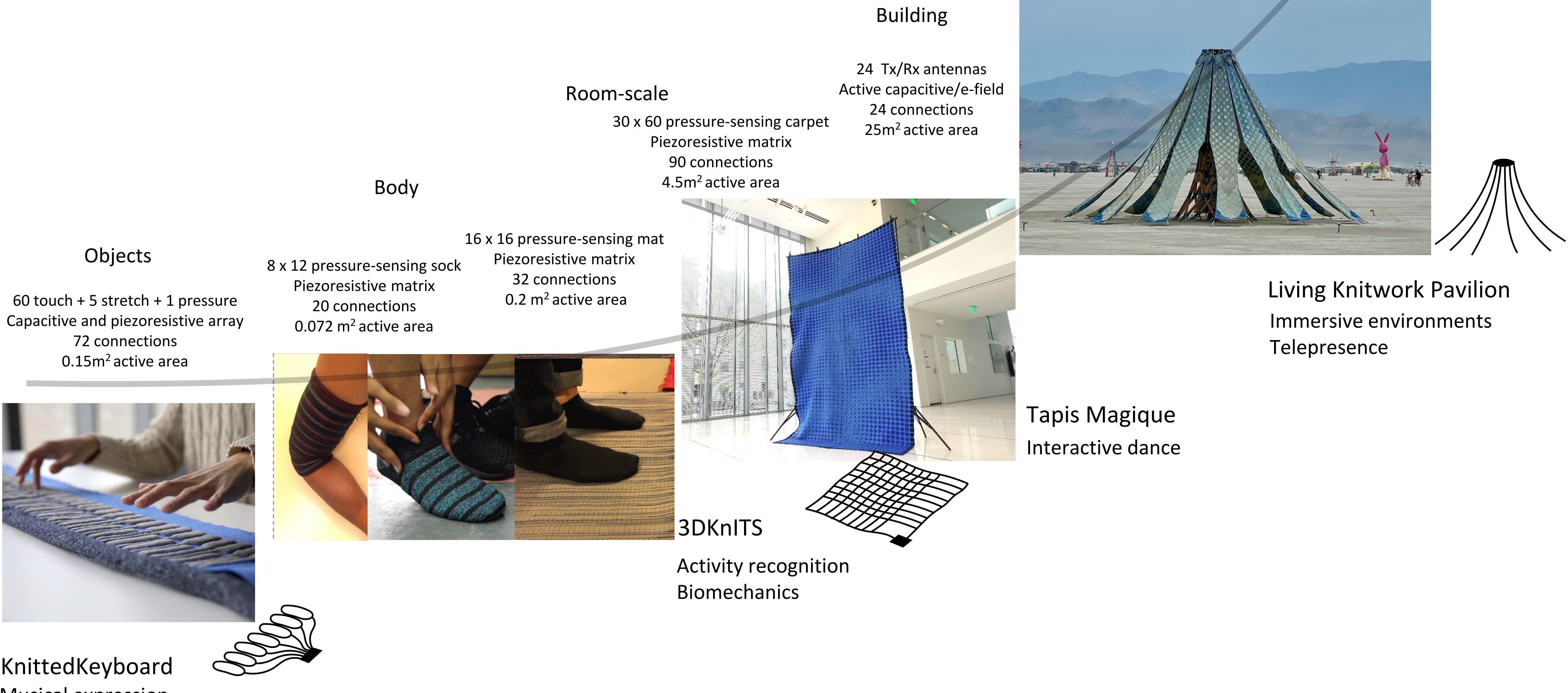
Choreographer, Dancer: Loni Landon, Sound Mapping: Don Derek Haddad





Performance: Pichet Klunchun Dance Company, Sound Mapping: Don Derek Haddad

Architecting sensate textiles across scales



Black Rock City, NV



The background is a soft-focus photograph of a vast, sandy or dusty landscape, possibly a desert or a large sand dune. In the mid-ground, a small, white, boxy vehicle, resembling a vintage car or a mobile art installation, is visible, appearing as a dark silhouette against the light-colored dust. The overall atmosphere is hazy and dreamlike.

Waking Dreams

BURNING MAN 2022

Living Knitwork Pavilion



Related Work



Lumen (2017)
Jenny Sabin Studio
MoMA PS1, New York



KnitCandela (2018)
Block Research Group/ETH Zurich & Zaha Hadid Architects
MUAC, Mexico City

Living Knitwork Pavilion



Welcome to the
MIT Media Lab



Living Knitwork Pavilion

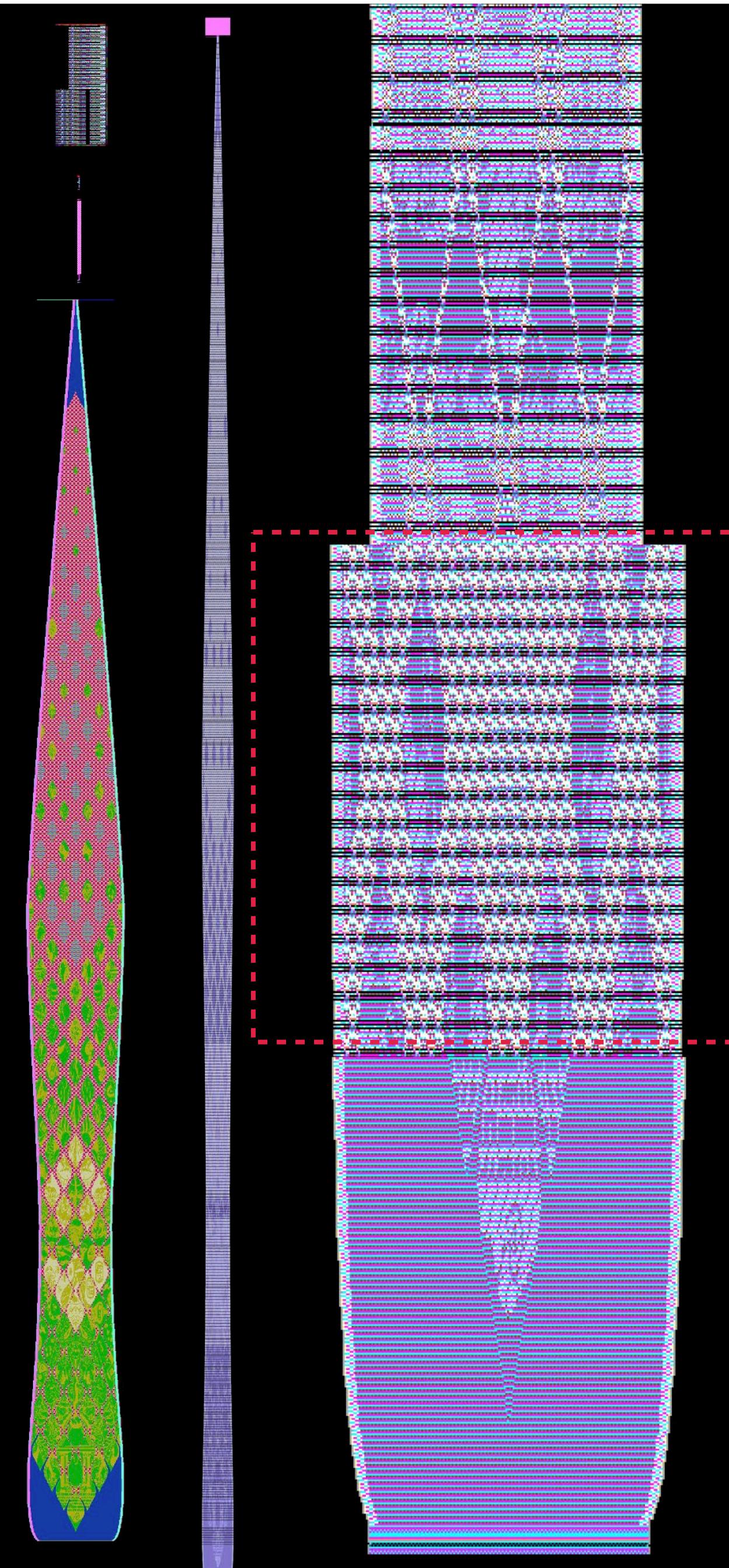
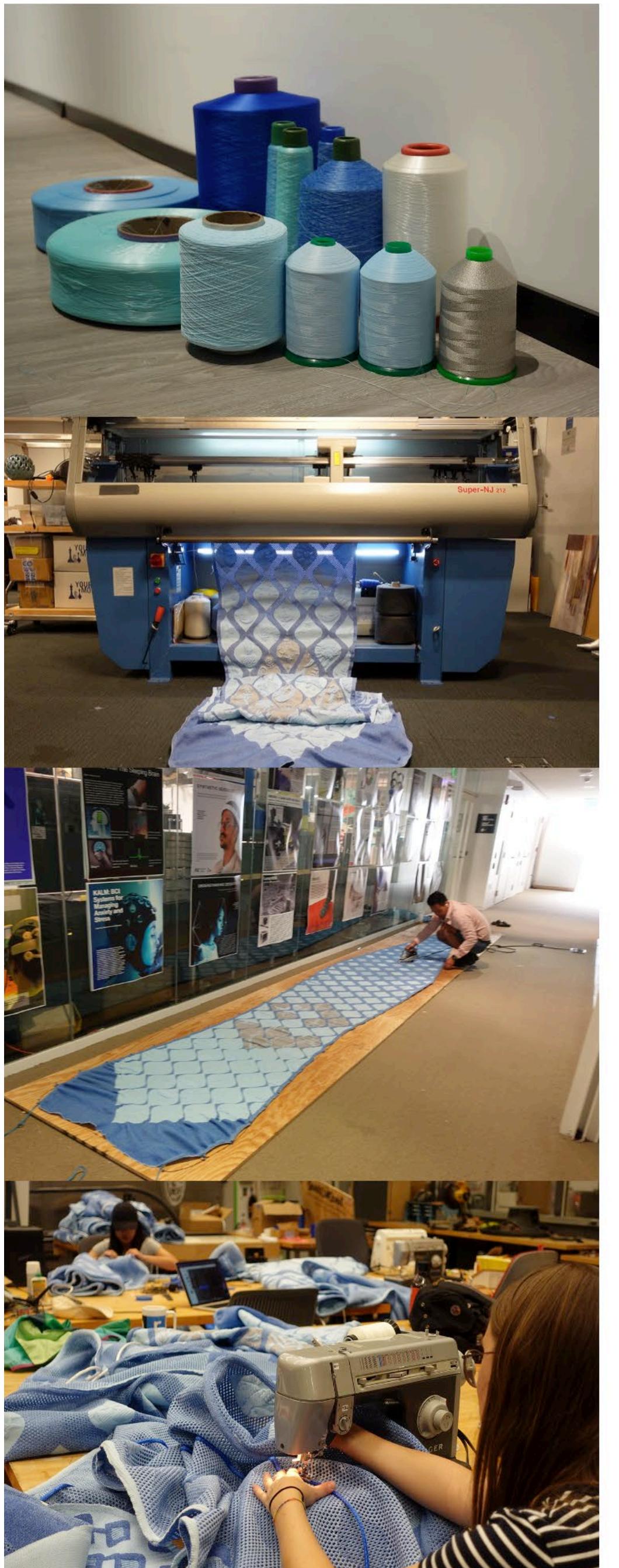
Textile popped-up patterns, inspired by cultural heritage



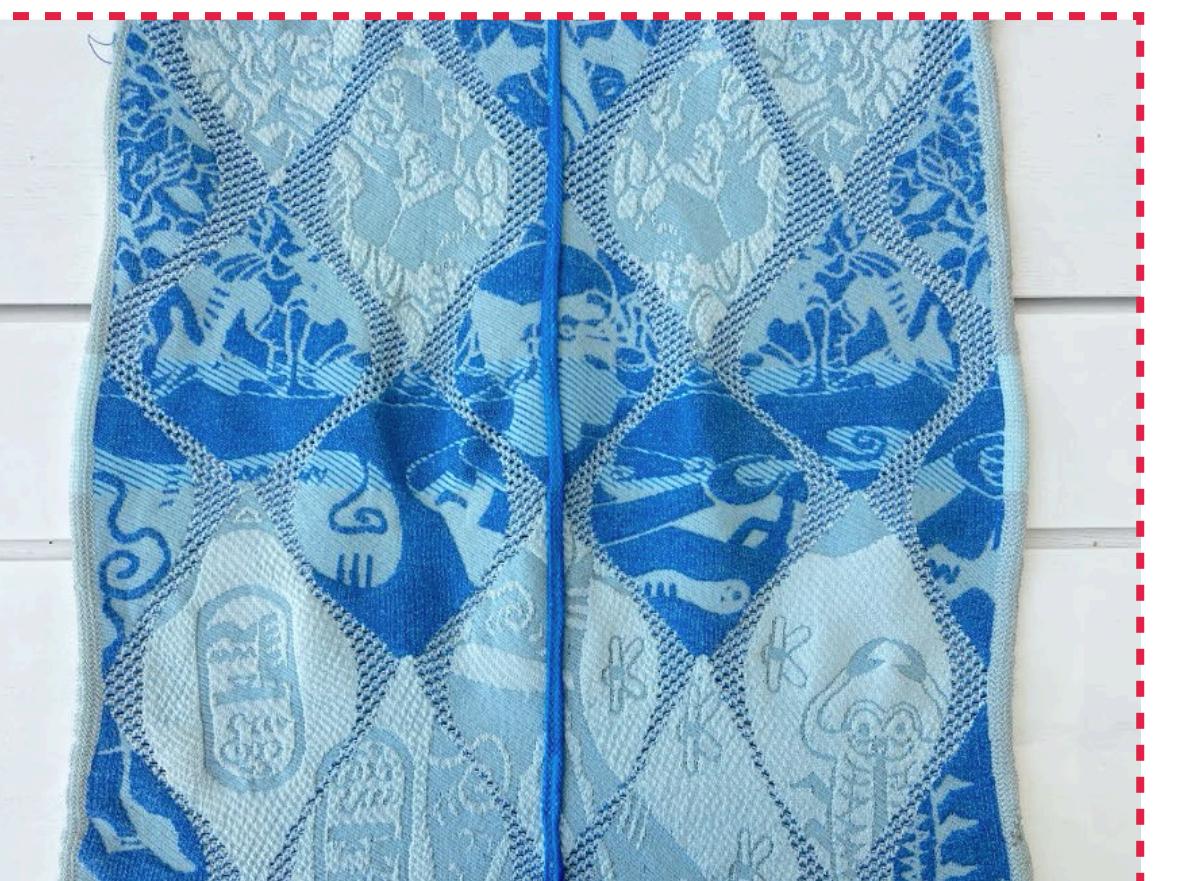
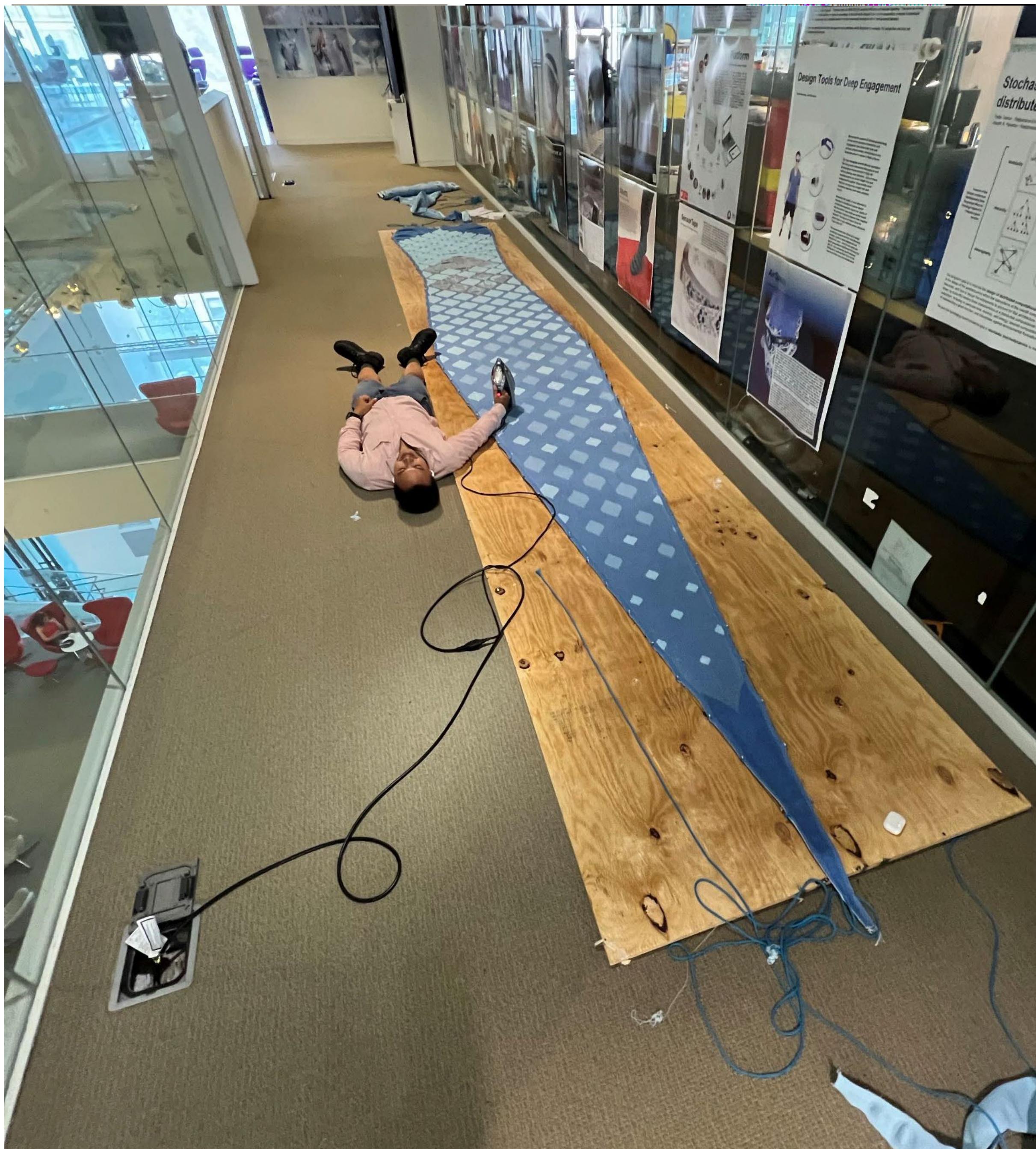
Balinese Pura



Digital Knitting of Sensate Textiles

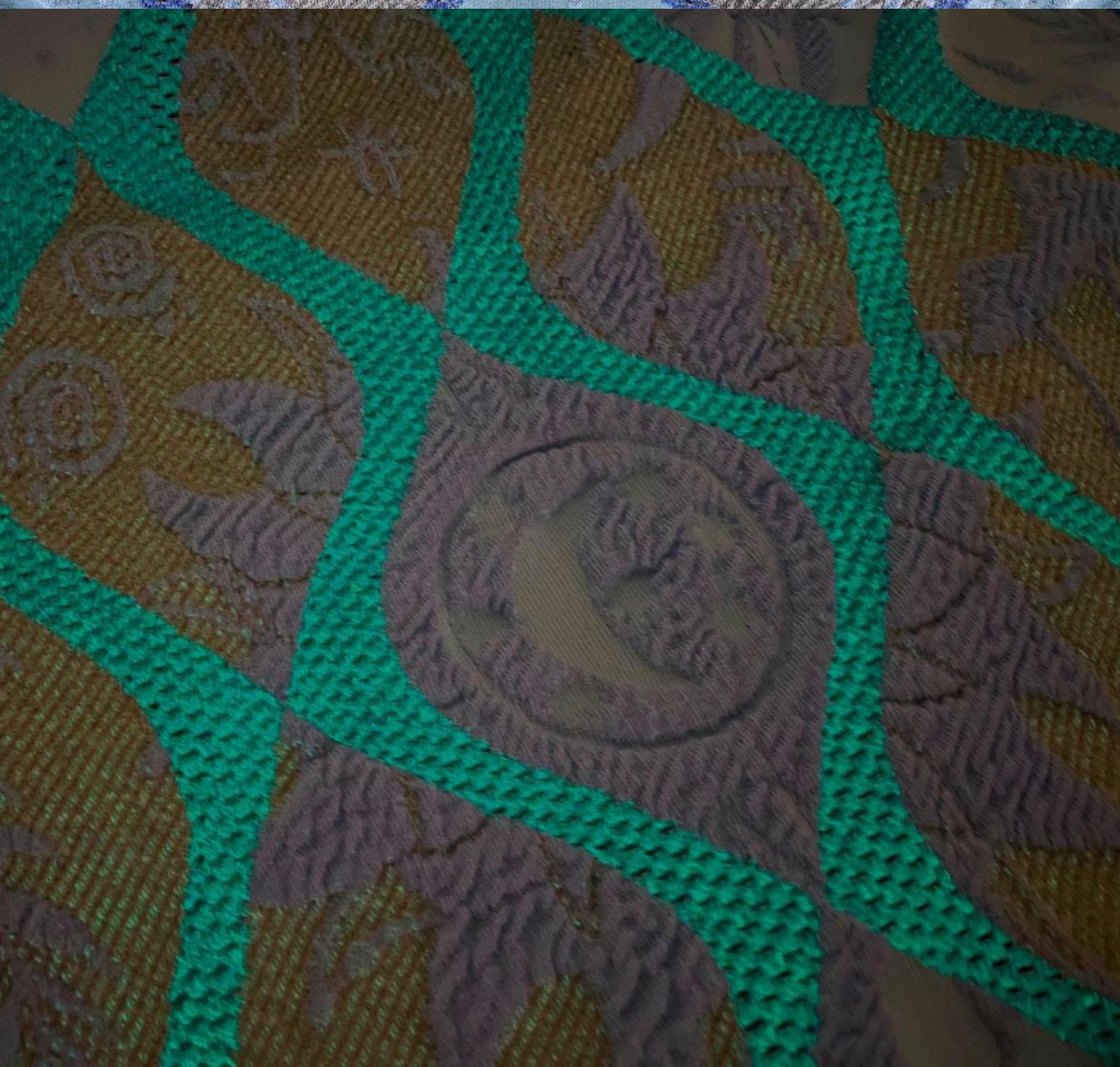


Digital Knitting of Sensate Textiles



Living Knitwork Pavilion

Integrated functional yarns



Living Knitwork Pavilion

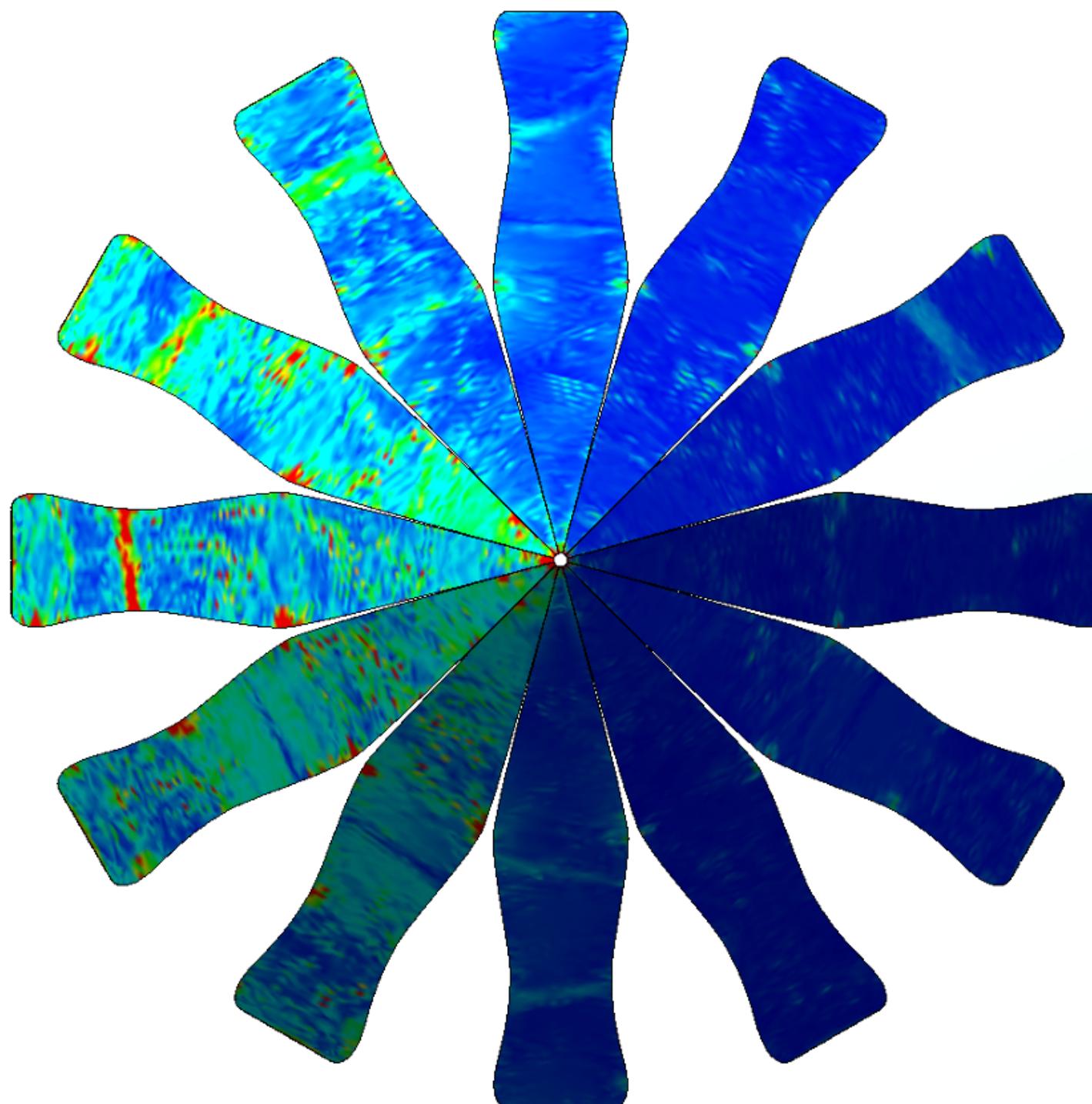
On-site building crew



Age van der Mei
Sam Chin,
Judyta Cichoka
Gabriela Advincula
Erik Strand
Alfonso Parra Rubio,
Nicole Bakker

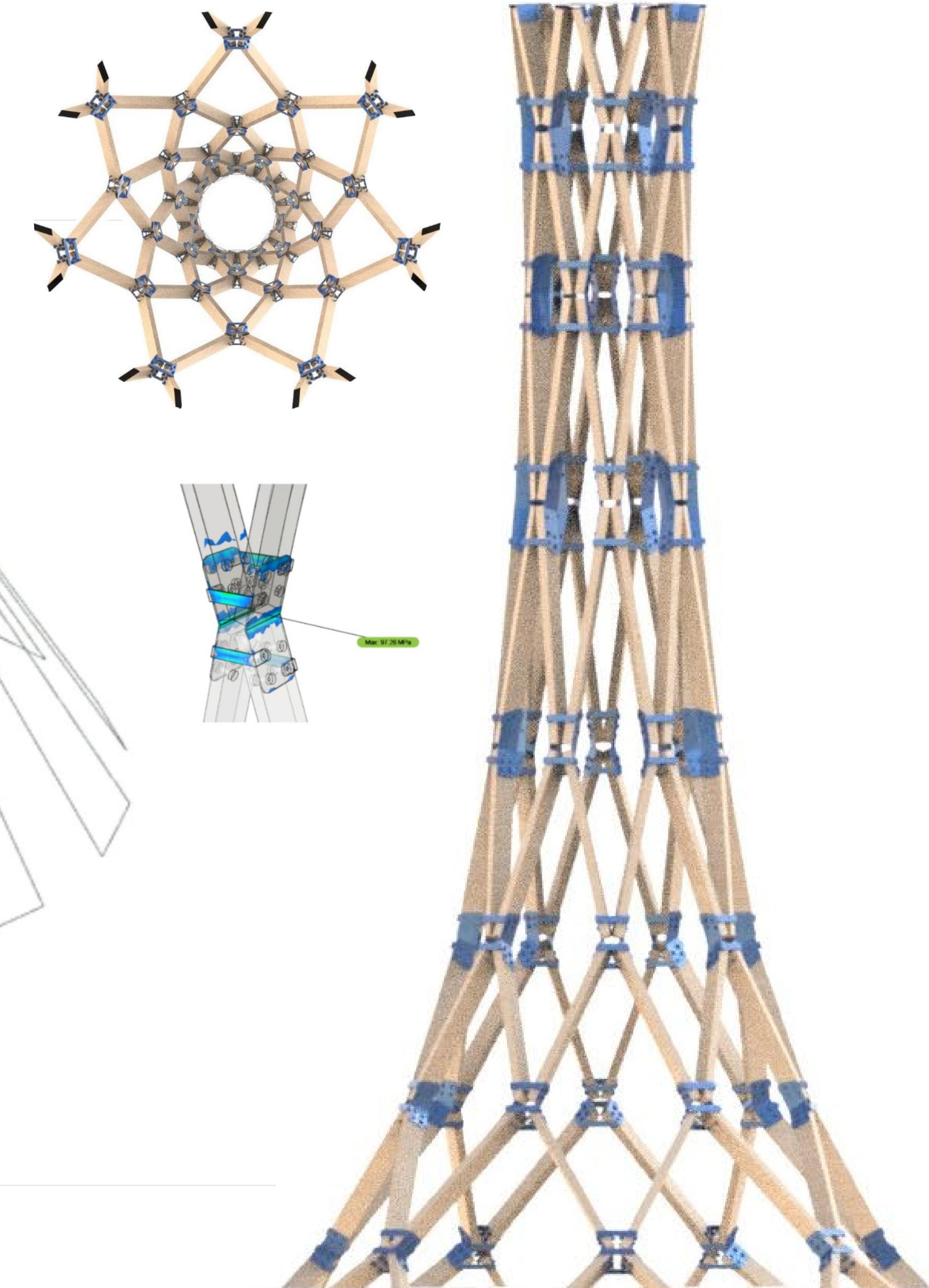
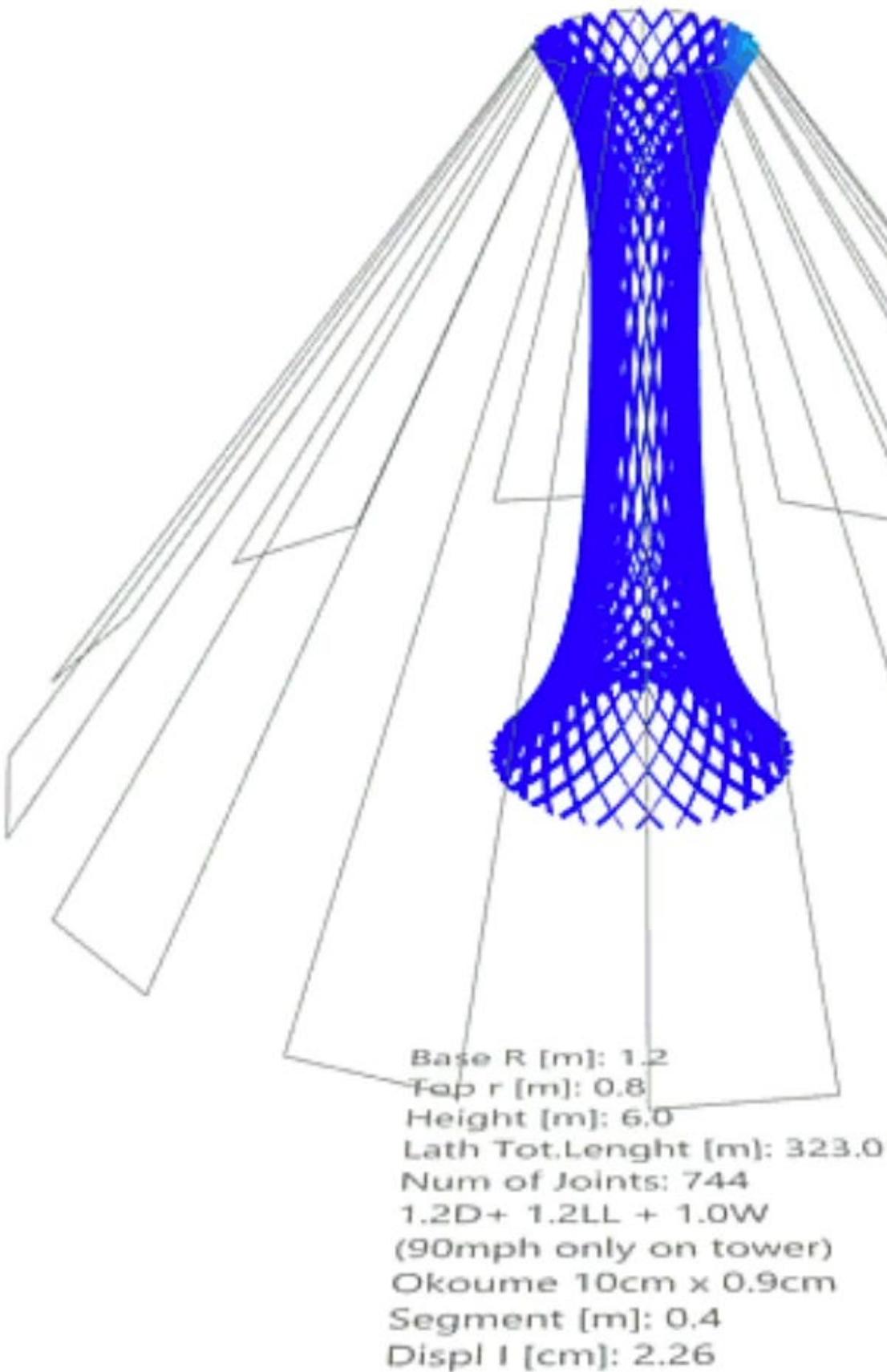
Living Knitwork Pavilion

Designing temporary structures for extreme environments



von Mises

3.0
2.7
2.4
2.1
1.8
1.5
1.2
0.9
0.6
0.3
0.0



Wind simulation: Tongge Yu

Central structure design: Judyta Cichoka, Alfonso Parra Rubio

Wicaksono, Rubio, Cichoka et al., Living Knitwork Pavilion, accepted (2024)



Timelapse: Gabriela Advincula



Timelapse: Gabriela Advincula



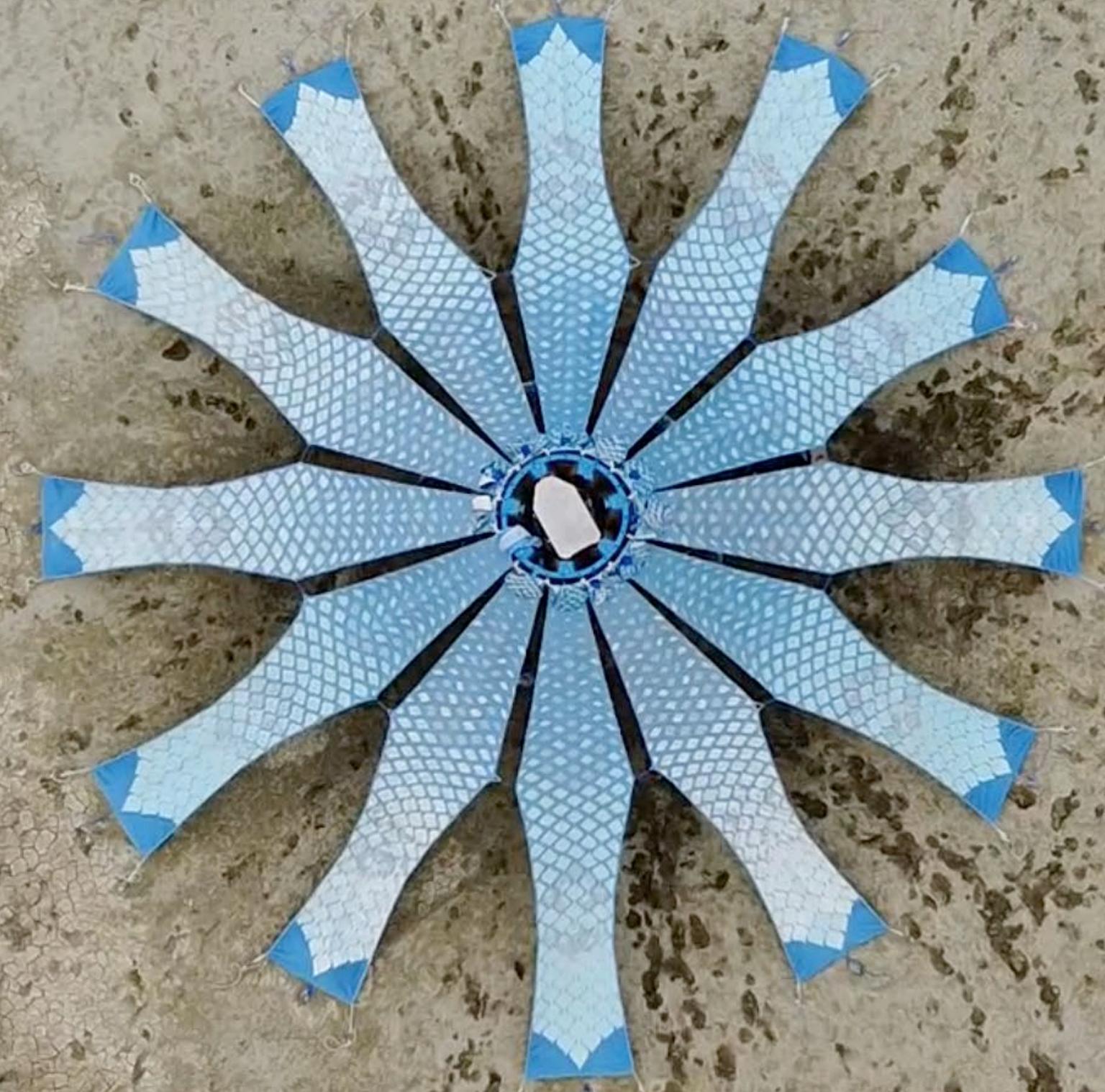
Timelapse: Gabriela Advincula



Timelapse: Gabriela Advincula

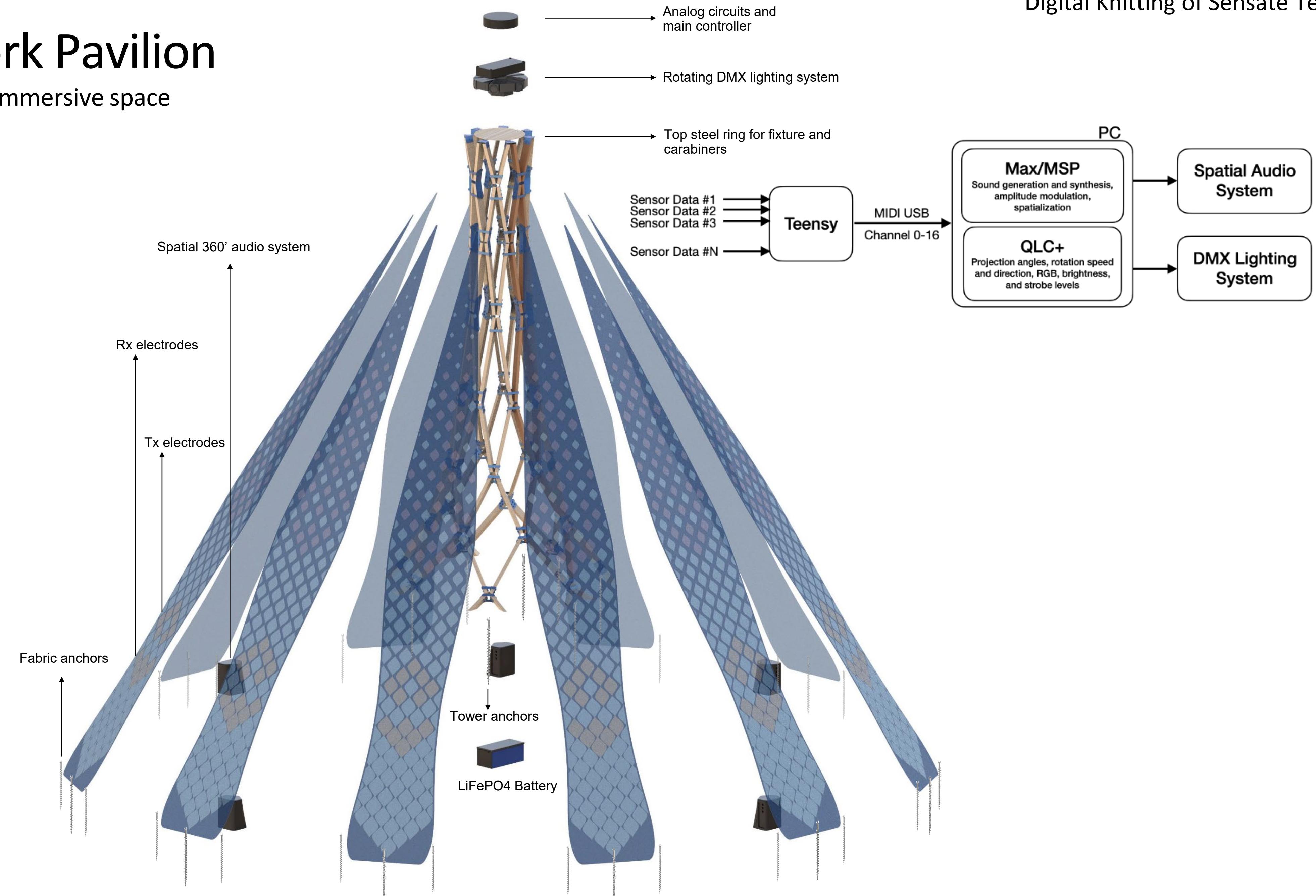






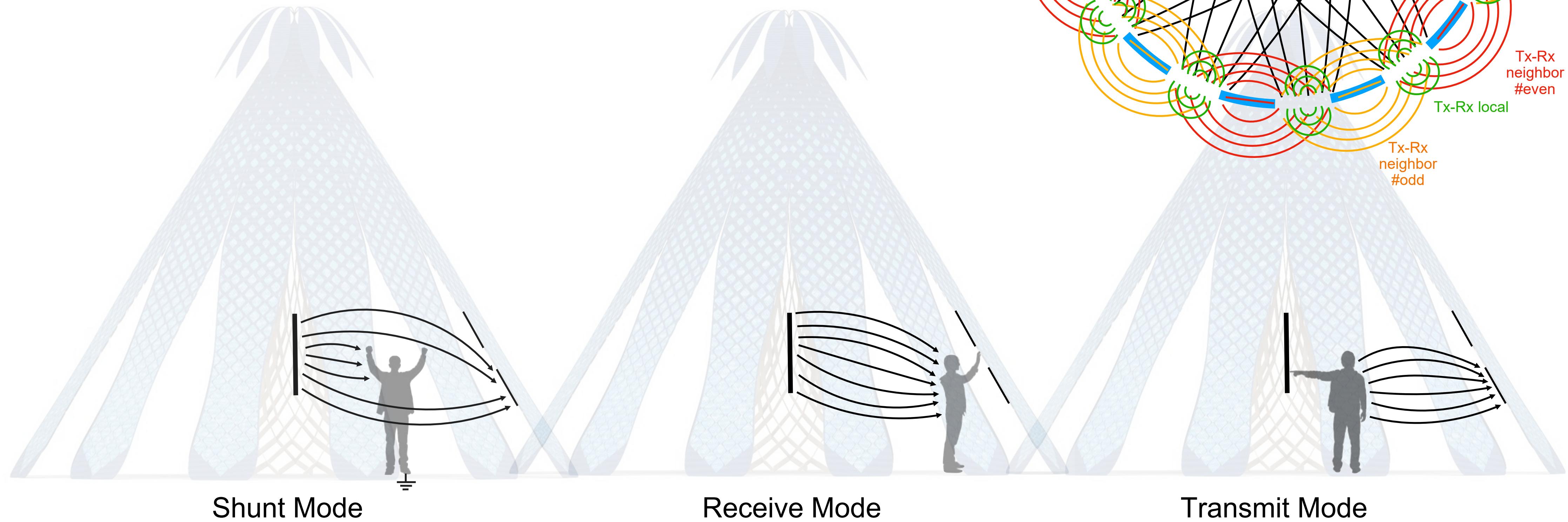
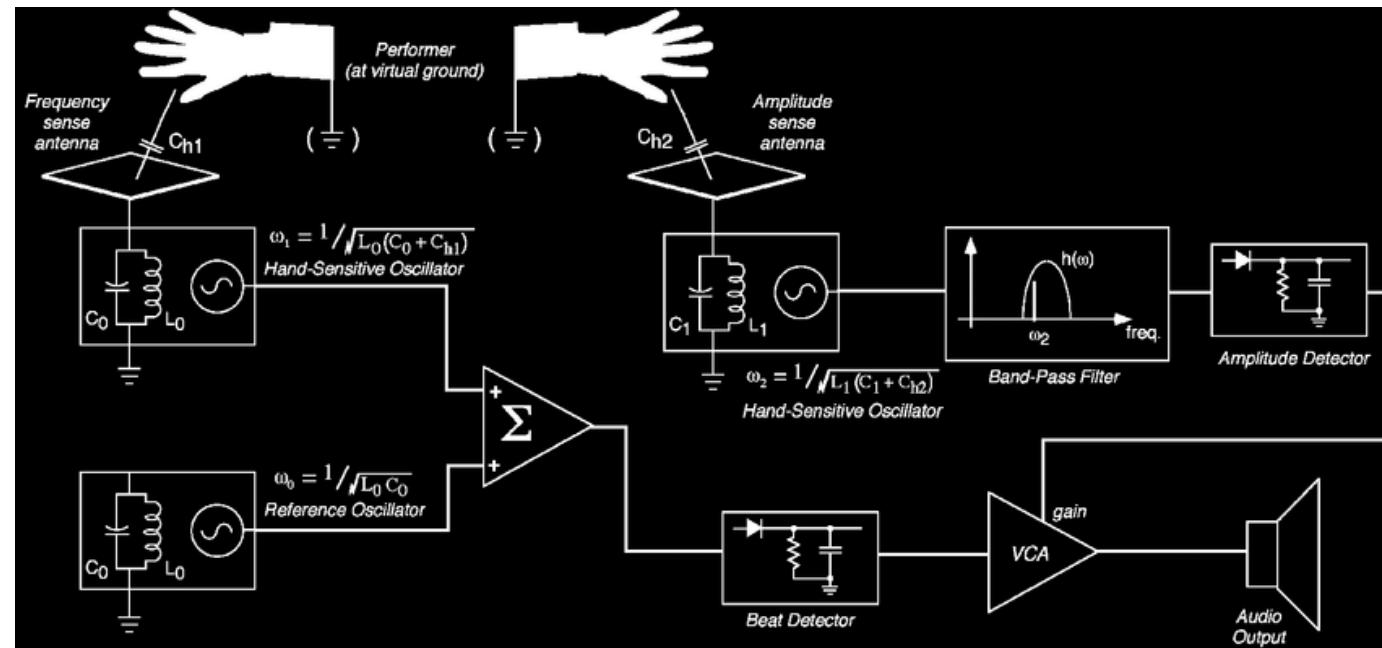
Living Knitwork Pavilion

Integrated system for an immersive space



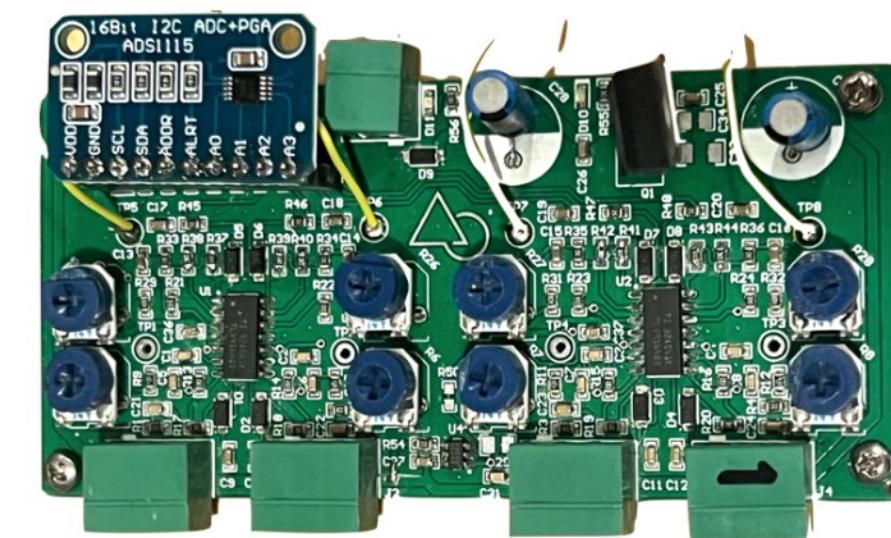
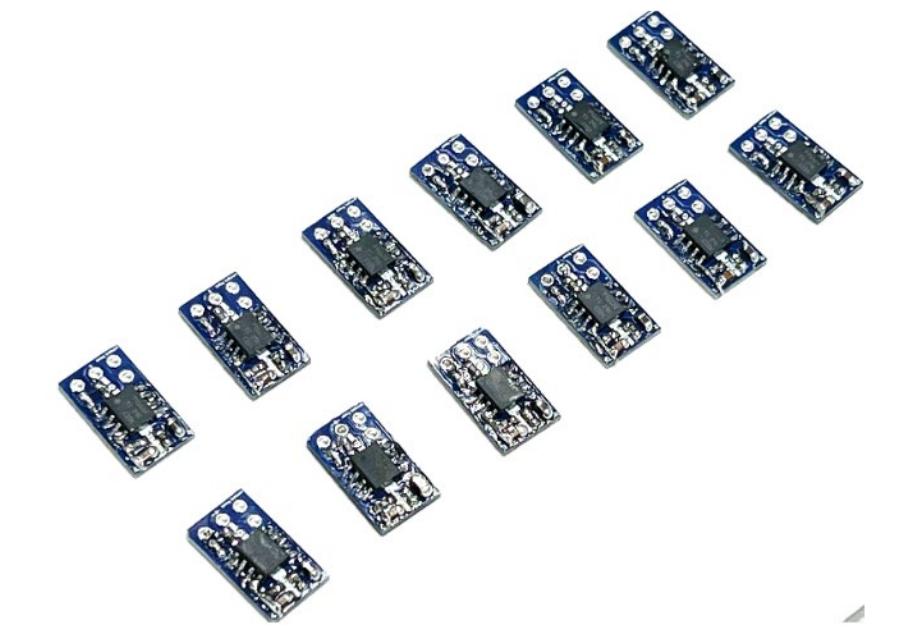
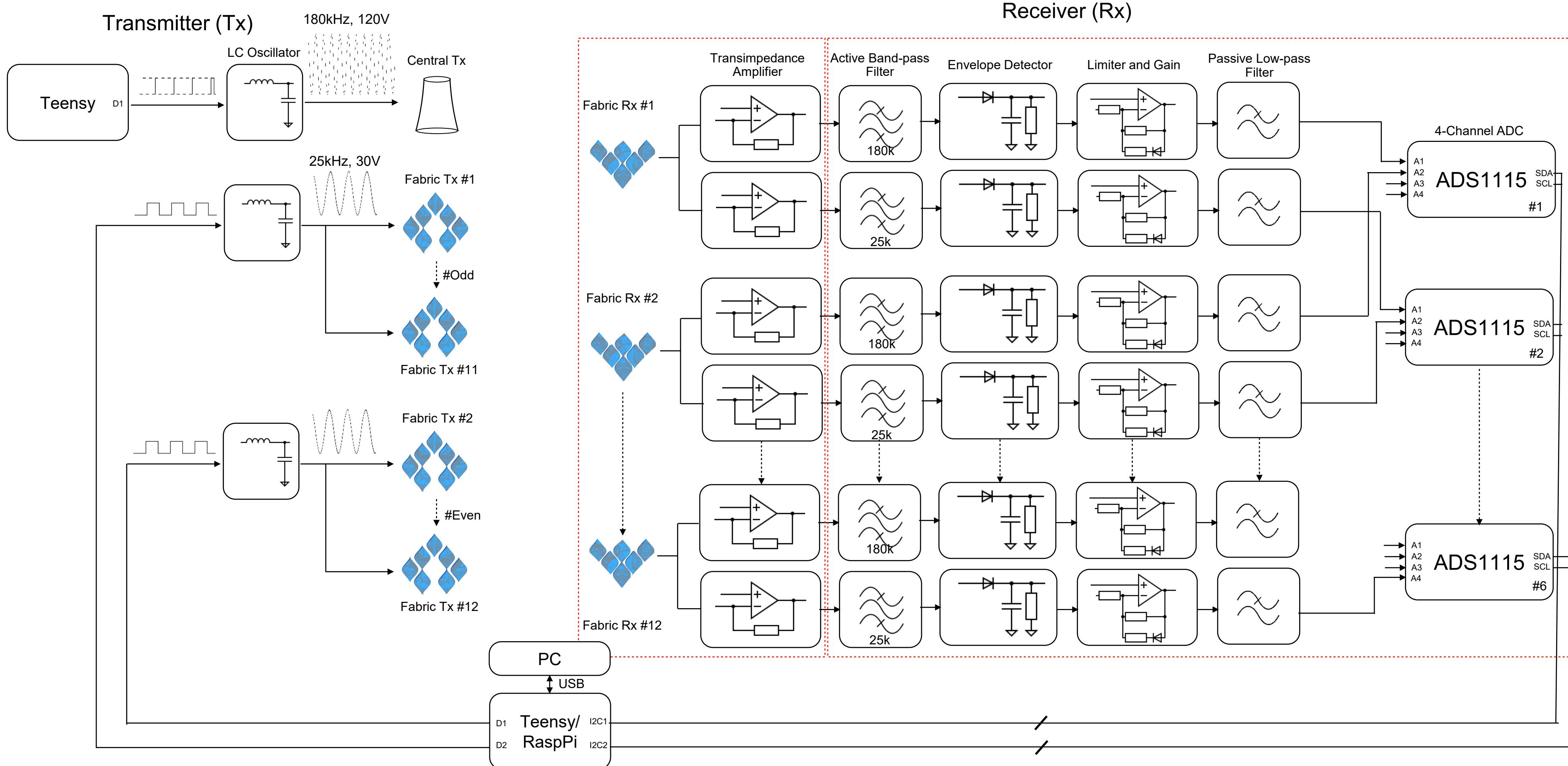
Living Knitwork Pavilion

An architectural theremin, distributed e-field sensing

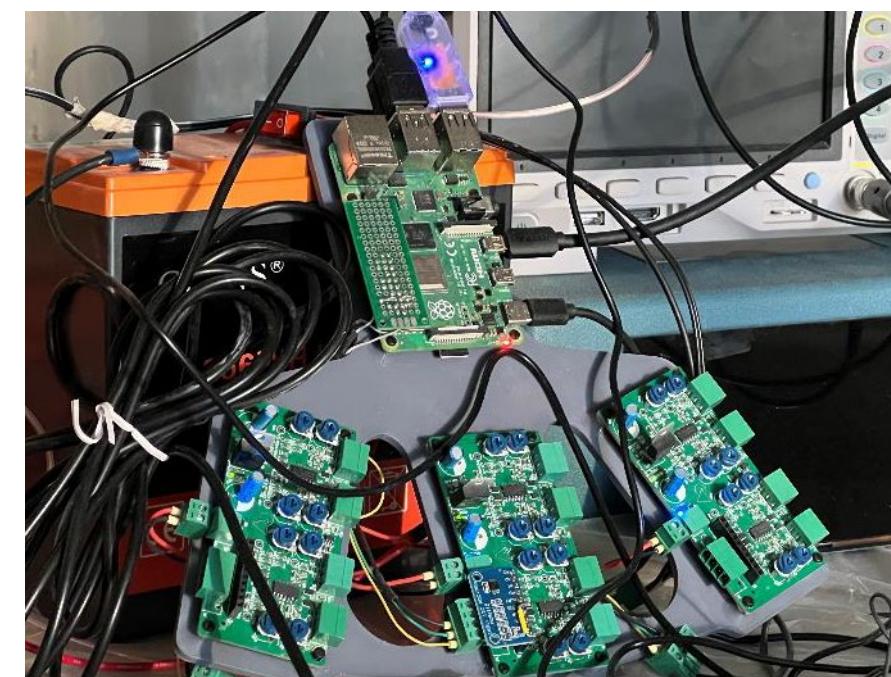


Living Knitwork Pavilion

Hardware system for e-field sensing

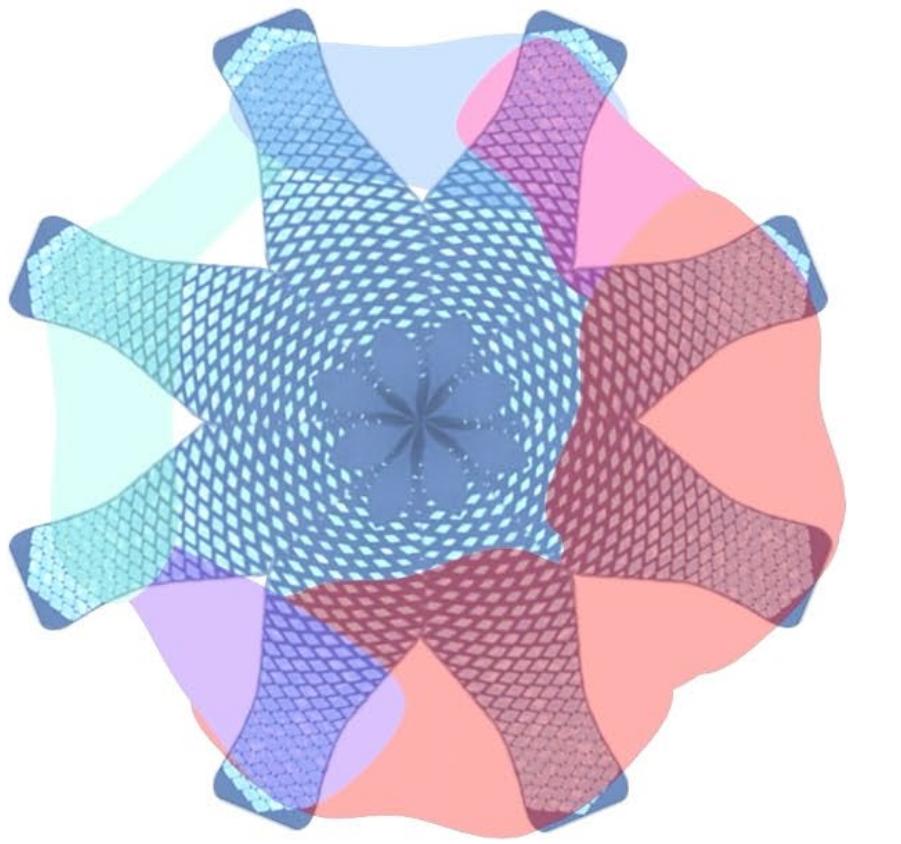


Transimpedance and Rx circuit

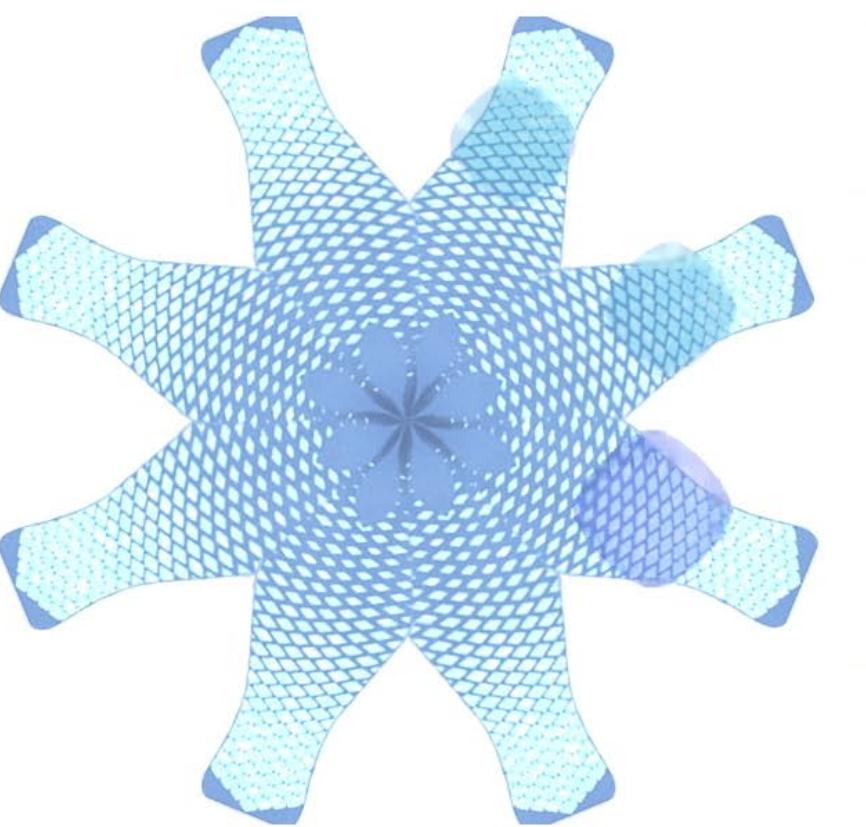
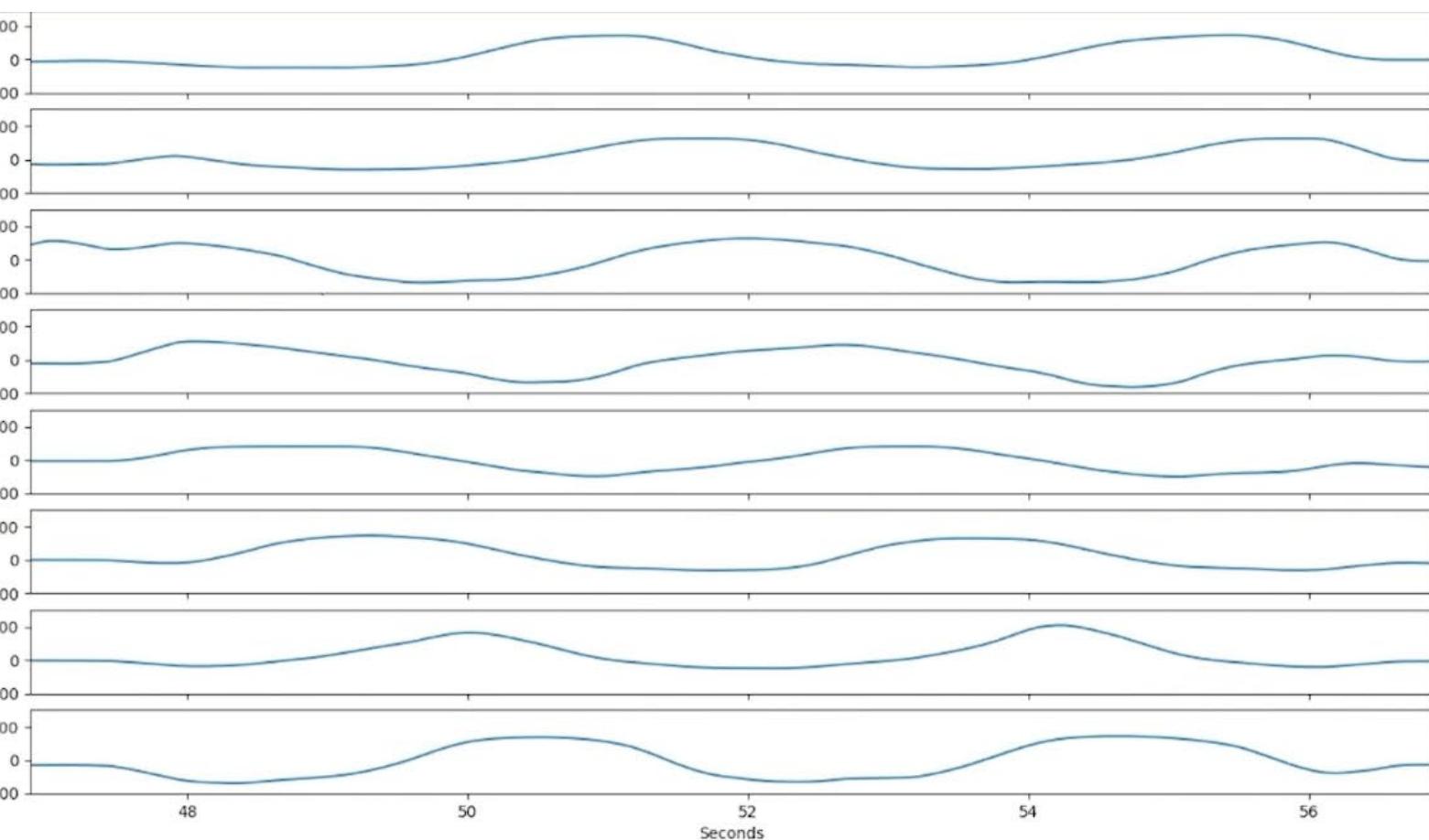


Central module

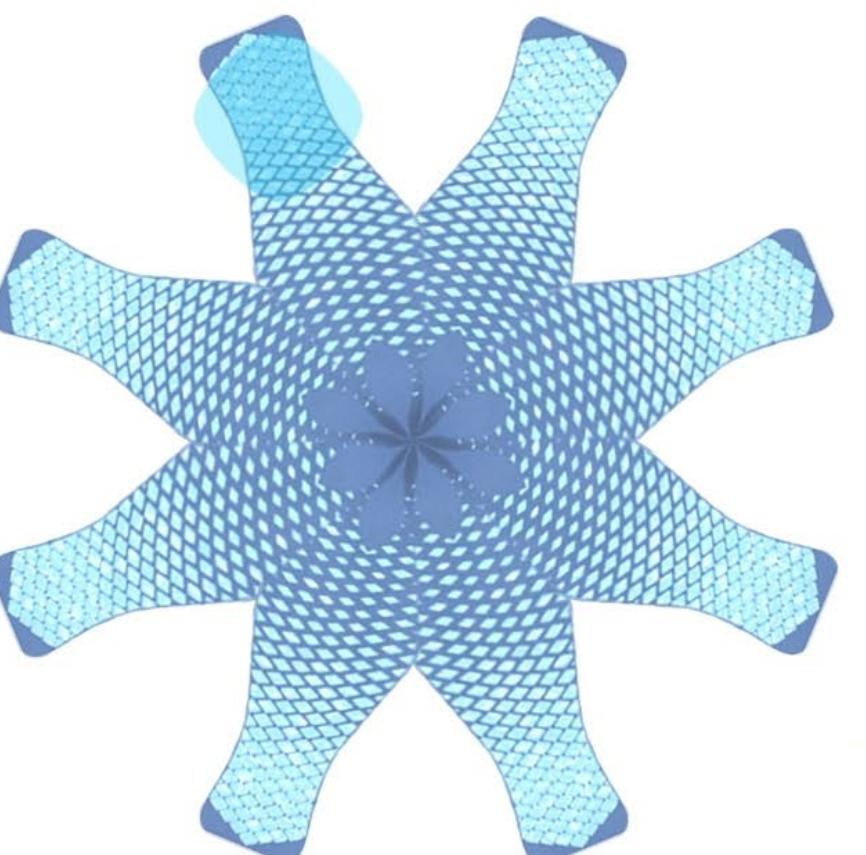
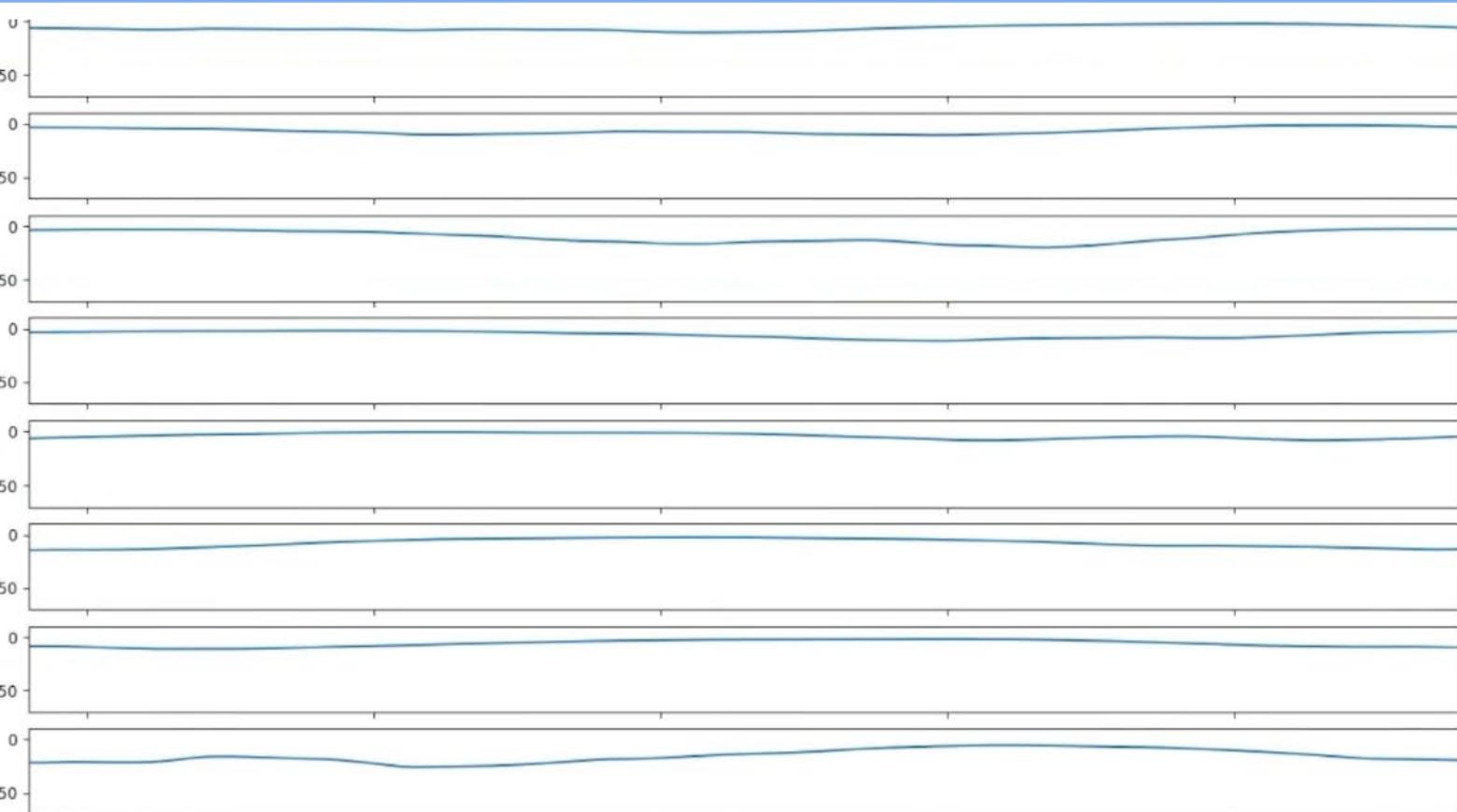
Hardware design with Sam Chin



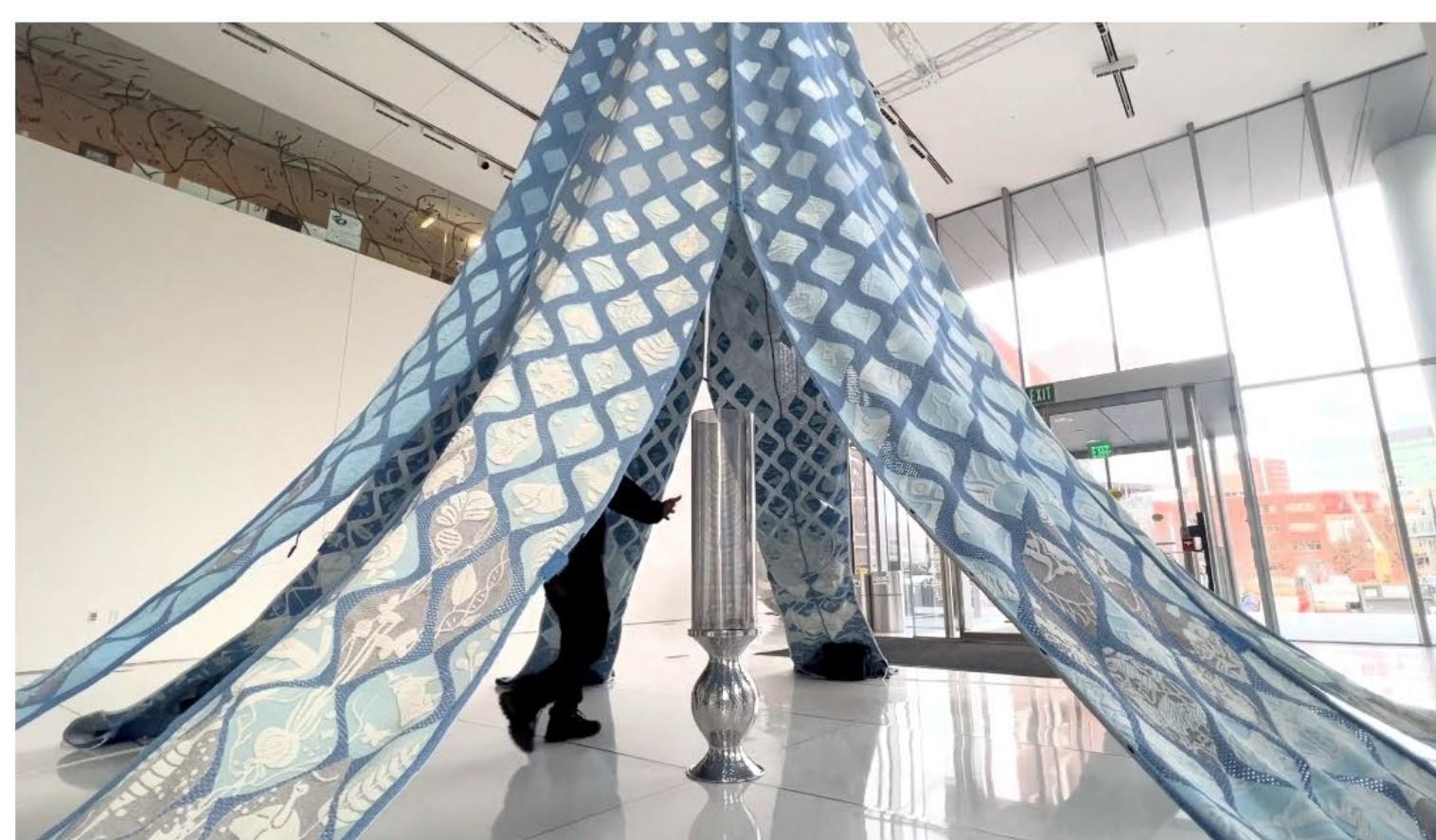
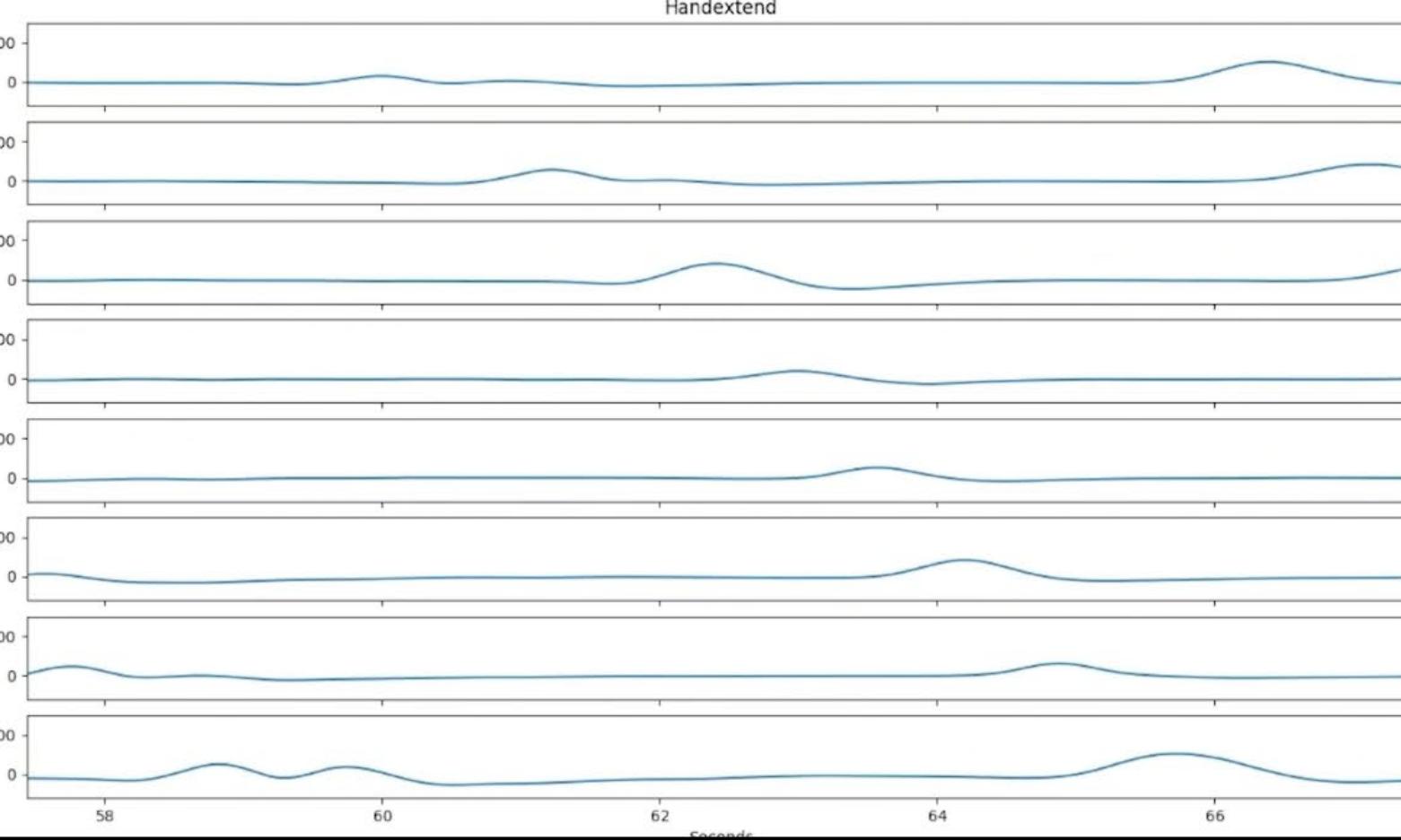
Transmit mode



Shunt mode

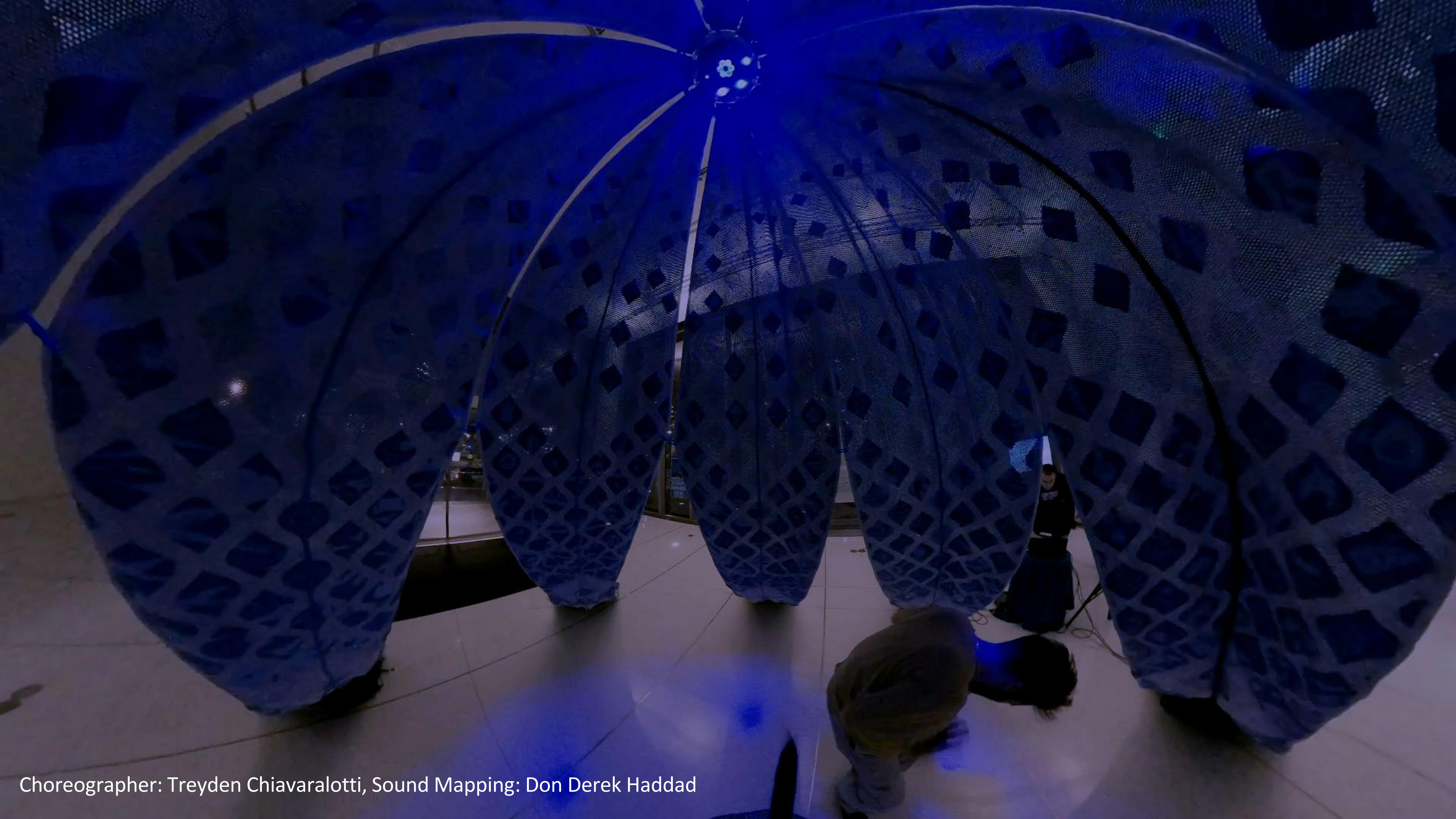


Receive mode





Video: Manaswi Mishra



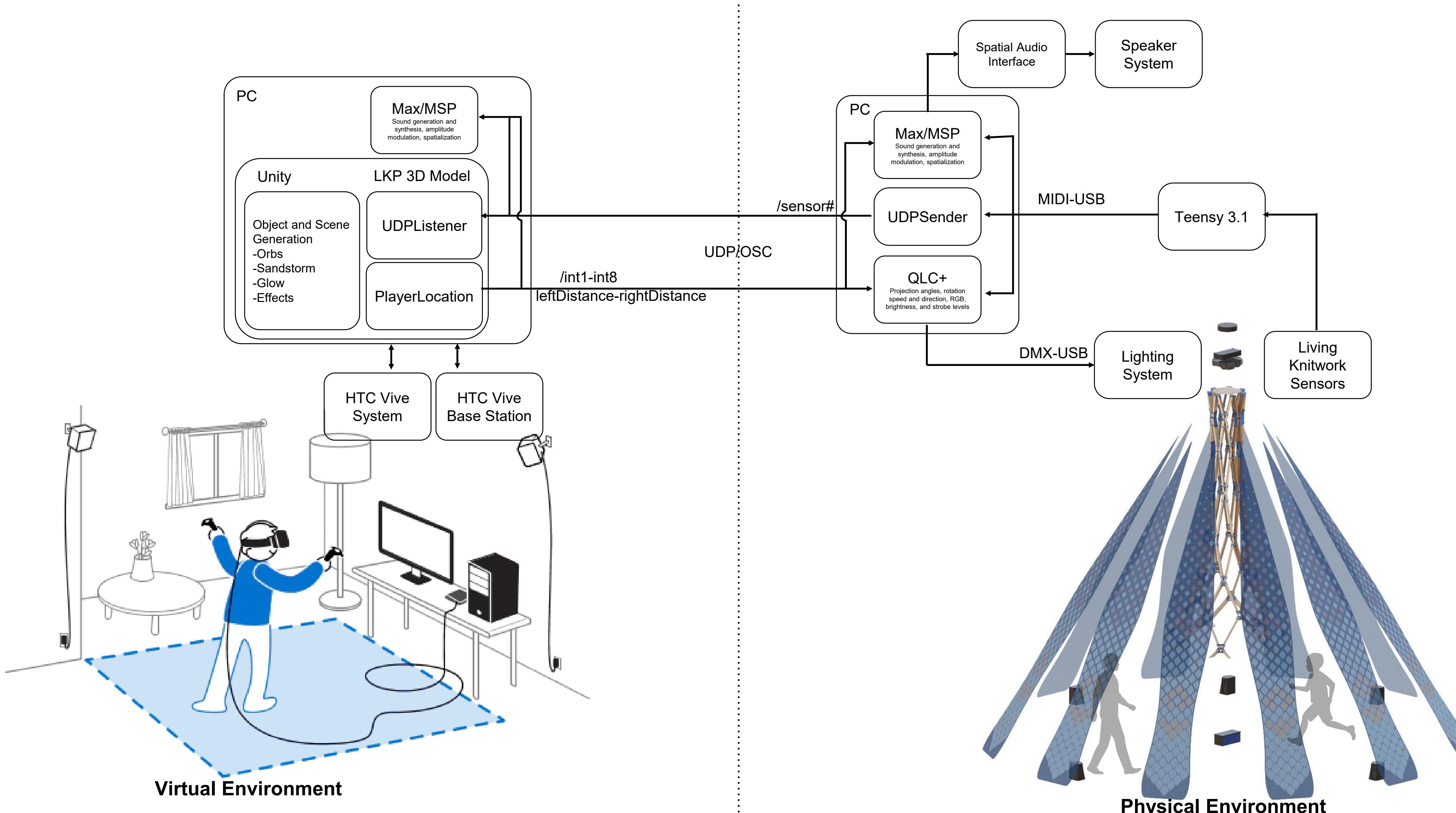
Choreographer: Treyden Chiavaralotti, Sound Mapping: Don Derek Haddad

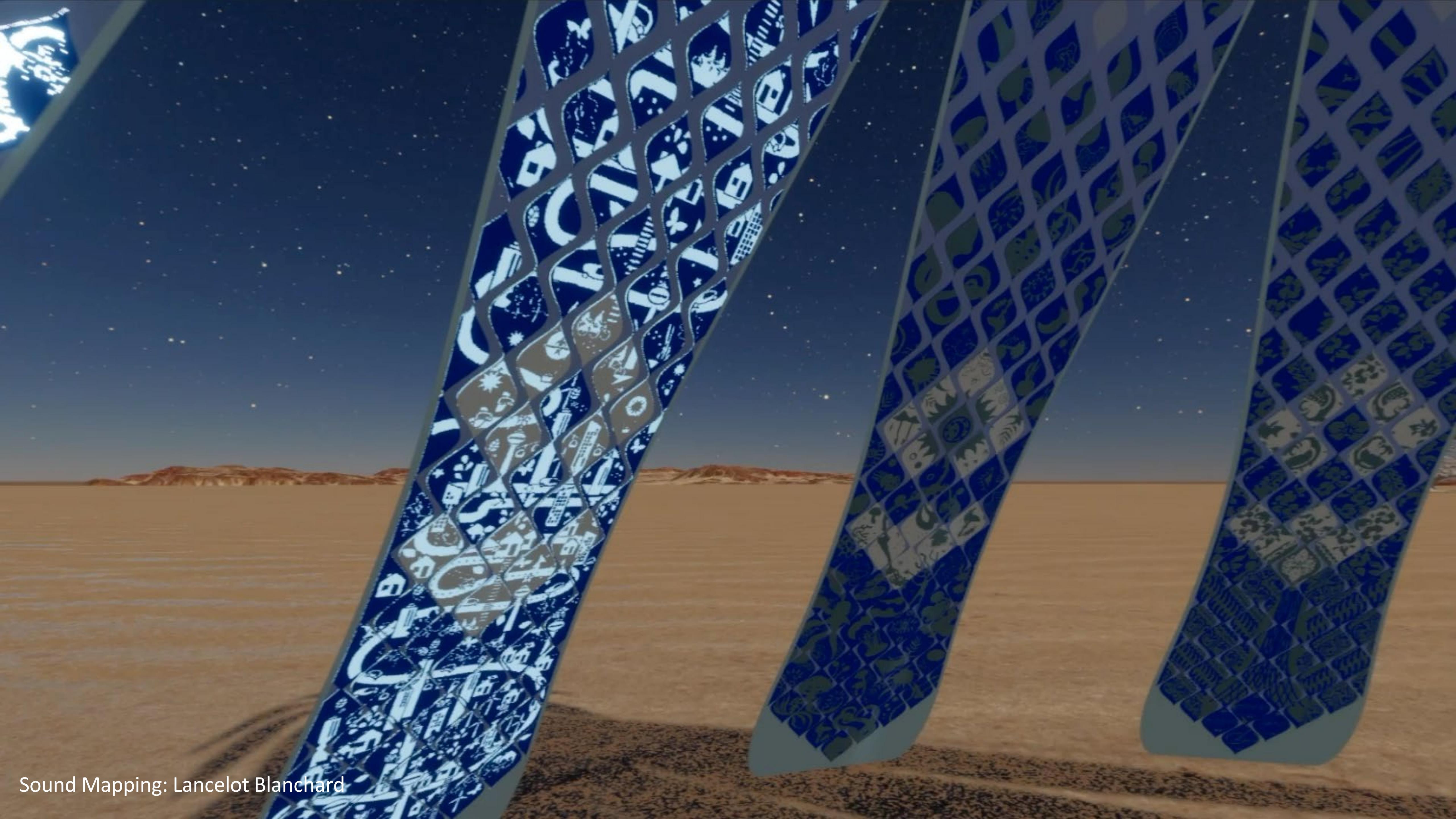


Choreographer: Treyden Chiavaralotti, Sound Mapping: Don Derek Haddad

KnitworkVR: A dual-reality telepresence experience

Connecting to the virtual and *vice versa*, driven by real-time sensor data and interaction





Sound Mapping: Lancelot Blanchard

EXIT



LIVING KNITWORK PAVILION

by Imanity Wicaksono and collaborators

Drawing inspiration from the artistry and craftsmanship of Indonesian batik textiles, theatrical perspective of Wayang Kulit, and the spirituality of a mandala, we present a new perspective on architectural-electronic textiles by integrating functional fibers, digital fabrication, sensing systems, and immersive technologies, while incorporating intricate details and avenues for self-expression.

The Living Knitwork Pavilion is an art, research, and immersive installation in the form of a dodecagonal pyramid (10 ft tall and 20 ft wide). It consists of 12 modular petals, each featuring 90 textile reliefs inspired by temple carvings. The fusion of parametric and individually-designed modules integrates the Living Knitwork into a narrative arc that is reflecting both a past for the past and a vision of the future. These reliefs, full of orange and blue tones, portray 12 scenarios—from ecosystem cities and bio-machine interfaces to the deep ocean and space exploration.

We employed 3D knitting, a digital fabrication technique that creates intricate organic forms as design practices, including recycled polyesters, conductive tiles, conductive yarns, and bimetallic yarns. This entire process enables the building of large-scale custom e-textiles with minimal raw materials and waste. The Knitwork petals feature mesh and openings along light and wind to pass through, double-knit sensing tile patterns, melting yarns for thermotransfer, and microfibers for securing optics and electrical cabling.

The structure of the Pavilion bonds an asymmetric assembly of lumber elements optimized for both structural integrity during the day, the Pavilion becomes a translucent space at night, creating a soft structure, providing an intimate space for gathering, reflection, and meditation. As the sun rises, the petals begin to change color as they emerge through photochromism.

At night falls, the Pavilion illuminates and activates, seamlessly integrating with each other and picking up the center of transmission. The body disrupts the e-textile and lighting network, turns the Pavilion into a source of energy and interaction.

Our effort integrates a structure which gathers, human interaction makes harmonious architecture, technology, the physical and the digital together. In this exhibition, we can be enveloped in sight, and sound. —

The interdisciplinary group includes researchers in architecture, arts, design, engineering, and business. Advisor: Marcus Moller-Nordenskjold. Age: 18-25 years old.

This project is possible thanks to the Green Startup Mentorship Program, Marcus Moller-Nordenskjold, and the University College London.

Image captions (from top):

1-10 Architectural rendering of the Pavilion at the U.S. Embassy in London.

1-10 Living Knitwork Pavilion.

7-10 Facing white, full moon.

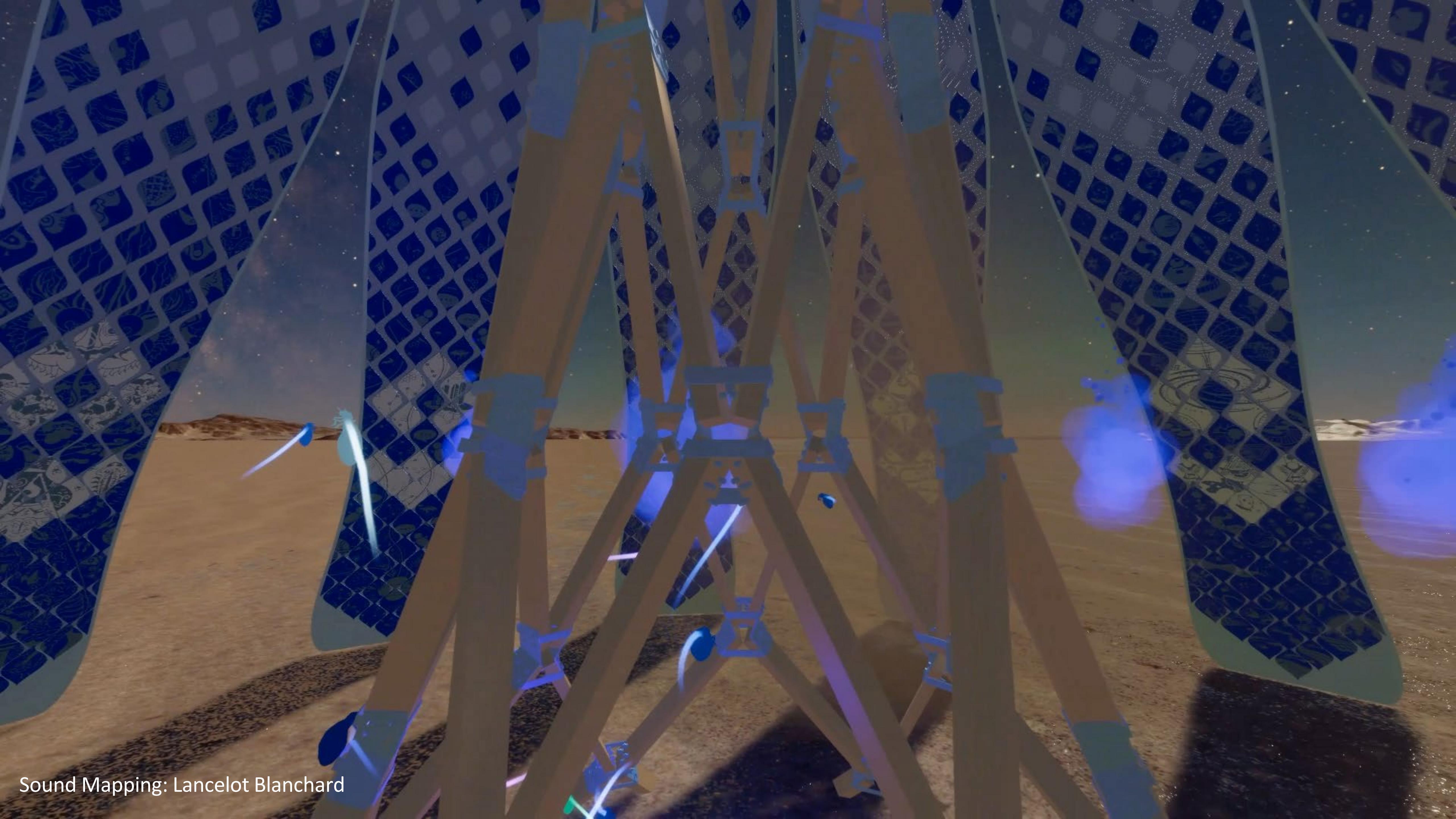
Bathing Moon demonstration.

11-12 The Living Knitwork pavilion at night, with the moon rising.

13-14 Pavilion at night, with the moon rising.



Sound Mapping: Lancelot Blanchard

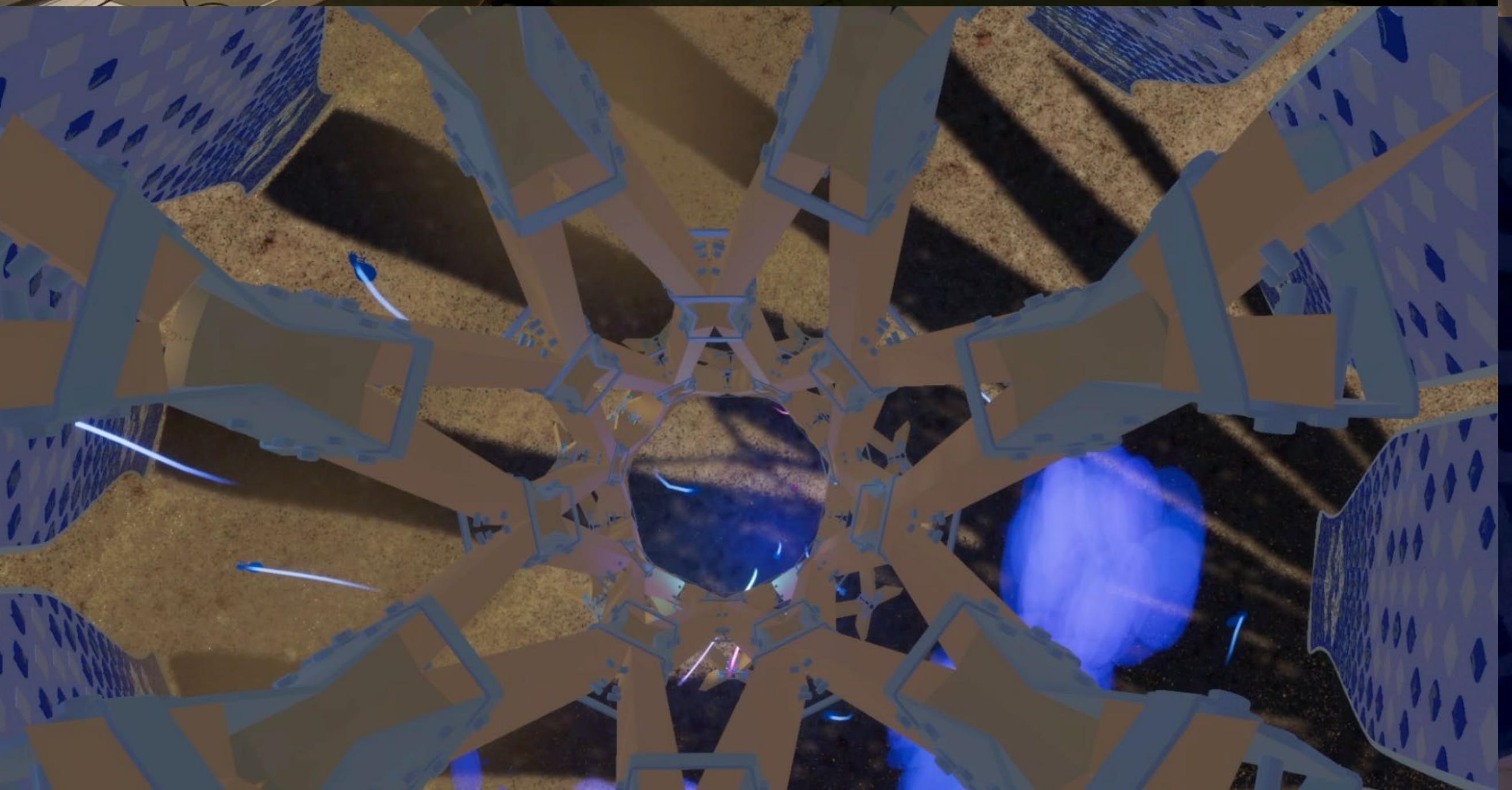
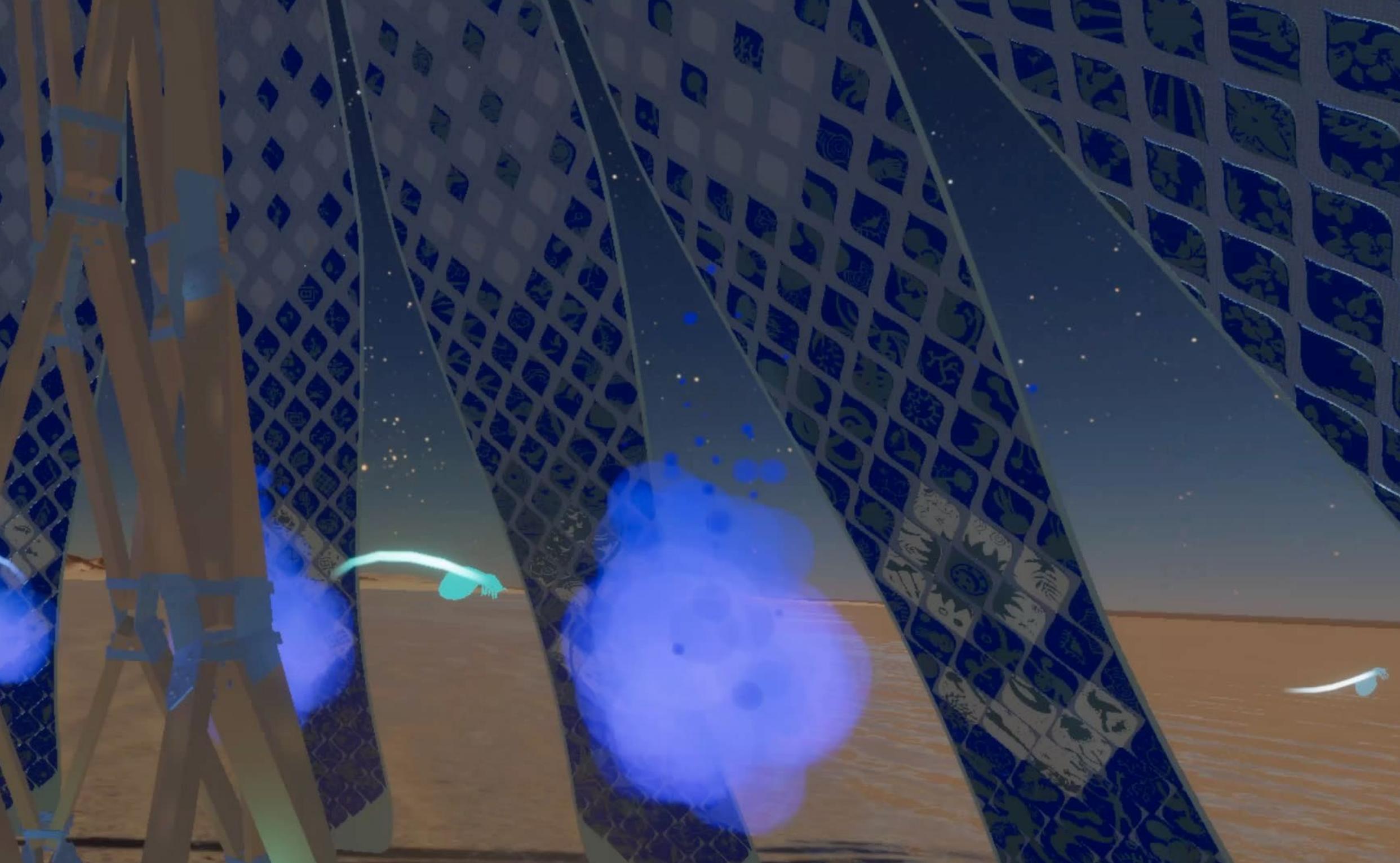


Sound Mapping: Lancelot Blanchard

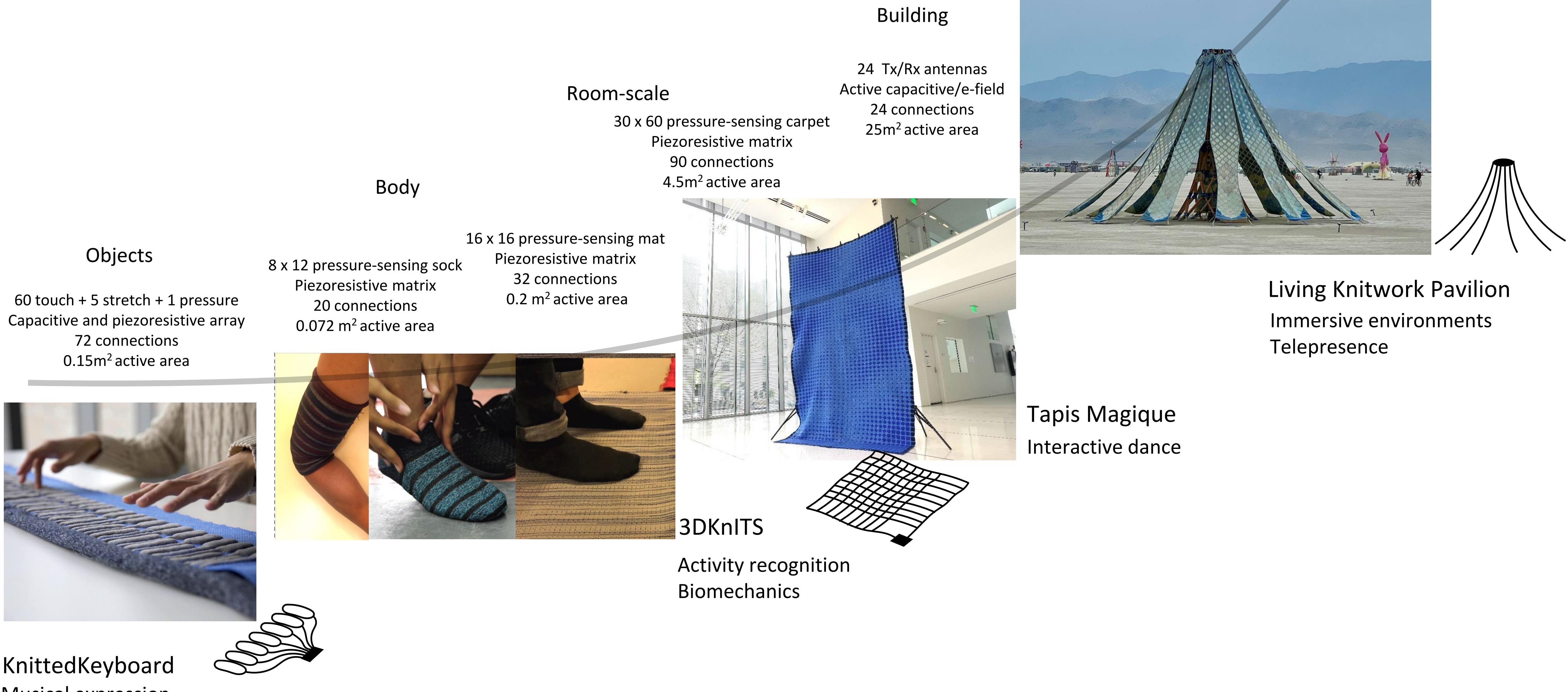
KnitworkVR



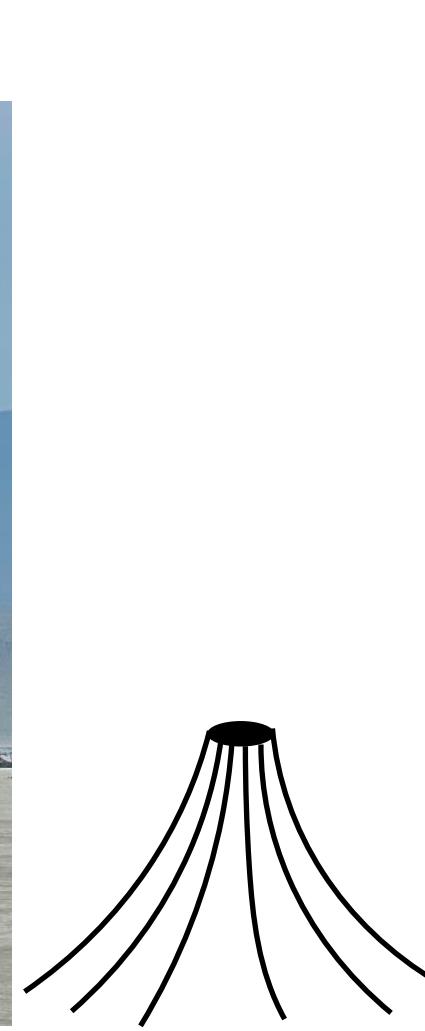
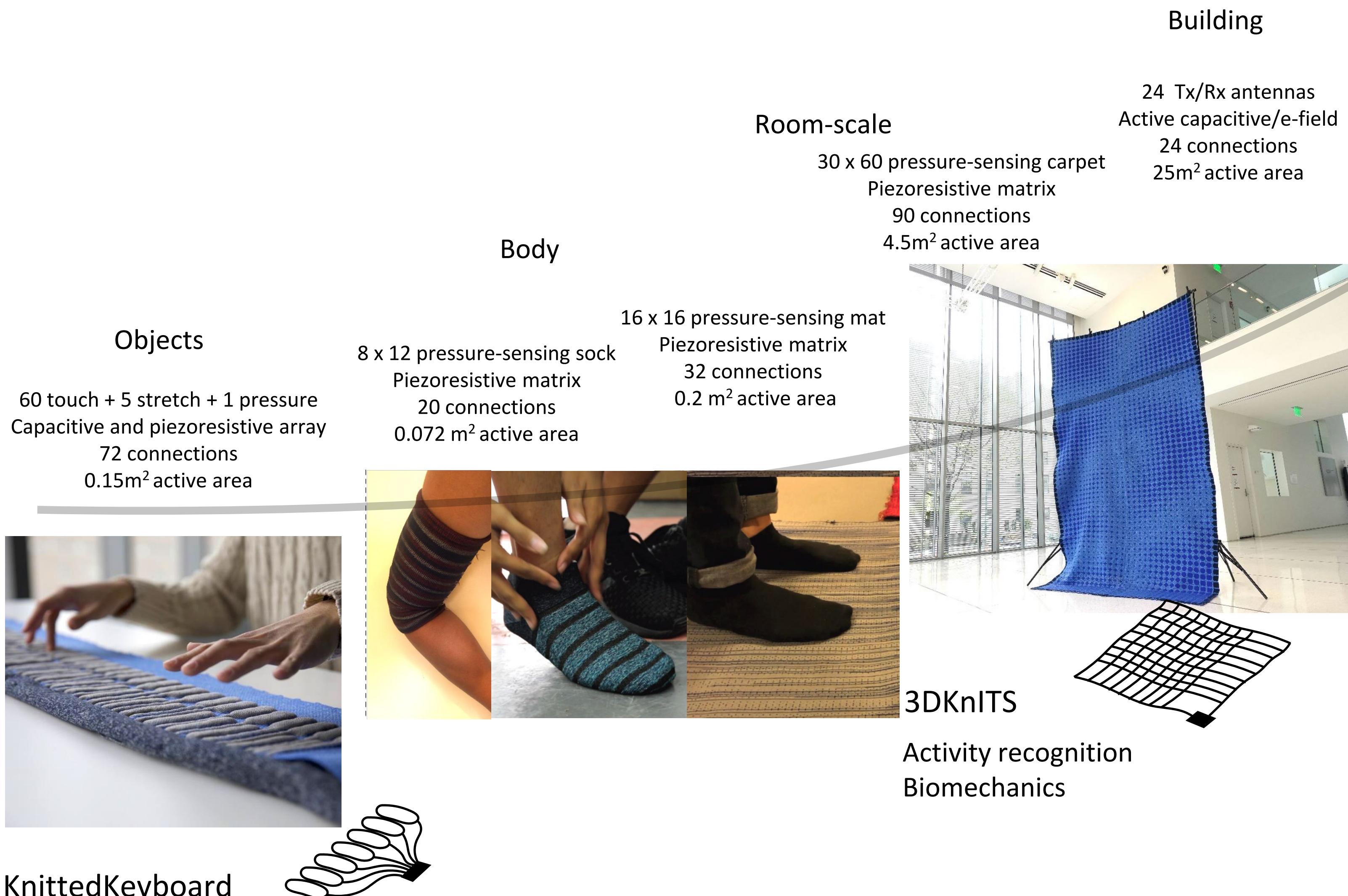
Cristian Colon



Architecting sensate textiles across scales

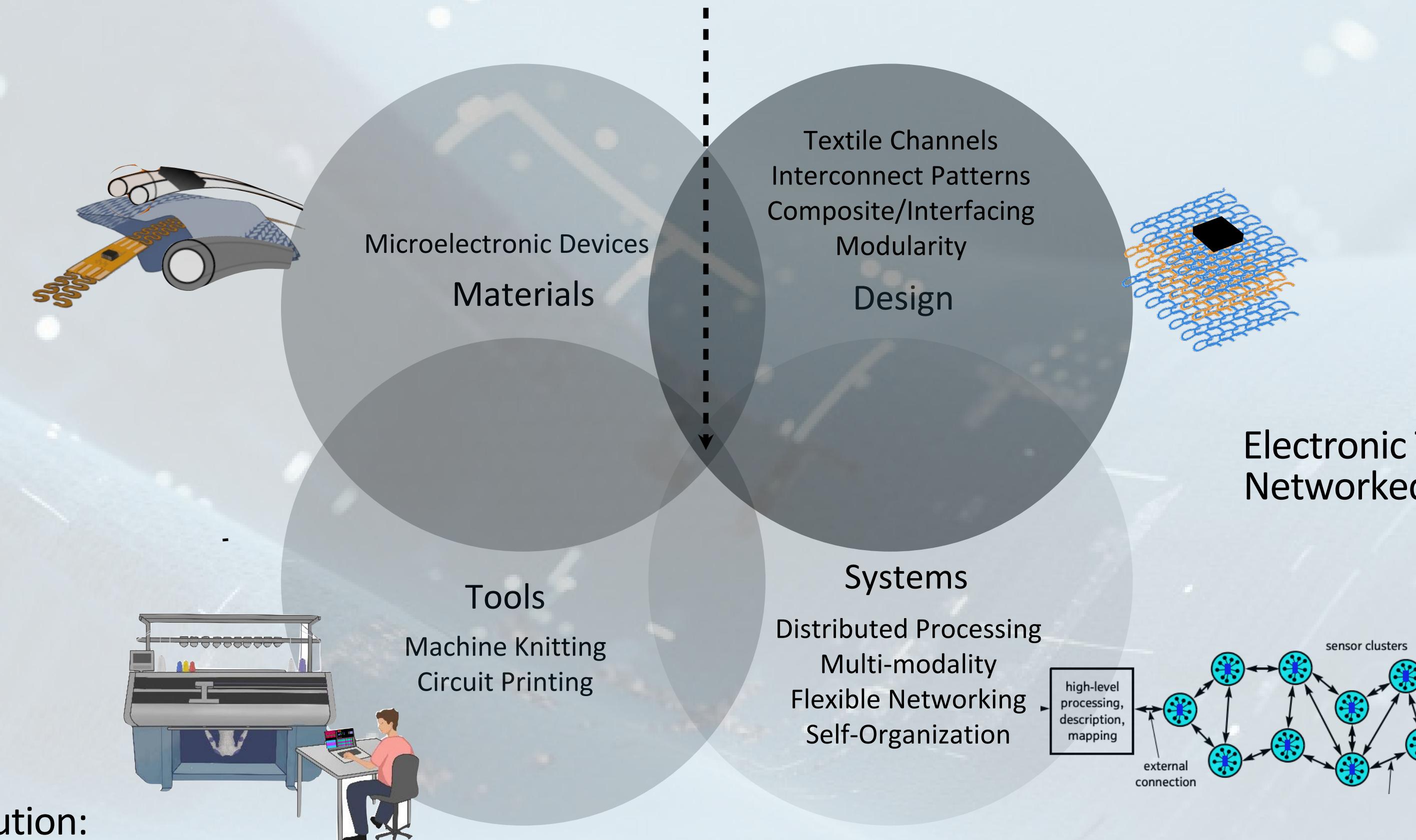


Architecting sensate textiles across scales



Computational Fabrics Framework

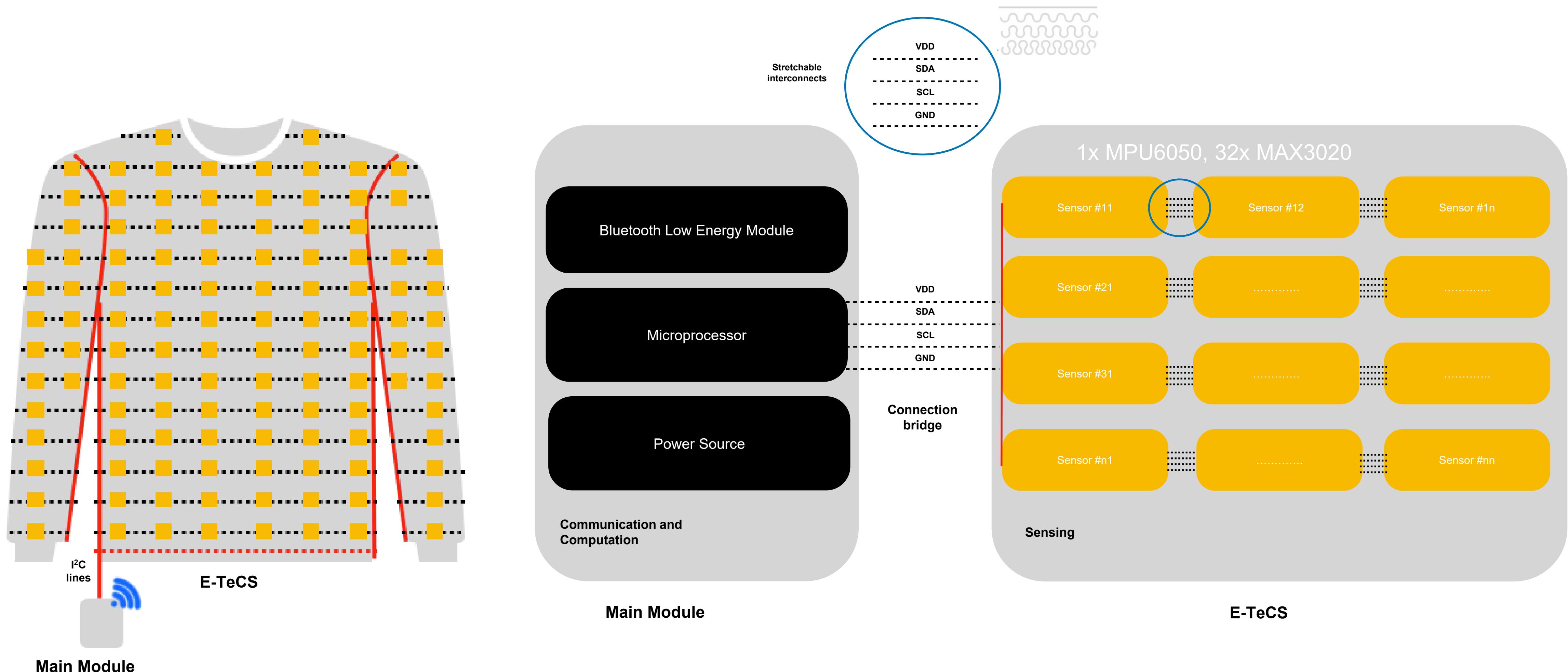
Distributed Computational Fabrics



Contribution:
 Design methodology and framework
 Project artifact across scales
 Hardware system development
 Application space

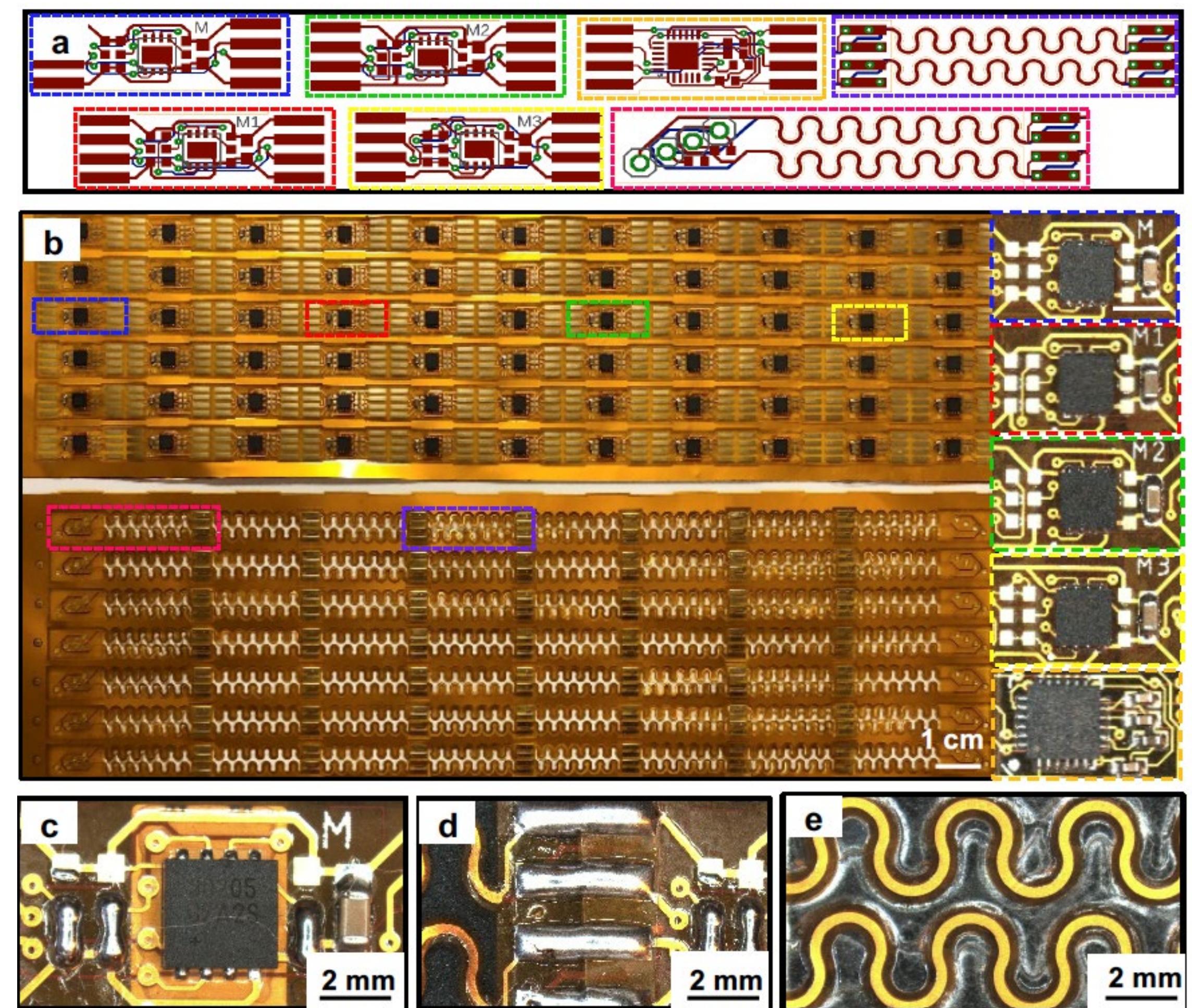
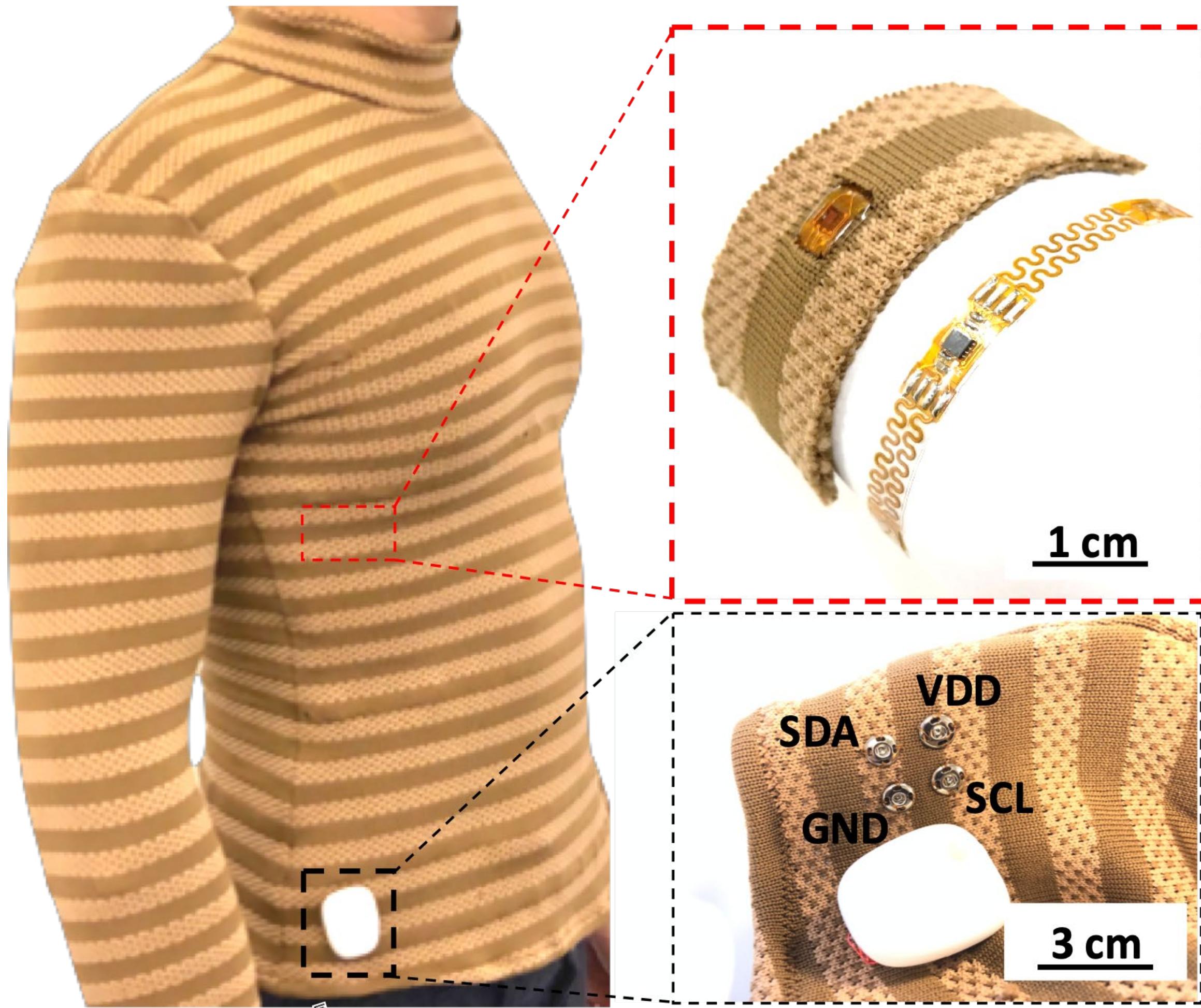
Projects:
 Electronic Textile Conformable Suit (E-TeCS)
 Networked Electronic Textile System (NETS)

E-TeCS: System Architecture

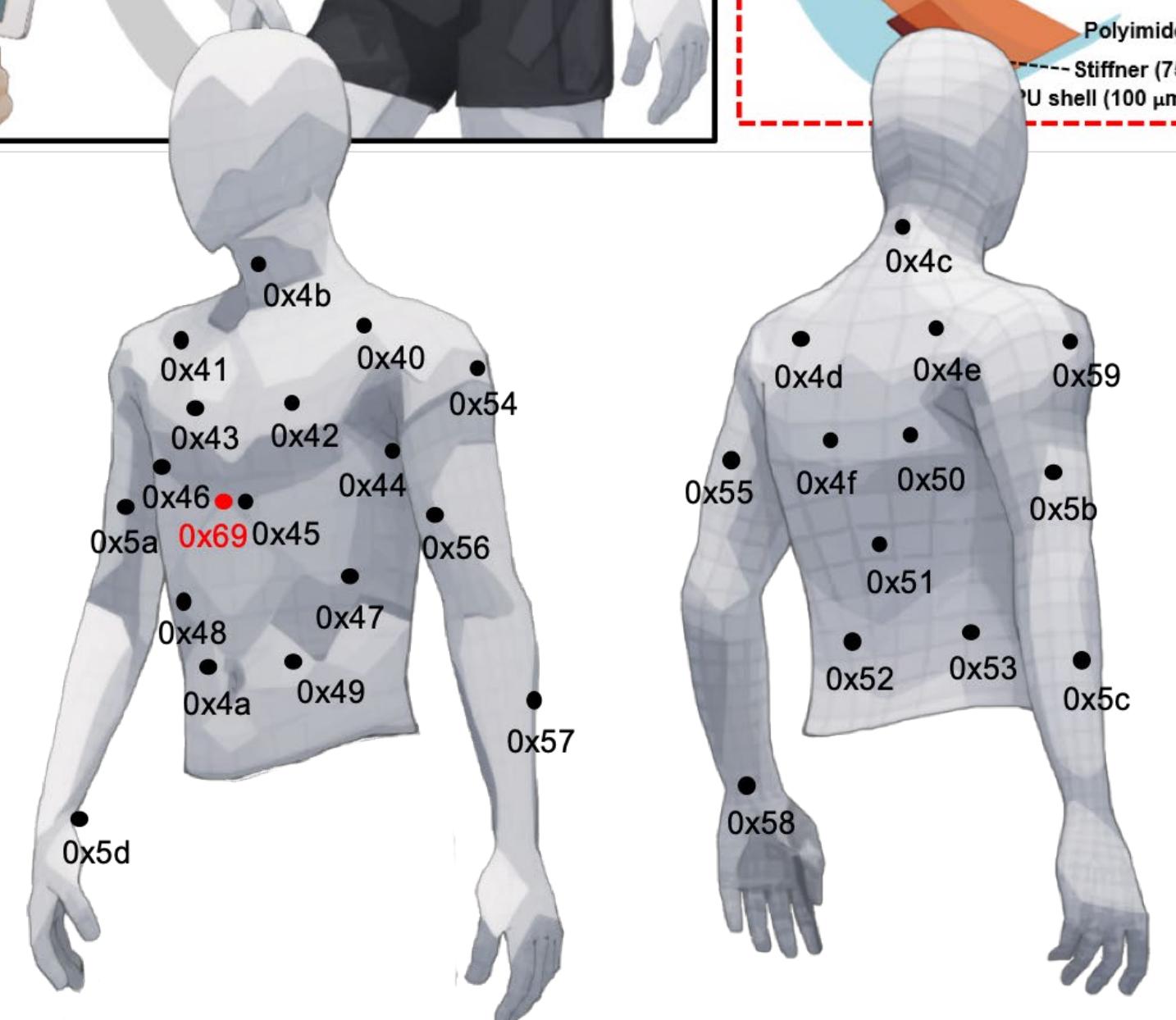
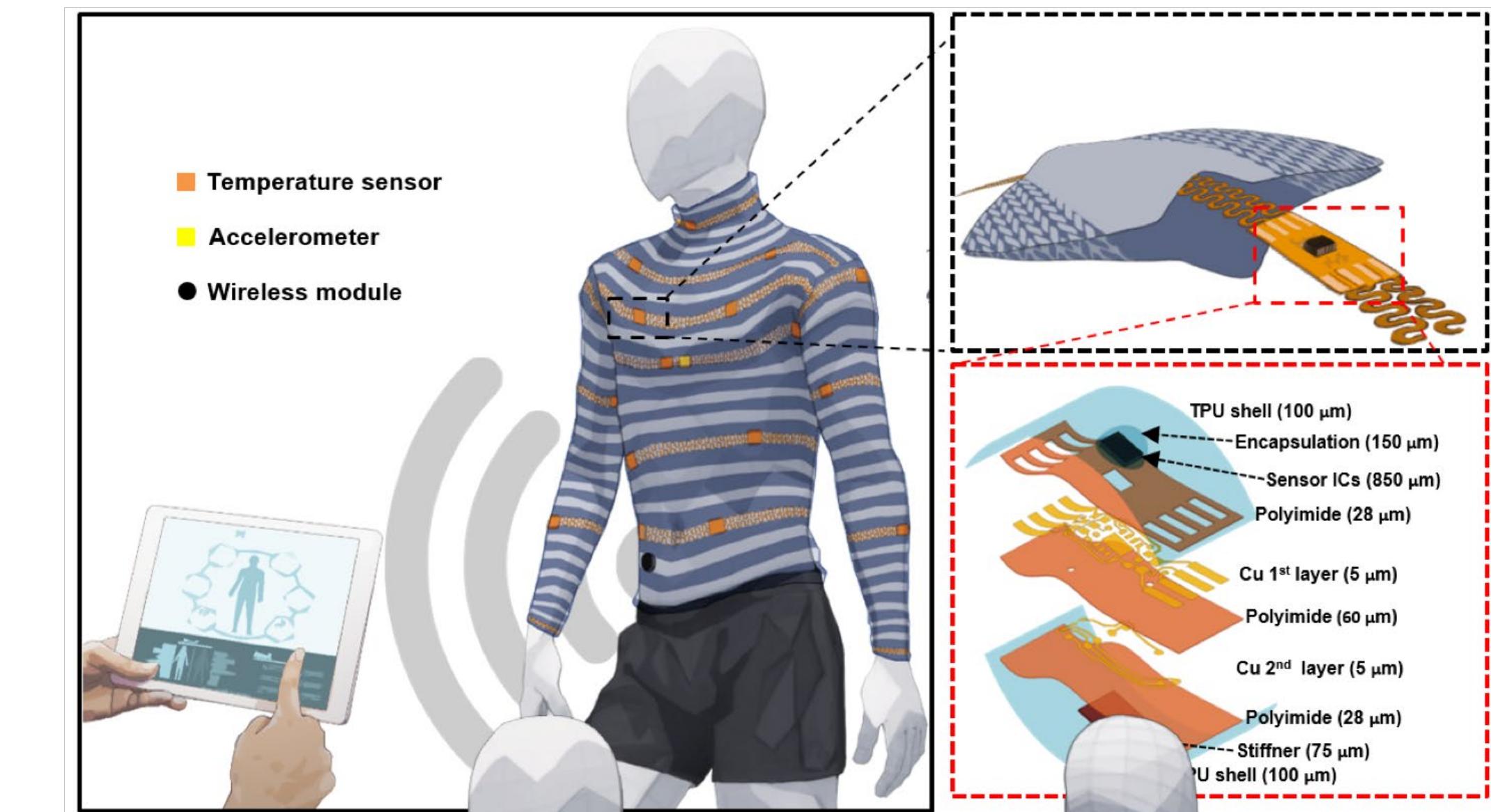


*Single spatiotemporal modality:
I²C Temperature Sensor is hard-wired to a maximum of 32 addresses*

E-TeCS: Electronic Textile Conformable Suit



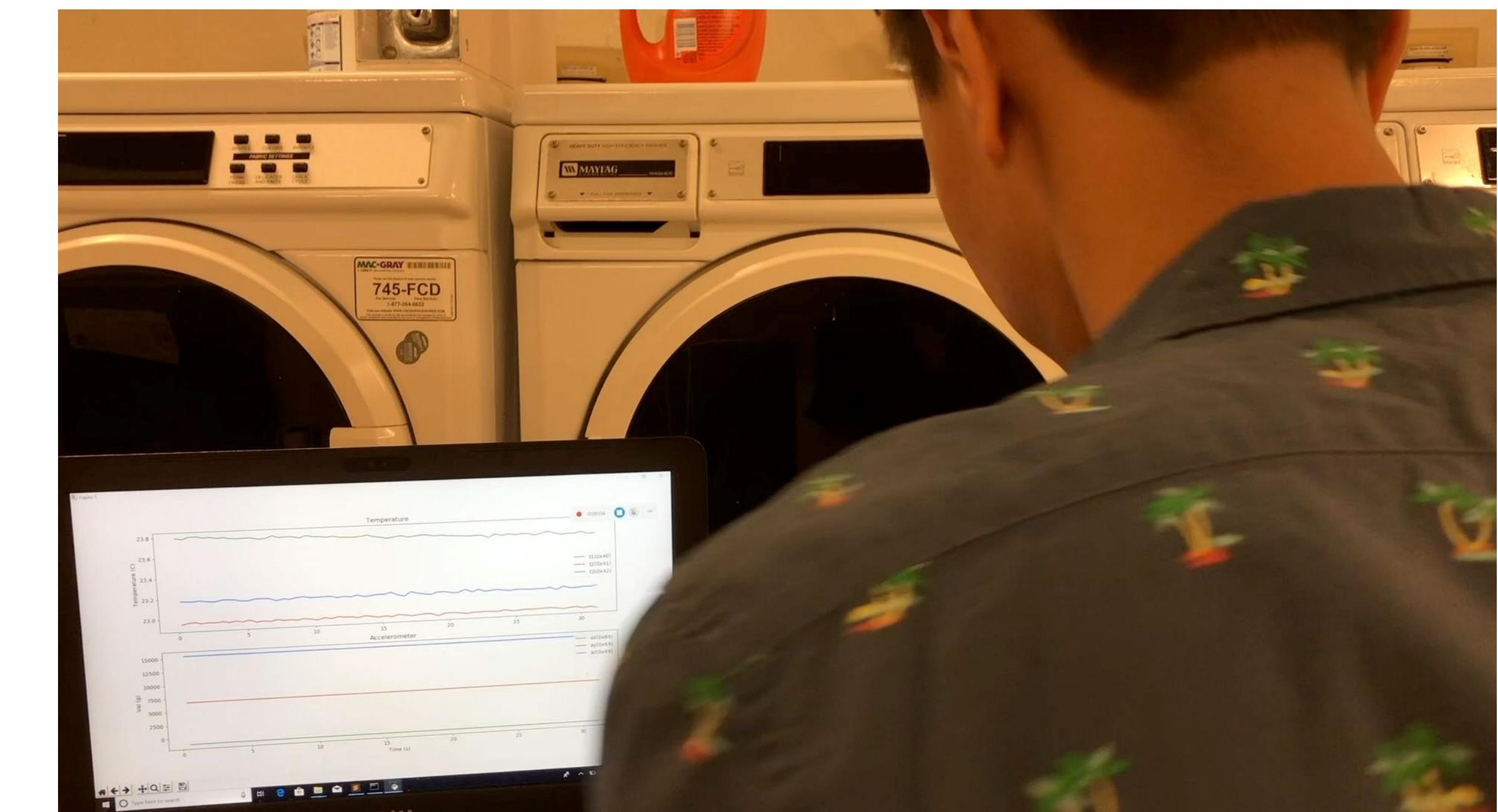
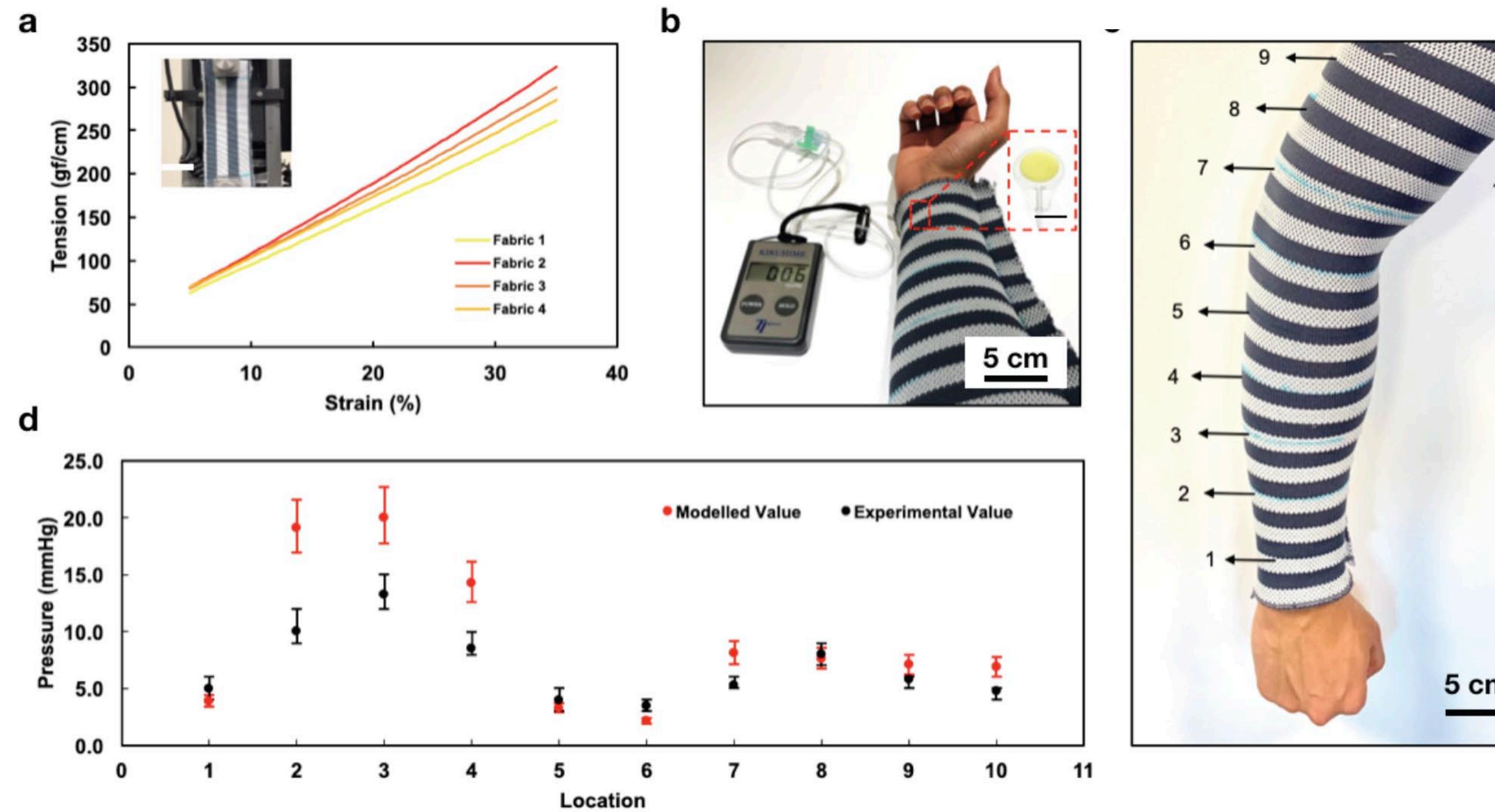
E-TeCS: Electronic Textile Conformable Suit



E-TeCS: Compression modelling and washability study

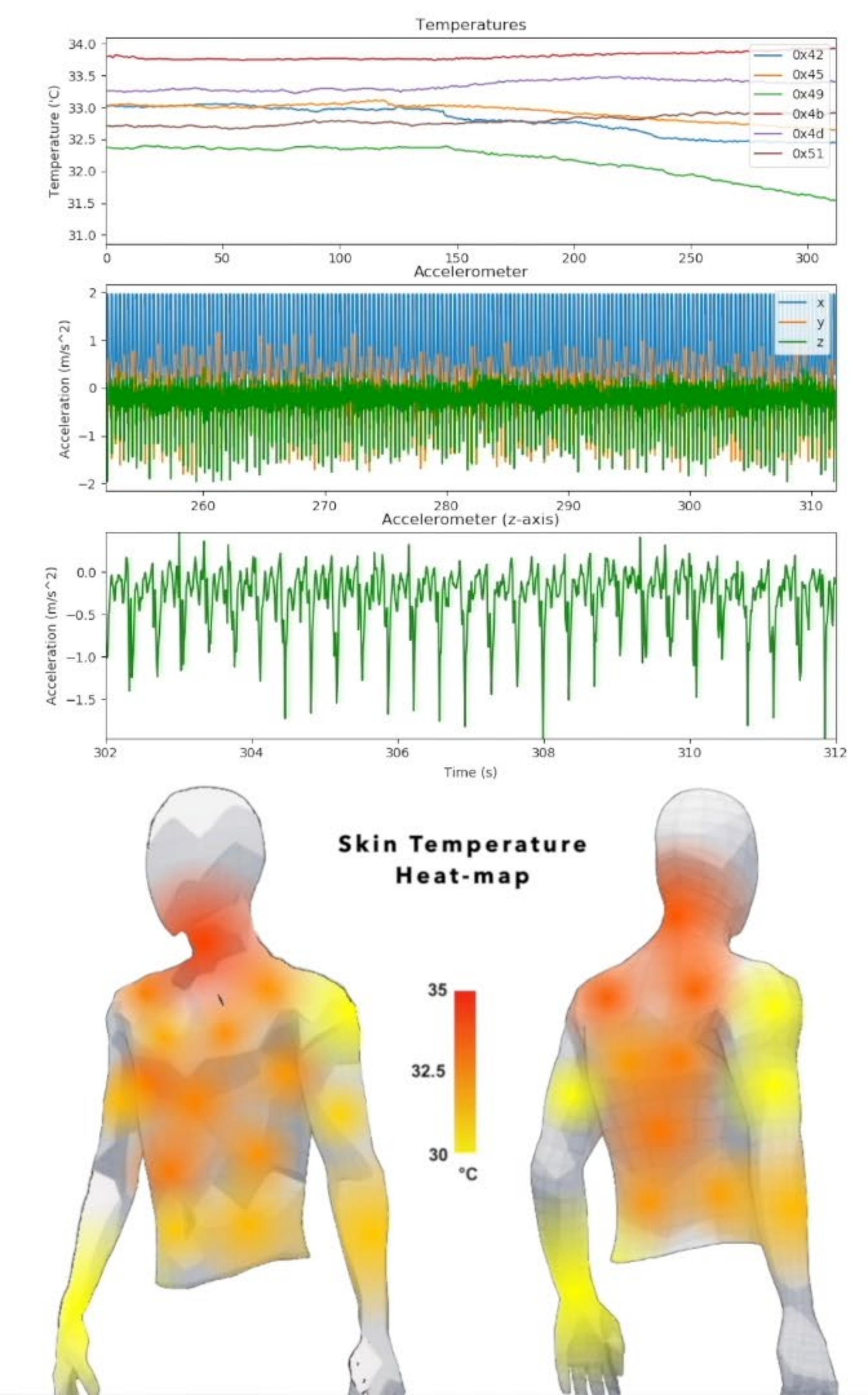
(Compression Pressure)

$$P = \frac{2\pi El(CF)}{C_{body}} \frac{Re}{1 - Re}$$





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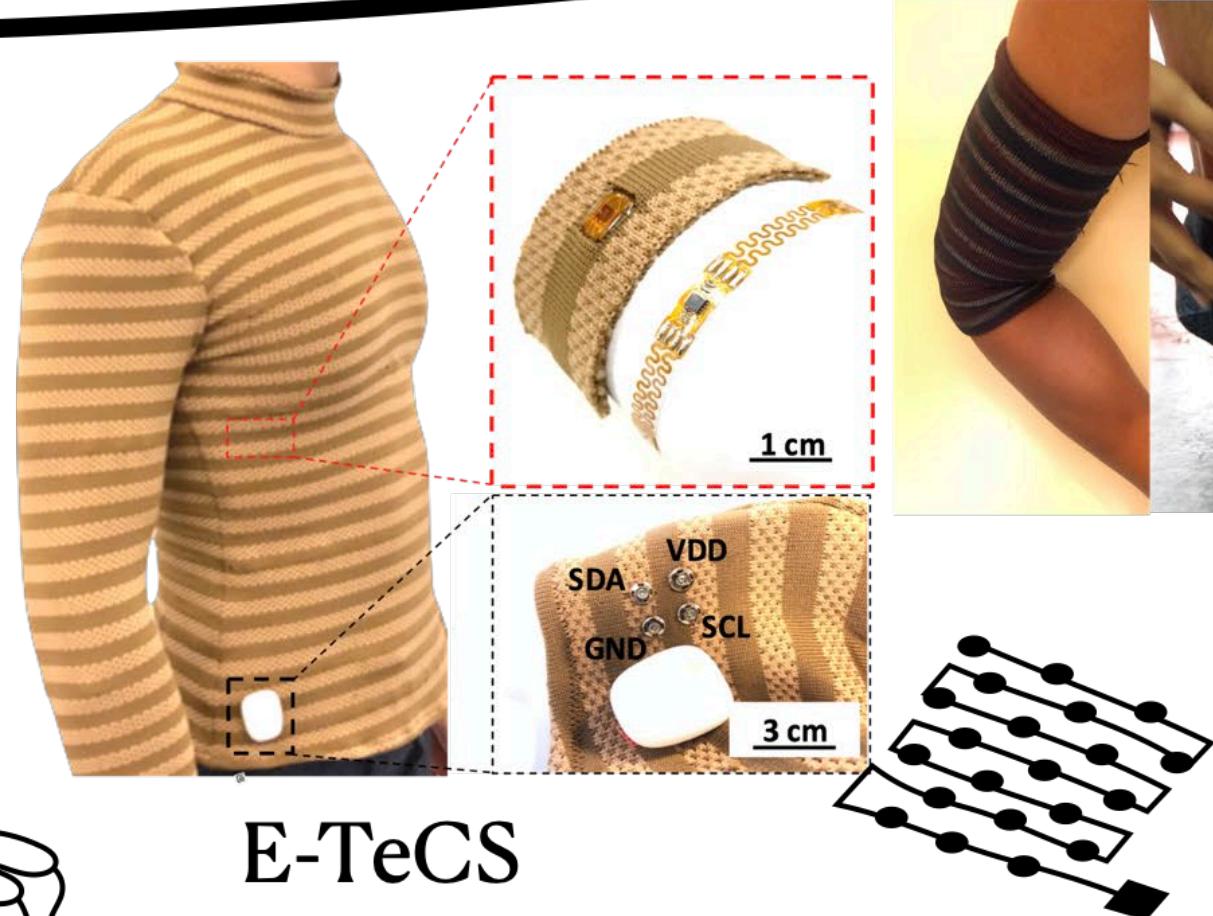
Architecting sensate fabrics across scales

Objects

60 touch + 5 stretch + 1 pressure
Capacitive and piezoresistive array
72 connections



31 temperature + 1 accelerometer
I₂C sensor nodes
4 connections



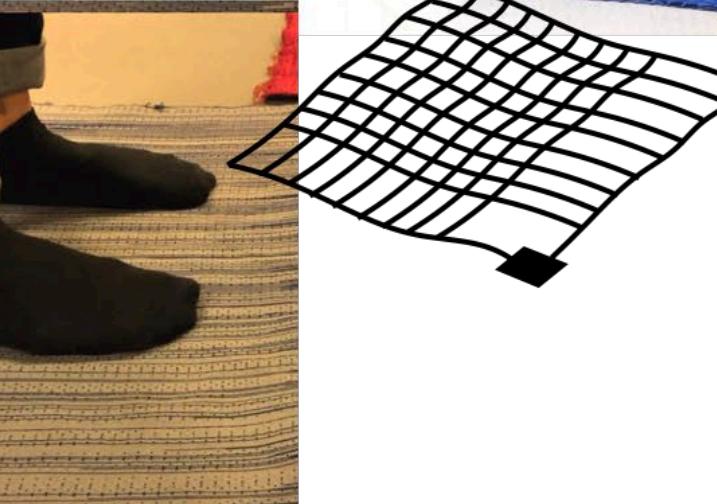
E-TeCS
Physiological sensing
Physical activity monitoring

KnittedKeyboard
Musical expression

Body

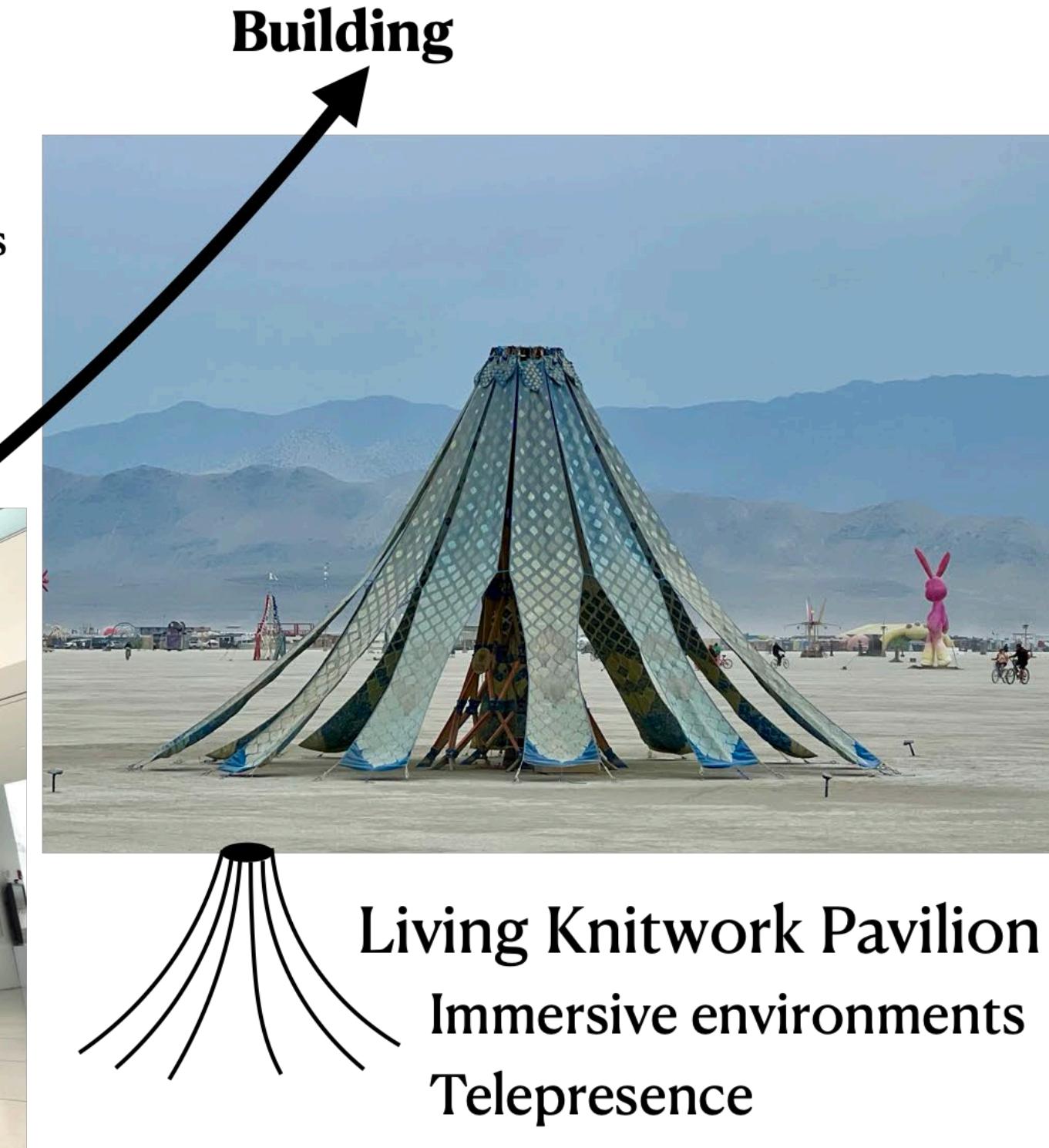
12 x 8 pressure-sensing pixels
Piezoresistive matrix
20 connections

Room-scale
30 x 60 pressure-sensing pixels
Piezoresistive matrix
90 connections



Tapis Magique
Interactive dance

3DKnITS
Activity recognition
Biomechanics



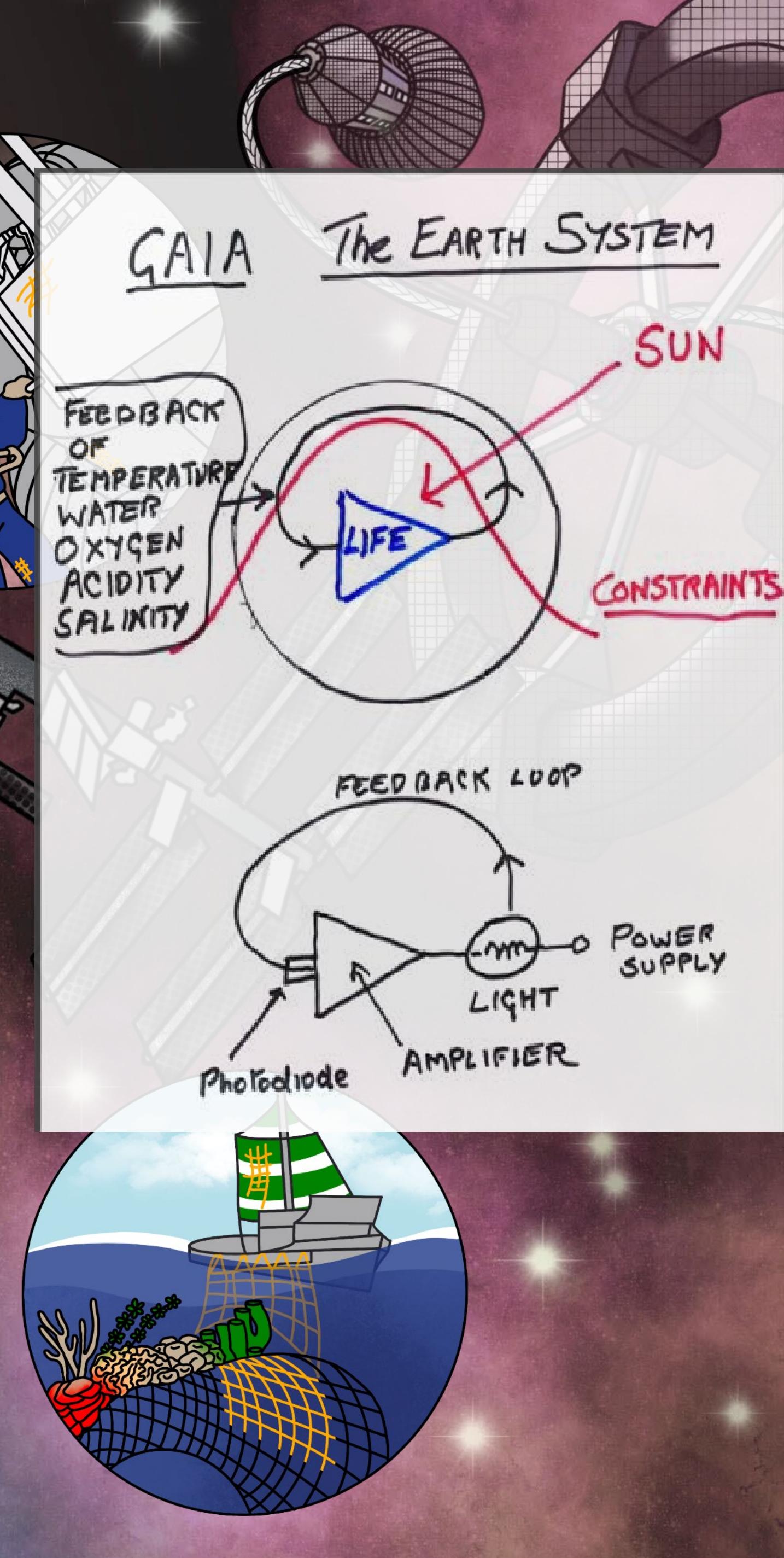
Toward Electronic Textile Gaia

Wicaksono, Cherston, and Paradiso. *IEEE Pervasive Computing*, 2021.



Toward Electronic Textile Gaia

Wicaksono, Cherston, and Paradiso. *IEEE Pervasive Computing*, 2021.

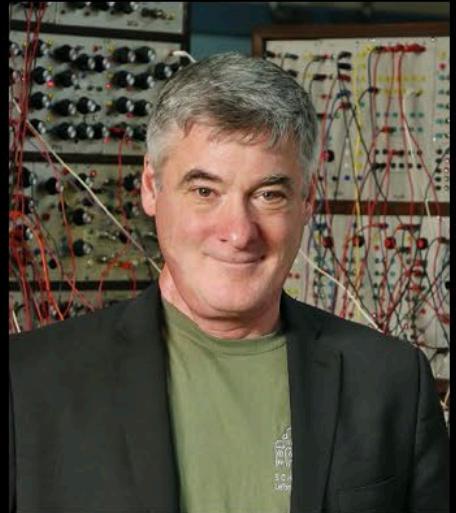




Krebs Cycle of Creativity III
Neri Oxman (2020)

Thanks a ton!

PhD Committee



Dr. Joseph A. Paradiso
Responsive Environments



Dr. Alexander Stolyarov
AFFOA



Dr. Svetlana Boriskina
MIT MechE



Dr. Kris Pister
UC Berkeley

SM Committee



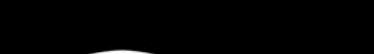
Dr. Canan Dagdeviren
Conformable Decoders



Dr. Hiroshi Ishii
Tangible Media



Dr. Rosalind Picard
Affective Computing



Musician, Sound Artists



Dr. Don Derek Haddad
Responsive Environments



Mike Jiang
Viral Communications



Jordan Rudess
Dream Theater



Lancelot Blanchard
Responsive Environments



Manaswi Mishra
Opera of the Future

Engineers, Scientists, Designers



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Media Lab, MIT+Harvard HST



Dr. Artem Dementyev
Google Deepmind



Fangzheng Liu
Responsive Environments



Gabriela Advincula
City Science



Dr. Tao Sun
Virginia Tech

Choreographer, Dancers



Loni Landon
Dance Company



Nina Gentile



Pichet Klunchun
Dance Company



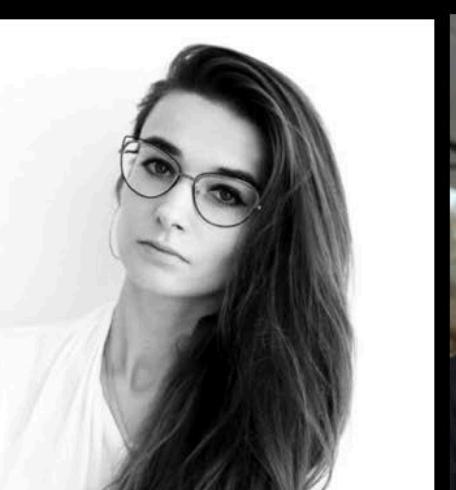
Treyden Chiaravallotti
Harvard GSD



Ali Shtarbanov
Responsive Environments



Dr. Juliana Cherston
Harvard Cfa



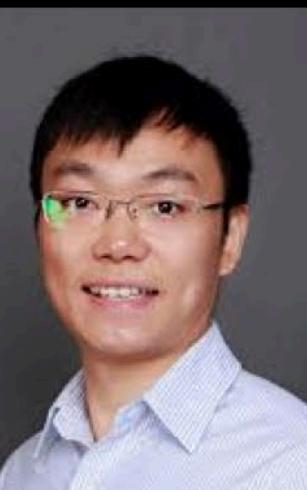
Judy Cichoka
FabLab Poland



Sam Chin
Responsive Environments



Alfonso Parra Rubio
Center for Bits and Atoms



Dr. Wei Yan
Donghua University

+ many others (UROPs, Media Lab, MIT SA+P, Phage, BM Community)



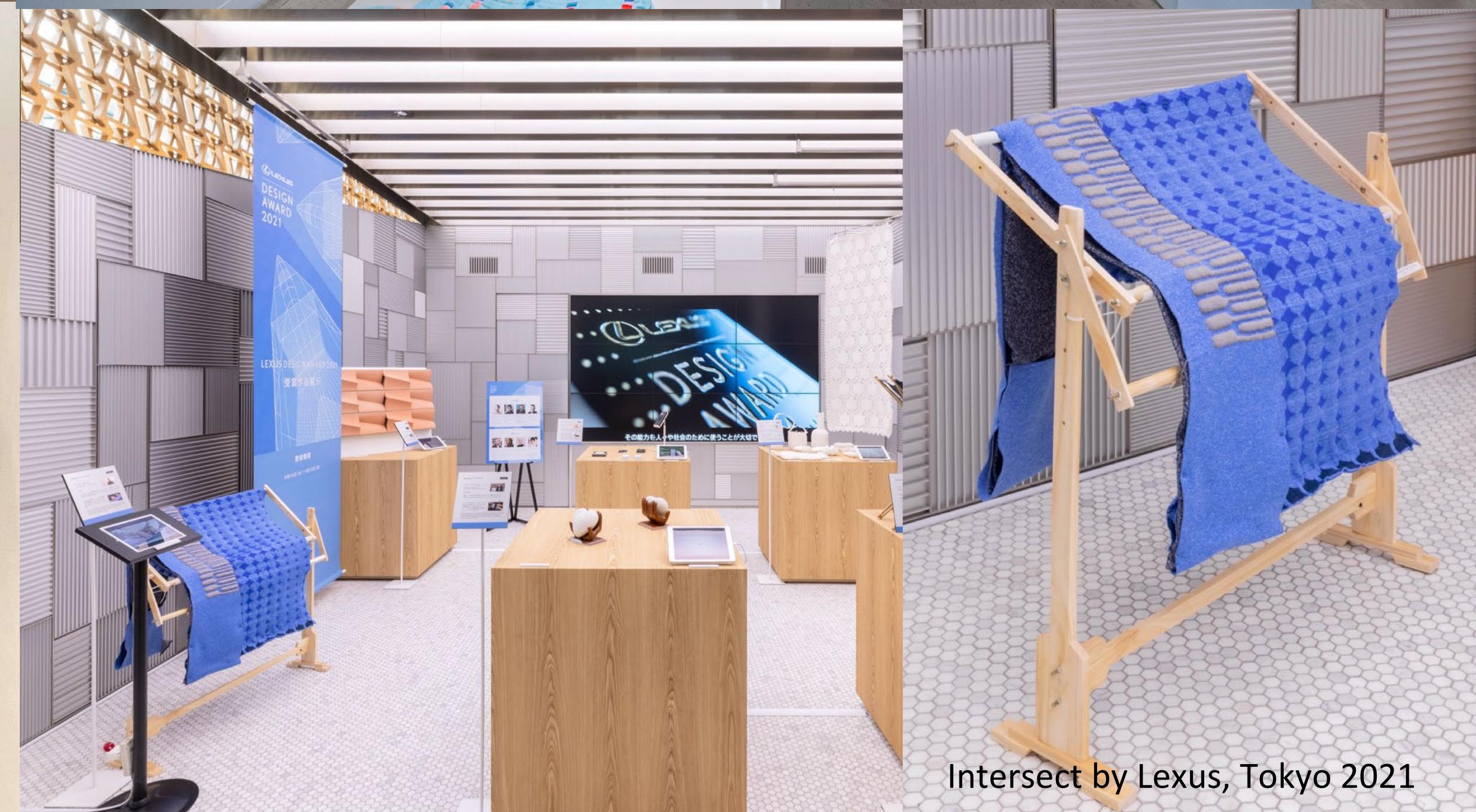
Indonesian Contemporary Arts and Design, Jakarta 2022



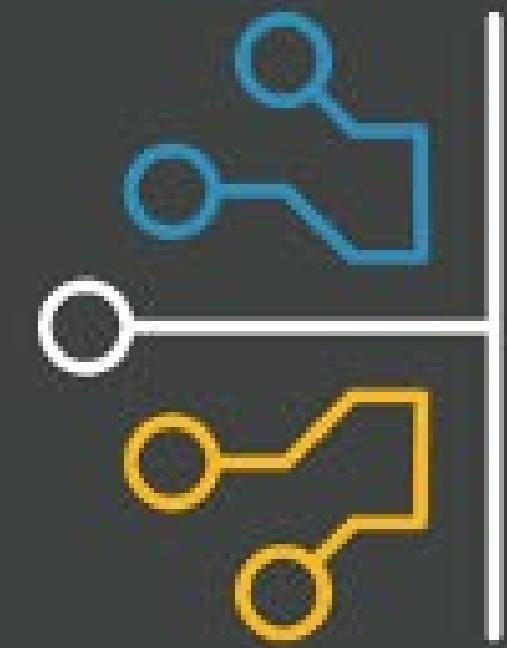
Ben Shahn Center for Visual Arts, New Jersey 2024



With Pichet Klunchun Dance Company, Bangkok 2022



Intersect by Lexus, Tokyo 2021



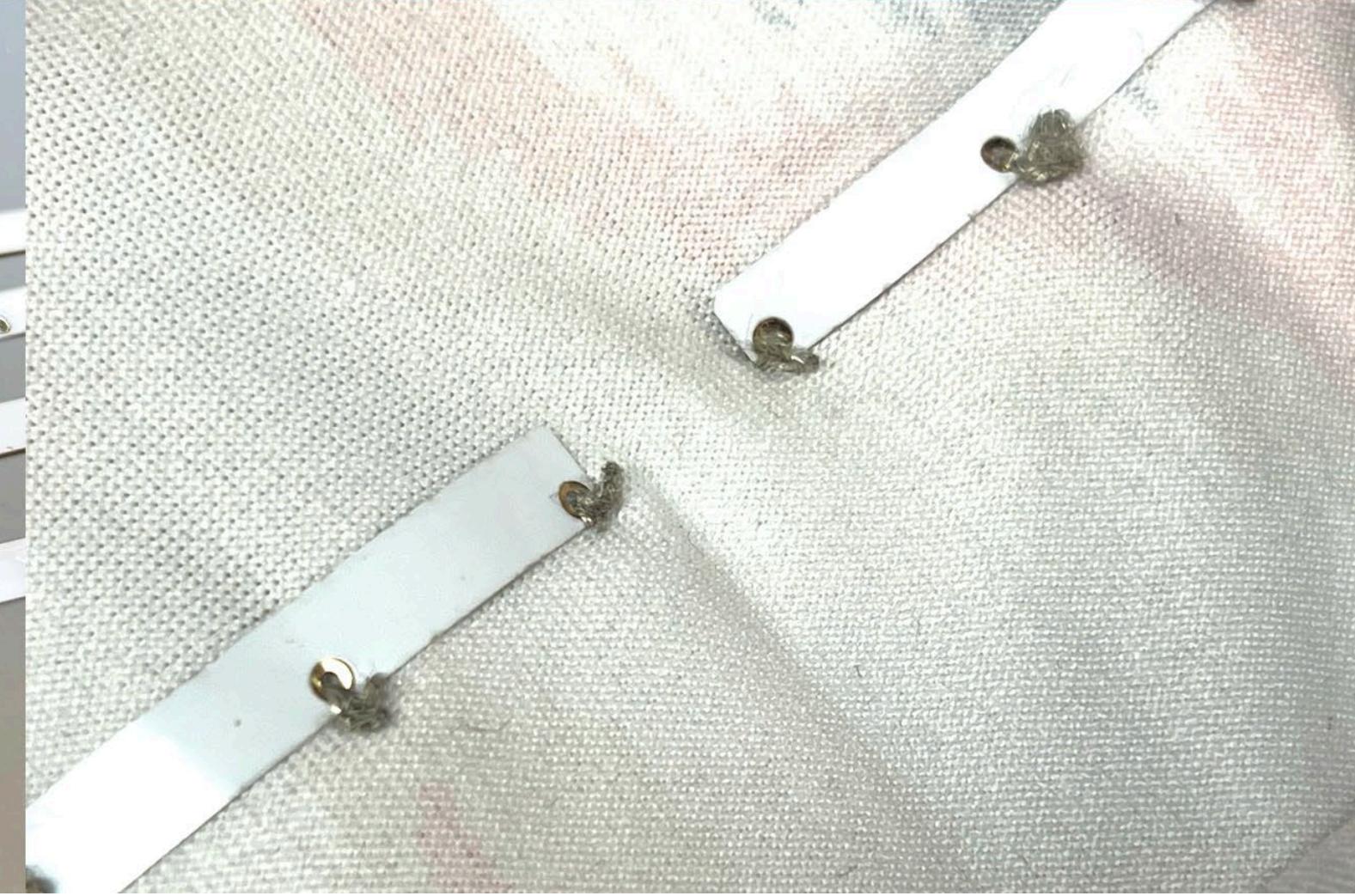
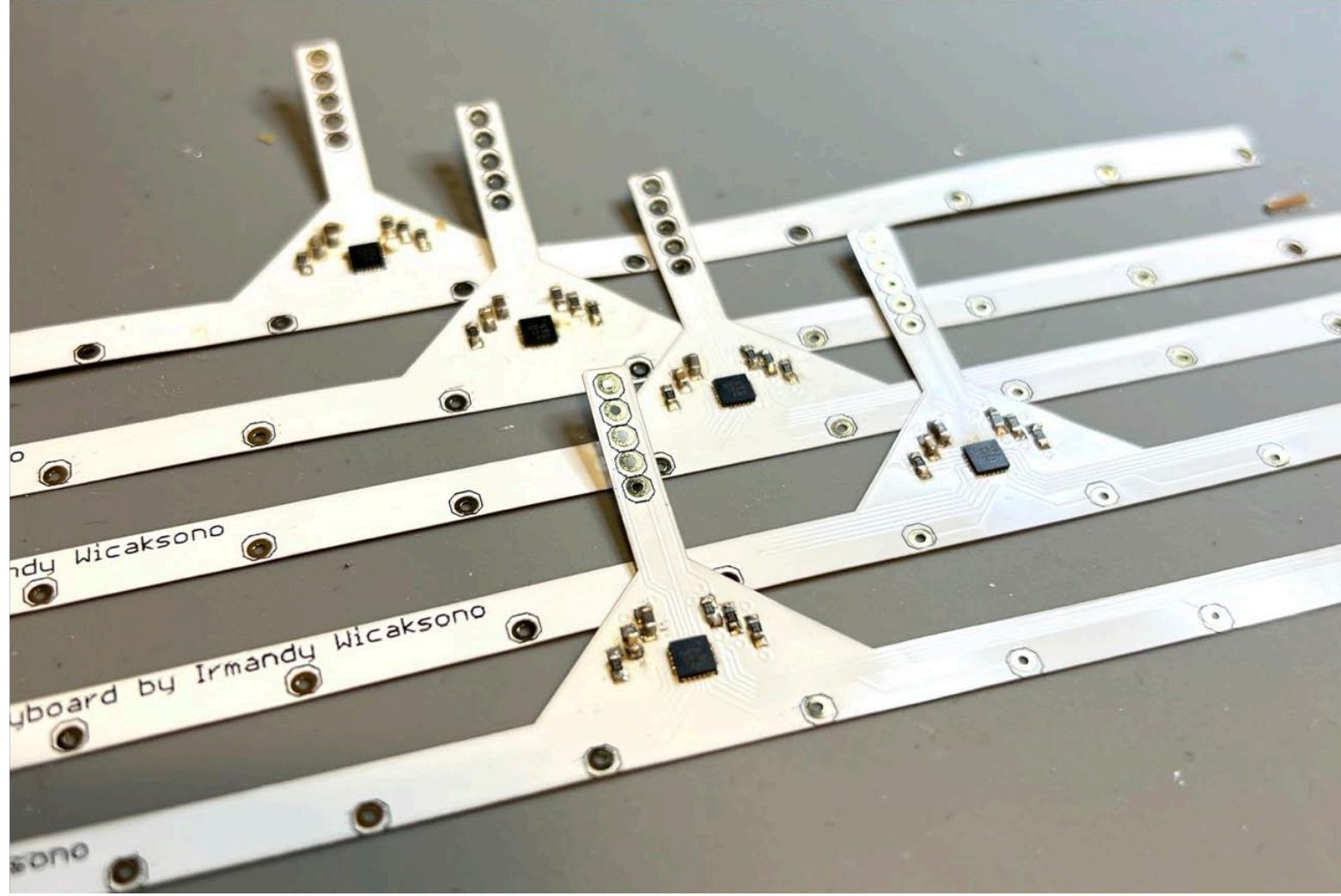
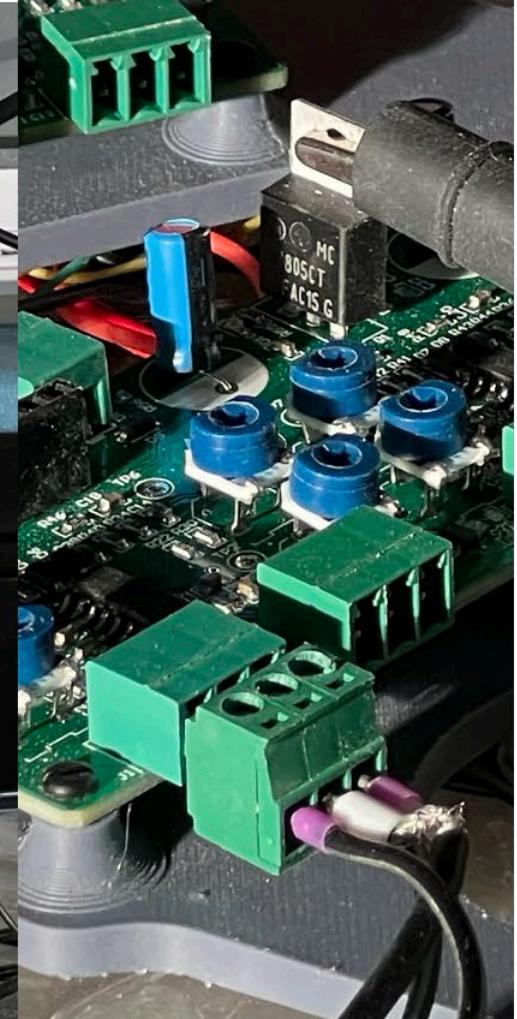
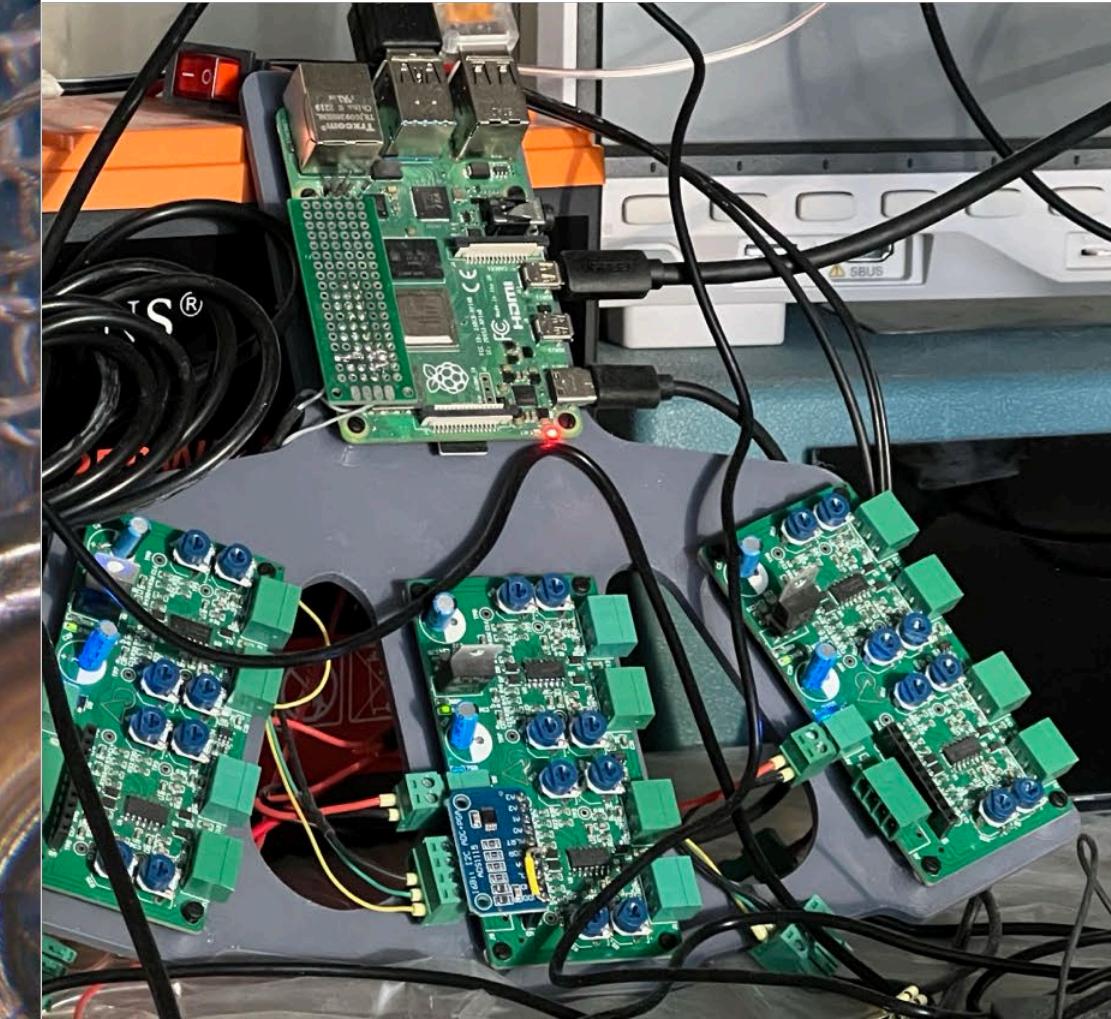
See you next year!

EMERGING TECHNOLOGIES

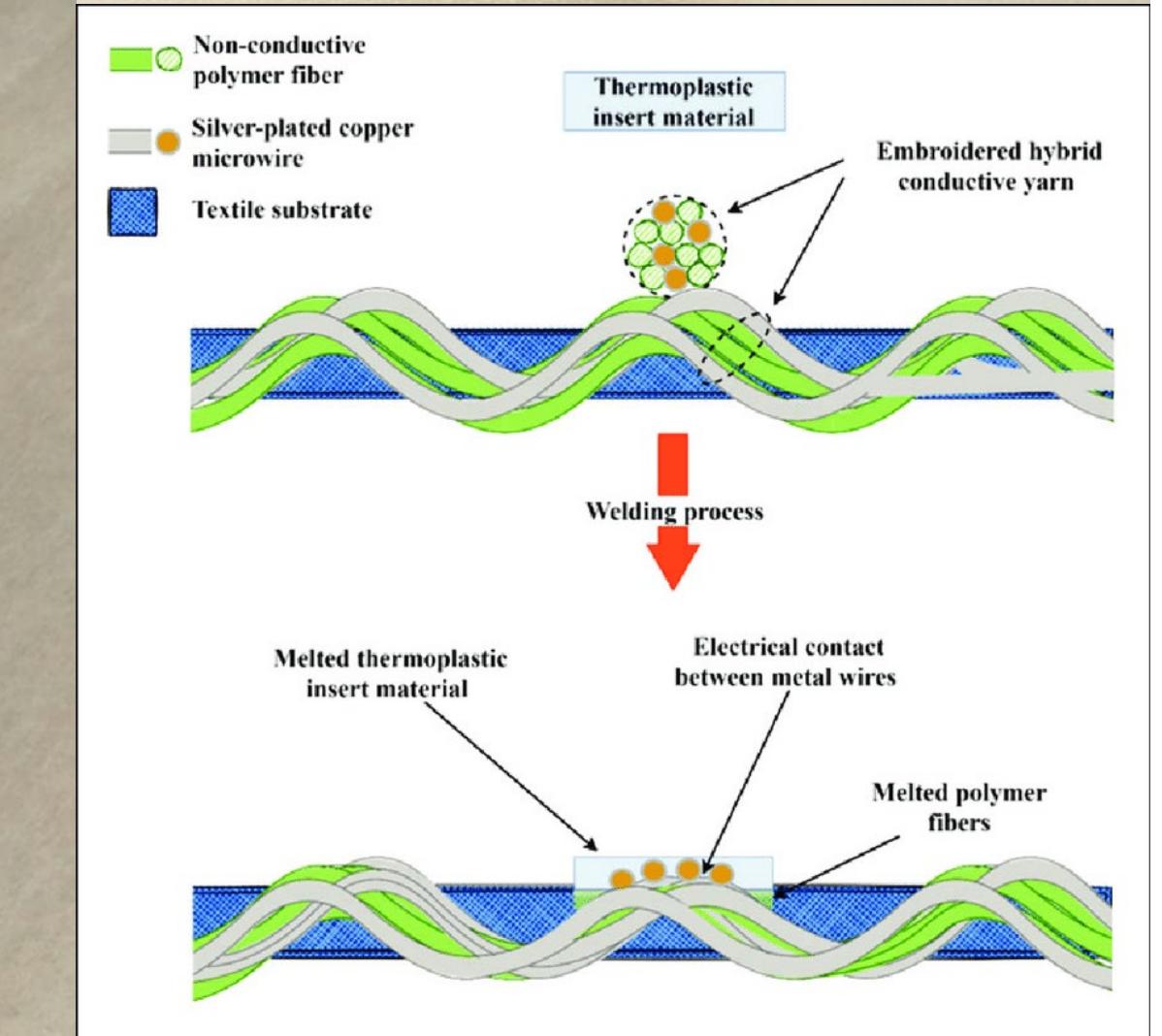
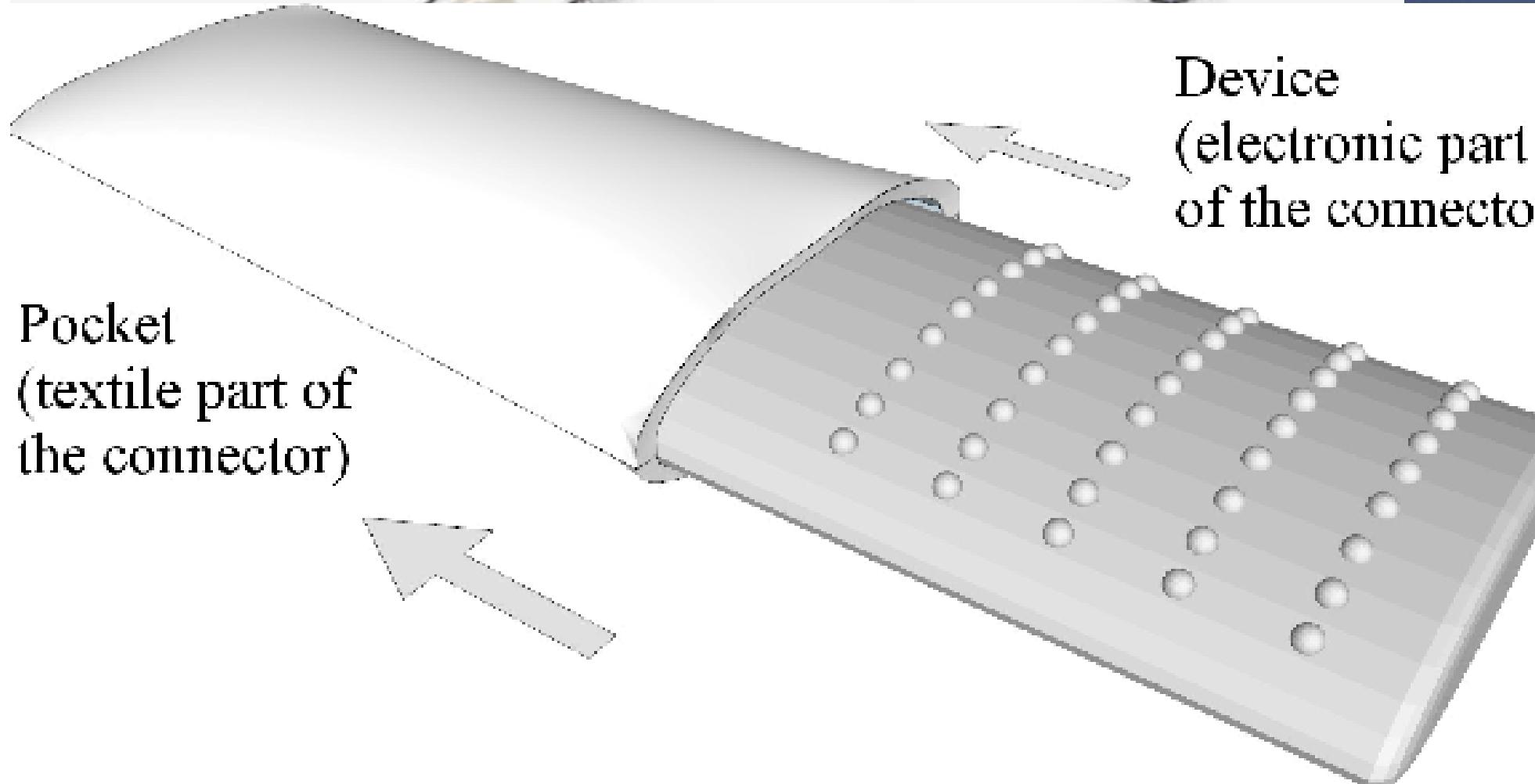
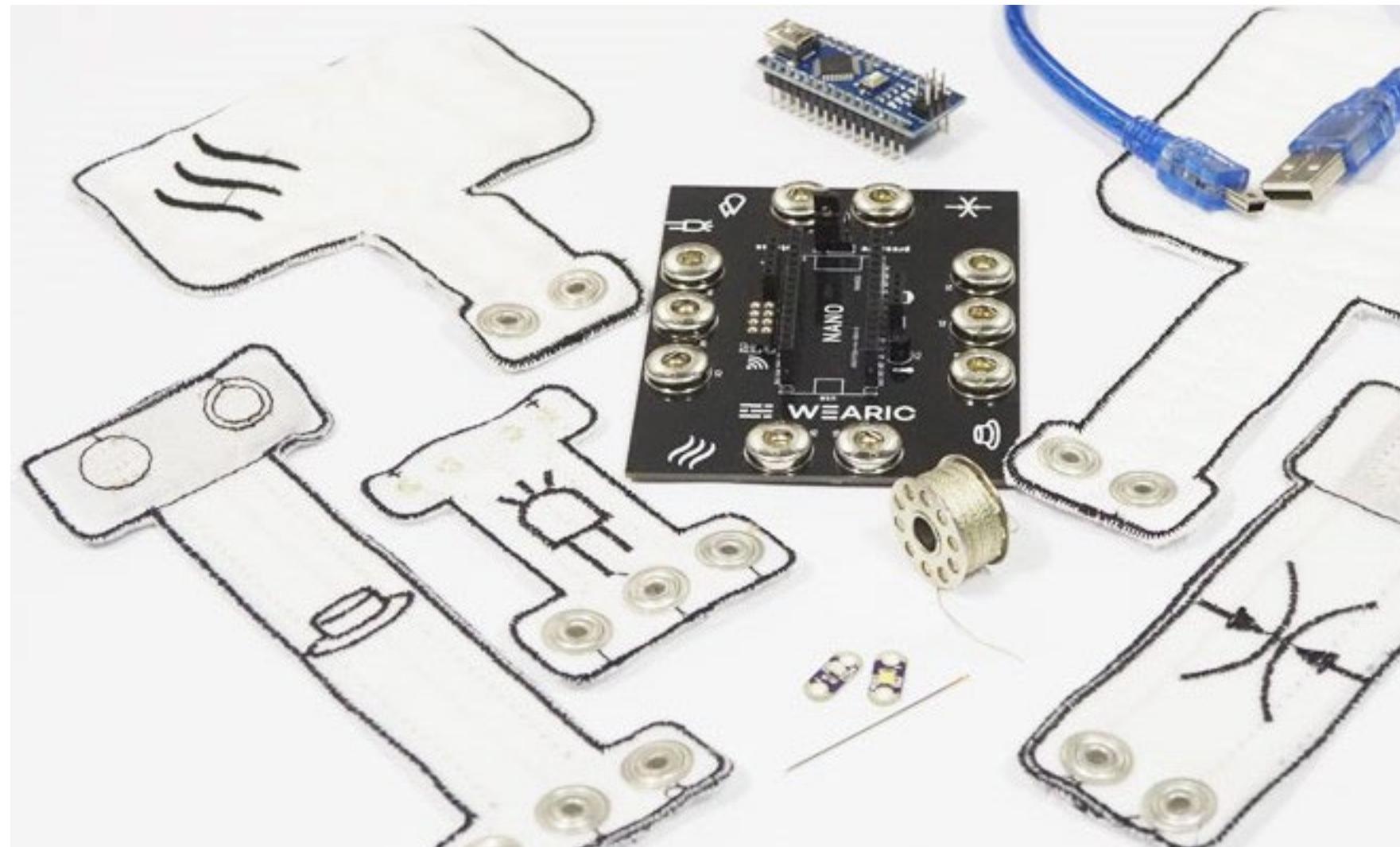
CONFERENCE at Advanced Textiles EXPO[®]

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Soft-Hard Interfaces/Connectorization



Soft-Hard Interfaces/Connectorization



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